

# Poster Session 1

December 4th, Tuesday 11:00-12:30 Room: Poster I (5th Floor)

Area 3: Crystalline Silicon Solar Cells and Technologies / Area 7: Terrestrial PV Systems

## Area 3

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- 4P-P1-01** CRYSTAL QUALITY IMPROVEMENT OF SOLID-PHASE CRYSTALLIZED EVAPORATED POLY-SI FILMS BY IN-SITU DENSIFICATION ANNEAL  
S. He<sup>1</sup>, B. Hoex<sup>2</sup>, D. Inns<sup>1</sup>, I. C. Brazil<sup>1</sup>, P. I. Widenborg<sup>1</sup> and A. G. Aberle<sup>1</sup>  
<sup>1</sup>The University of New South Wales, Australia, <sup>2</sup>Eindhoven University of Technology, The Netherlands
- 
- 4P-P1-02** PURIFICATION POSSIBILITY OF LOW-PURITY SILICON THIN FILMS USING REDUCTION POWER OF ALUMINUM  
T. Ito, Y. Aoki, E. Sudo and T. Motohiro  
Toyota Central Research and Development Laboratories, Inc., Japan
- 
- 4P-P1-03** THE EFFECT OF BULK LIFETIME DISTRIBUTION OVER MULTICRYSTALLINE SI WAFER ON SOLAR CELL EFFICIENCY  
Y. Do, J. Ahn and J. Jeong  
LG Chem. Ltd / Research Park, Korea
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- 4P-P1-04** HEAT TRANSFER BY THE GEOMETRIC PARAMETERS VARIATION OF HEAT EXCHANGER IN DIRECTIONAL SOLIDIFICATION PROCESS  
J. W. Shur, J. H. Hwang, Y. J. Kim and D. H. Yoon  
Sungkyunkwan University, Korea
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- 4P-P1-05** 3D GLOBAL ANALYSIS IN A UNIDIRECTIONAL SOLIDIFICATION PROCESS OF MULTICRYSTALLINE SILICON FOR PHOTOVOLTAIC  
H. Miyazawa, L. J. Liu, S. Nakano, Y. Kangawa and K. Kakimoto  
Kyushu University, Japan
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- 4P-P1-06** MINORITY-CARRIER COLLECTION MECHANISMS IN THE BASE AND DIFFUSED REGIONS IN ONE-DIMENSIONAL SOLAR CELL  
S. Shaie, K. A. Breh and M. Almotawakel  
Sana'a University, Republic of Yemen
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- 4P-P1-07** ANALYSIS OF CARBON DISTRIBUTION AND SIC PRECIPITATION USING UNIDIRECTIONAL-SOLIDIFICATION PROCESS FOR MULTI-CRYSTALLINE SILICON  
S. Nakano, L. J. Liu, X. J. Chen, H. Miyazawa, Y. Kangawa and K. Kakimoto  
Kyushu University, Japan
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- 4P-P1-08** DEGRADATION OF THE MINORITY CARRIER LIFETIME CAUSED BY Mn-CORRELATED DEFECTS IN Ga-IMPLANTED Si:P  
S. Beljakowa<sup>1</sup>, G. Pensl<sup>1</sup> and M. Rommel<sup>2</sup>  
<sup>1</sup>University of Erlangen-Nuernberg, Germany, <sup>2</sup>Fraunhofer-Institut fuer Integrierte Systeme und Bauelementetechnologie (IISB), Germany
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- 4P-P1-09** POLYCRYSTALLINE SILICON SOLAR CELL PROBLEM: THEORY AND APPLICATION  
M. K. AL-Motawakel  
Sana'a University, Republic of Yemen
- 
- 4P-P1-10** PURIFICATION OF METALLURGICAL GRADE SILICON IN FRACIONAL MELTING PROCESS  
W. Lee<sup>1</sup>, W. Yoon<sup>1</sup> and C. Park<sup>2</sup>  
<sup>1</sup>Korea University, Korea, <sup>2</sup>KCC Central Research Institute, Korea
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- 4P-P1-11** UNIFORMITY OF ELECTRICAL AND CRYSTAL QUALITY IN POLYCRYSTALLINE Si SUBSTRATES FOR SOLAR CELLS  
S. Tanaka<sup>1</sup>, K. Imai<sup>1</sup>, T. Kagawa<sup>1</sup>, A. Ogura<sup>1</sup>, Y. Ohshita<sup>2</sup>, K. Arafune<sup>2</sup>, H. Kawai<sup>2</sup>, F. Kusuoka<sup>2</sup>, M. Tajima<sup>3</sup> and M. Inoue<sup>1,3</sup>  
<sup>1</sup>Meiji University, Japan, <sup>2</sup>Toyota Tech. Inst., Japan, <sup>3</sup>ISAS/JAXA, Japan
- 
- 4P-P1-12** GROWTH OF CRYSTALLINE SI FILM BY USING LIQUID PHASE EPITAXY FROM SI PURE MELT FOR SOLAR CELL APPLICATIONS  
K. Kutsukake<sup>1</sup>, H. Kodama<sup>1</sup>, Z. Wang<sup>1</sup>, N. Usami<sup>1</sup>, K. Fujiwara<sup>1</sup>, Y. Nose<sup>2</sup> and K. Nakajima<sup>1</sup>  
<sup>1</sup>Tohoku University, Japan, <sup>2</sup>Kyoto University, Japan
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- 4P-P1-13** CALCULATION STUDY OF THE EFFECT OF IRON CONTAMINATION ON MINORITY CARRIER LIFETIME IN N-TYPE AND P-TYPE SILICON WAFERS  
M. Dhamrin, M. Suda, T. Saitoh and K. Kamisako  
Tokyo University of Agriculture and Technology, Japan
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**4P-P1-14** GROWTH AND CHARACTERIZATION OF N-TYPE POLYCRYSTALLINE SILICON INGOTS

K. Arafune, M. Nohara, Y. Ohshita and M. Yamaguchi  
Toyota Technological Institute, Japan

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**4P-P1-15** THE REFINING BEHAVIORS OF SILICONE WITH A "WASHING OUT" TECHNIQUE IN FRACTIONAL MELTING

K. Choi and W. Yoon  
Korea University, Korea

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**4P-P1-16** REFINING MECHANISMS AND IMPURITIES BEHAVIORS IN THE FRACTIONAL MELTED SILICON

J. Lee<sup>1</sup>, W. Yoon<sup>1</sup> and J. Kim<sup>2</sup>  
<sup>1</sup>Korea University, Korea, <sup>2</sup>Hongik University, Korea

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**4P-P1-17** EFFECT OF GRAIN BOUNDARIES ON METAL DISTRIBUTION IN POLYCRYSTALLINE SILICON FOR SOLAR CELLS

H. Kawai, K. Arafune, Y. Ohshita and M. Yamaguchi  
Toyota Technological Institute, Japan

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**4P-P1-18** STRENGTH CHARACTERIZATION AND PROOF TESTING OF THIN SOLAR WAFER

S. Schoenfelder, A. Bohne and J. Bagdahn  
Fraunhofer Institute for Mechanics of Materials Halle, Germany

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**4P-P1-19** GRAIN BOUNDARY POTENTIAL BARRIER HEIGHT IN POLYCRYSTALLINE SILICON : EFFECT OF GRAIN BOUNDARY STRUCTURE AND IMPURITY

Y. Nishibe<sup>1</sup>, K. Kido<sup>1</sup> and S. Tsurekawa<sup>2</sup>  
<sup>1</sup>Tohoku University, Japan, <sup>2</sup>Kumamoto University, Japan

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**4P-P1-20** MICROSTRUCTURAL CHARACTERIZATION OF BULK POLYCRYSTALLINE SILICON WAFER FABRICATED BY DIRECT CHILL CASTING

B. Hur<sup>1</sup>, H. Seong<sup>1</sup>, C. Suk<sup>2</sup> and K. Kang<sup>1</sup>  
<sup>1</sup>The Gyeongsang National University, Korea, <sup>2</sup>Komex INC, Korea

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**4P-P1-21** DEFECT STRUCTURES IN CAST-GROWN POLYCRYSTALLINE SILICON

Y. Ohshita<sup>1</sup>, K. Arafune<sup>1</sup>, T. Kuba<sup>2</sup>, A. Ogura<sup>3</sup> and M. Yamaguchi<sup>1</sup>  
<sup>1</sup>Toyota Technological Institute, Japan, <sup>2</sup>JEOL Ltd., Japan, <sup>3</sup>Meiji University, Japan

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**4P-P1-22** EFFECT OF SILVER THICK FILM PASTE ON SCREEN PRINTED OHMIC CONTACTS OF SILICON SOLAR CELLS

**Late News** J. Zheng<sup>1</sup>, Y. Zhang<sup>1</sup>, T. Gong<sup>2</sup>, Y. Aao<sup>2</sup>, Y. Yang<sup>1</sup>, L. Ding<sup>1</sup> and G. Chen<sup>1</sup>  
1East China University of Science and Technology, China, 2Shanghai Solar Energy Science and Technology Co Ltd., China

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**4P-P1-23** REAL-TIME OBSERVATION OF UNIDIRECTIONAL SOLIDIFICATION PROCESSES FOR HIGHER-QUALITY MULTICRYSTALLINE SILICON INGOTS

**Late News** I. Yamaga, K. Yamada, N. Araki, H. Suzuki and T. Saitoh  
Dai-Ichi Kiden Corp., Japan

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## Area 7

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- 4P-P1-24** AN OPTIMUM CONTROL STRATEGY FOR ENERGY MANAGEMENT IN A REMOTE AREA STAND-ALONE PV SYSTEM
- A. E. A. Nafeh  
Electronics Research Institute, Egypt
- 
- 4P-P1-25** FUZZY LOGIC OPERATION CONTROL FOR PV-DIESEL-BATTERY HYBRID ENERGY SYSTEM
- A. E. A. Nafeh  
Electronics Research Institute, Egypt
- 
- 4P-P1-26** PERFORMANCE EVALUATION OF SMALL PHOTOVOLTAIC STAND-ALONE SYSTEMS
- X. Zou, L. Bian, Y. Zhai and H. Liu  
Chinese Academy of Sciences, China
- 
- 4P-P1-27** HIGH EFFICIENCY SWITCHING CHARGER FOR PHOTOVOLTAIC POWER SYSTEMS BASED ON BOOST CONVERTERS
- T. Tanitteerapan<sup>1</sup> and S. Suteabtan<sup>2</sup>  
King Mongkut's University of Technology Thonburi, Thailand
- 
- 4P-P1-28** POWER SUPPLY FOR PHOTOVOLTAIC POWERED NEON SIGN FOR ADVERTISING BOARD IN REMOTE AREA BASED ON TV FLYBACK TRANSFORMERS
- T. Tanitteerapan<sup>1</sup>, and B. Yimnoi<sup>2</sup>  
<sup>1</sup>King Mongkut's University of Technology Thonburi, Thailand, <sup>2</sup>Chaiyapoom Technical College, Thailand
- 
- 4P-P1-29** EXPERIMENTAL STUDY OF STANDALONE PHOTOVOLTAIC SYSTEM
- W. Shen and T. Yoong  
Monash University, Malaysia
- 
- 4P-P1-30** ASSESSMENT OF PV/HYDRO/DIESEL HYBRID SYSTEM TO SAVING ENERGY OF ROYAL PROJECT RESEARCH STATION AT Mea-ya-noi
- J. Thongpran<sup>1,2</sup>, R. Watjanakunanan<sup>1,3</sup> and K. Kritikara<sup>1,3</sup>  
<sup>1</sup>Clean Energy Systems Group (CES), Thailand, <sup>2</sup>Rajamangala University of Technology Lanna (RMUTL), Thailand, <sup>3</sup>King Mongkut's University of Technology Thonburi (KMUTT), Thailand
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- 4P-P1-31** FIRST OPERATING YEAR OF PHOTOVOLTAIC BUS STOP INSTALLED AT EDUCATIONAL THAI UNIVERSITY
- S. Hiranvarodom, B. Plank-Klang and P. Apiratikul  
Rajamangala University of Technology Thanyaburi (RMUTT), Thailand
- 
- 4P-P1-32** THE DEVELOPMENT OF CAR'S INTERIOR AIR CONDITION SYSTEM BY THE SOLAR CELL DRIVE
- T. Ito and J. Itsumi  
Sojo University, Japan
- 
- 4P-P1-33** The photovoltaic power generation degradation by shade in shaped-eave installation PV module and its reduction
- M. Kanou, H. Kaneuchi, S. Kobayashi and T. Yachi  
Tokyo University of Science, Japan
- 
- 4P-P1-34** VALIDATION OF PV-HYBRID SYSTEM TECHNOLOGY AND OPERATION FOR RURAL ELECTRIFICATION IN SPAIN
- X. Vallvé and A. Graillot  
Trama TecnoAmbiental S.L., Spain
- 
- 4P-P1-35** AN EXPERIMENTAL STUDY OF A PHOTOVOLTAIC GRID-CONNECTED SYSTEM: MODELING
- N. Silsirivanich, E. Pakpairote, C. Limsakul, M. Seapan, B. Meunpinij, N. Chayavanich, A. Sangswang, D. Chenvidhya and C. Jivacate  
King's Mongkut University of Technology Thonburi (KMUTT), Thailand
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- 4P-P1-36** PERFORMANCE ANALYSIS OF FOUR 3KW GRID-CONNECTED PV SYSTEM FOR FIELD DEMONSTRATION TEST IN KOREA
- J. M. Park<sup>1</sup>, Y. O. Choi<sup>1</sup>, B. G. Min<sup>1</sup>, G. B. Cho<sup>1</sup>, H. L. Baek<sup>1</sup> and H. W. Lim<sup>2</sup>  
<sup>1</sup>Chosun University, Korea, <sup>2</sup>Korea Electric Testing Institute, Korea
- 
- 4P-P1-37** PERFORMANCE RESULT AND ANALYSIS OF A 53KW GRID-CONNECTED PV SYSTEM FOR CHOSUN UNIVERSITY DORMITORY IN KOREA
- Z. Piao, Y. Choi, N. Jeong, G. Cho and H. Baek  
Chosun University, Korea
-

**4P-P1-38 CONSTRUCTION PLAN OF 30 KW CPV POWER PLANT NEAR CENTRAIR AIRPORT**

K. Araki  
Daido Steel, Japan

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**4P-P1-39 IMPEDANCE MODELING OF A PV GRID CONNECTED SYSTEM**

E. Pakpairote, D. Chenvidhya, T. Chayavanich, K. Kiratikara, A. Sangswang and N. Ruangrotsin  
King's Mongkut University of Technology Thonburi (KMUTT), Thailand

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**4P-P1-40 STUDY OF CONTROL METHOD UNDER THE 30-MINUTE BALANCING RULE BY USING FORECAST OF IRRADIATION**

M. Nishihata<sup>1</sup>, K. Fujiwara<sup>1</sup>, Y. Ishihara<sup>1</sup>, T. Todaka<sup>1</sup>, T. Funabashi<sup>2</sup>, H. Nakashima<sup>2</sup> and Y. Okuno<sup>2</sup>  
<sup>1</sup>Doshisha University, Japan, <sup>2</sup>Meidensha Corporation, Japan

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**4P-P1-41 ONLINE CORRECTION FOR INSOLATION FORECASTING USING WEATHER FORECAST**

T. Shimada<sup>1,2</sup> and K. Kurokawa<sup>2</sup>  
<sup>1</sup>Hitachi, Ltd., Japan, <sup>2</sup>Tokyo University of Agriculture and Technology, Japan

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**4P-P1-42 BIFACIAL PV SYSTEM IN AICHI RINKU NEW ENERGY GENERATION PLANT**

I. Araki, M. Tatsunokuchi, H. Nakahara and T. Tomita  
Hitachi, Ltd., Japan

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**4P-P1-43 A SMART CENTRAL CONTROL SYSTEM OF ON-GRID HCPV**

C. Ma<sup>1</sup>, I. Lung<sup>1</sup>, S. Chyou<sup>1</sup> and H. Lin<sup>2</sup>  
<sup>1</sup>Institute of Nuclear Energy Research, Taiwan, <sup>2</sup>Atomtech Engineer Consultant Company Ltd., Taiwan

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**4P-P1-44 EVALUATION OF POWER QUALITY OF PV-GRID CONNECTED SYSTEM WITH BATTERY STORAGE UNDER LOW RADIATION**

T.Chayavanich<sup>1</sup>, J.Thongpro<sup>2</sup>, N. Chayavanich<sup>1</sup>, D. Chenvidhya<sup>1</sup>, C. Jivacate<sup>1</sup> and K.Kirtikara<sup>1</sup>  
<sup>1</sup>King Mongkut's University of Technology Thonburi (KMUTT), Thailand, <sup>5</sup>Rajamankgala University of Technology Lanna (RMUTL), Thailand

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**4P-P1-45 UTILITY INTERACTIVE PV SYSTEM WITH POWER SHAPING FUNCTION FOR INCREASING PEAK POWER CUT EFFECT**

H. Heo<sup>1</sup>, H. Kim<sup>2</sup>, G. Choe<sup>1</sup>, J. Kim<sup>3</sup> and Y. Choi<sup>1</sup>  
<sup>1</sup>Kon-Kuk Univ., Korea, <sup>2</sup>Hanbit Co., Korea, <sup>3</sup>Soong-Sil Univ., Korea

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**4P-P1-46 THE INFLUENCE OF SOILS ON THE PHOTOVOLTAIC SYSTEM PERFORMANCE IN THE FIELD TEST PROJECT IN JAPAN**

T. Oozeki<sup>1</sup>, T. Yamada<sup>1</sup>, K. Kato<sup>1</sup> and T. Yamamoto<sup>2</sup>  
<sup>1</sup>National Institute of Advanced Industrial Science and Technology, Japan, <sup>2</sup>New Energy and Industrial Technology Development Organization (NEDO), Japan

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**4P-P1-47 ANALYTICAL EVALUATION OF A PV GRID-CONNECTED SYSTEM INSTALLED AT RESOURCES CENTER BUILDING IN THAILAND**

S. Sangtron<sup>1</sup> and S. Hiranvarodom<sup>2</sup>  
<sup>1</sup>Rajamangala University of Technology Lanna (RMUTL-Tak), Thailand, <sup>2</sup>Rajamangala University of Technology Thanyaburi (RMUTT), Thailand

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**4P-P1-48 RESEARCH ON THREE-DIMENSIONAL COORDINATES ACQUISITION FOR SHADOW ESTIMATION IN PHOTOVOLTAIC SYSTEM**

Y. Watanabe and K. Krokawa  
Tokyo University of Agriculture and Technology (TUAT), Japan

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**4P-P1-49 ANALYSIS OF FLUCTUATION CHARACTERISTICS OF PV SYSTEM ACCORDING TO THE ARRAY CONFIGURATION**

N. Kawasaki<sup>1</sup>, K. Kitamura<sup>2</sup>, H. Sugihara<sup>3</sup>, S. Nishikawa<sup>4</sup> and K. Kurokawa<sup>1</sup>  
<sup>1</sup>Tokyo University of Agriculture and Technology, Japan, <sup>2</sup>MEIDENSHA CORPORATION, Japan, <sup>3</sup>Kandenko co., Ltd, Japan, <sup>4</sup>Nihon University, Japan

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**4P-P1-50 TRANSFORMERLESS GRID CONNECTED PHOTOVOLTAIC INVERTER WITH HYSTERSIS CURRENT CONTROL**

N. A. Rahim, J. Selvaraj and C. Krismadinata  
University Malaya, Malaysia

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**4P-P1-51 DECISION METHOD OF OPTIMAL 24-HOURS SENDING VOLTAGE PROFILE IN DISTRIBUTION NETWORK WITH PV SYSTEMS**

Y. Hayashi<sup>1</sup>, Y. Hanai<sup>1</sup>, J. Matsuki<sup>1</sup>, Y. Fuwa<sup>2</sup> and K. Mori<sup>2</sup>  
<sup>1</sup>University of Fukui, Japan, <sup>2</sup>Tokyo Electric Power Company, Japan

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**4P-P1-52** DESIGN, INSTALLATION AND EVALUATION OF SOLAR PV - DIESEL HYBRID SYSTEM AT LAKSHADWEEP - BANGARAM ISLAND,INDIA – A CASE STUDY

**Late News** C. V. S. N. Murty and S. Lokabhiraman  
Bharat Heavy Electricals Ltd., India

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**4P-P1-53** VILLAGE ELECTRIFICATION THROUGH A OFF-GRID SOLAR PV (SPV) POWER PLANT - A SUCCESSFUL MODEL FOR RURAL INDIA

**Late News** C. V. S. N. Murty and B. N. Ramesh  
BHEL, India

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**4P-P1-54** NON LINEAR CONTROL OF A PHOTOVOLTAIC PUMPING SYSTEM

**Late News** R. Andoulsi<sup>1</sup>, A. Sellami<sup>1</sup>, B. Khiari<sup>1</sup>, A. Mami<sup>2</sup> and G. Dauphin-Tanguy<sup>3</sup>  
1Research and Technology Centre of Energy, Tunisia, 2ENIT, Tunisia, 3Ecole Centrale de Lille, France

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**4P-P1-55** INVERTER CONTROL FOR SINGLE-STAGE SINGLE-PHASE PHOTOVOLTAIC GRID-CONNECTED SYSTEM

**Late News** H. Xiang<sup>1</sup>, Y. Yan<sup>1</sup> and H. Jiang<sup>2</sup>  
1Nanjing University of Aeronautics & Astronautics, China, 2Shanghai Aviation Electric Co., Ltd, China

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**4P-P1-56** PERFORMANCE OF A GRID CONNECTED SOLAR HYDROGEN PV SYSTEM IN MALAYSIA

**Late News** T. Marnoto, W. R. W. Daud, K. Sopian, R. Zulkifli, M. N. Ab Rahman, M. AlGhoul and N. Amin  
Universiti Kebangsaan Malaysia, Malaysia

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**4P-P1-57** EVALUATION METHOD OF PERFRMANCE AND ECONOMICS OF CLUSTERED PV SYSTEM (1)

**Late News** S. Nishikawa<sup>1</sup> and H. Suguhara<sup>2</sup>  
1Nihon University, Japan, 2Kandenko co., ltd., Japan

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**4P-P1-58** FORECASTING METHOD OF TIME SERIES OF SOLAR ENERGY BY USING WIDE METEOROLOGICAL DATA

**Late News** K. Ichiyangi<sup>1</sup>, K. Taniguchi<sup>1</sup>, H. Nakano<sup>1</sup>, K. Yukita<sup>1</sup>, Y. Goto<sup>1</sup>, F. Yamada<sup>2</sup>, N. Yamamoto<sup>2</sup> and S. Sugimoto<sup>2</sup>  
<sup>1</sup>Aichi Institute of Technology, Japan, <sup>2</sup>Chubu Electric Power Co., Inc., Japan

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## Poster Session 2

December 4th, Tuesday 16:00-17:30 Room: Poster II (5th Floor)

Area 3: Crystalline Silicon Solar Cells and Technologies

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- 4P-P2-01** EVALUATION OF THE OHMIC PROPERTIES OF THE SILVER METAL CONTACTS FORMED ON THE MULTICRYSTALLINE SILICON SOLAR CELLS  
P. N. Vinod  
Naval Physical and Oceanographic Laboratory, India
- 
- 4P-P2-02** THE MATCHING INVESTIGATION OF DEPOSITED PRESSURE AND ANNEALING TEMPERATURE OF SiN<sub>x</sub>H ANTIREFLECTION FILMS  
C. Liu, T. Gong, X. Yuan, R. Xu, X. Huang and L. Wang  
Shanghai Solar Energy Science & Technology Co.,Ltd, China
- 
- 4P-P2-03** SPHELAR® PANEL AS A FAÇADE ELEMENT  
H. Sugimura<sup>1</sup>, H. Nakamura<sup>1</sup>, T. Matsumoto<sup>1</sup>, S. Poulsen<sup>2</sup>, H. Lauritzen<sup>2</sup>, J. Christoffersen<sup>3</sup>,  
K. Taira<sup>1</sup>, E. Omura<sup>1</sup>, I. Inagawaa<sup>1</sup> and J. Nakata<sup>1</sup>  
<sup>1</sup>Kyosemi Corporation, Japan, <sup>2</sup>Danish Technological Institute, Denmark, <sup>3</sup>Danish Building Research Institute, Denmark
- 
- 4P-P2-04** P-TYPE EMITTER EPITAXY ON N-TYPE SILICON WAFER  
E. Schmich, H. Lautenschlager and S. Reber  
Fraunhofer Institute for Solar Energy Systems, Germany
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- 4P-P2-05** A SOLUTION-PREPARED SURFACE TEXTURE FOR SOLAR CELLS  
M. Tao, W. Zhou, H. Yang and K. Han  
University of Texas at Arlington, USA
- 
- 4P-P2-06** BORON DOPED SILICON OXIDE FILMS FOR USE AS LOCAL BACK SURFACE FIELD IN CAST POLYCRYSTALLINE SILICON SOLAR CELLS  
A. Limmanee<sup>1</sup>, T. Sugiura<sup>1</sup>, H. Yamamoto<sup>1</sup>, T. Sato<sup>2</sup>, S. Miyajima<sup>1</sup>, A. Yamada<sup>1</sup> and M. Konagai<sup>1</sup>  
<sup>1</sup>Tokyo institute of Technology, Japan, <sup>2</sup>Mitsubishi Electric Corporation, Japan, <sup>3</sup>Tokyo Institute of Technology, Japan
- 
- 4P-P2-07** EVALUATION OF SILICON SOLAR PANEL'S ELECTRICAL PARAMETERS IN DIFFERENT ENVIRONMENTAL CONDITIONS USING A COMPREHENSIVE MEASUREMENT SYSTEM  
M. Taherbaneh<sup>1,3</sup>, H. Ghafori Fard<sup>2</sup>, A. H. Rezaie<sup>3</sup>, O. Shekoofa<sup>4</sup> and S. Karbasian<sup>4</sup>  
<sup>1</sup>Iranian Space Agency, Iran, <sup>2</sup>Imam Khomeini International University, Iran, <sup>3</sup>Amirkabir University of Technology, Iran, <sup>4</sup>Iran Telecommunication Research Center, Iran
- 
- 4P-P2-08** DENSITY OF INTERFACE STATES AT THE SILICON-SILICON DIOXIDE INTERFACE OF TEXTURED SILICON WITH RANDOM PYRAMIDS  
L. P. Johnson and K. R. McIntosh  
Australian National University, Australia
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- 4P-P2-09** FABRICATON OF BOWING RELEASED THIN CRYSTALLINE SILICON SOLAR CELLS WITH SCREEN-PRINTED CONTACTS  
D. Lee, J. Kim, H. Park, J. You and J. Jeong  
LG Chem. Ltd./Research Park, Korea
- 
- 4P-P2-10** DESIGN OF A REFLECTED LIGHT MEASURING APPARATUS FOR LBIC MEASUREMENT OF CRYSTALLINE SOLAR CELLS  
K. Lin, Y. Chiang, Y.Liu, L. Cheng, C. Liu and Y. Chang  
ITRI, Industrial Technology Research Institute, Taiwan
- 
- 4P-P2-11** INFLUENCE OF ACIDIC TEXTURISING CONDITIONS ON ANTI-REFLECTION COATING PROCESS AND MUTI-CRYSTALLINE SILICON SOLAR CELL PERFORMANCE  
J. Ahn, J. Cheong, D. Lee, Y. Do, S. Lee and J. Jeong  
LG Chem, Ltd./ Research Park, Korea
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- 4P-P2-12** A OPTIMIZATION OF ANTI-REFLECTION COATINGS ON CRYSTALLINE SILICON SOLAR CELLS WITH GLASS ENCAPSULATION  
J. Ahn, H. Park, S. Lee and J. Jeong  
LG Chem, Ltd./ Research Park, Korea
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- 4P-P2-13** THE EVALUATION OF THE BULK AND THE SURFACE PASSIVATION EFFECTS FOR MULTI-CRYSTALLINE SILICON SOLAR CELL  
Y. Kurimoto, H. Mizukami, S. Ooka, Y. Takaba, Y. Yamamoto and S. Okamoto  
SHARP Corp., Japan
-

- 4P-P2-14** HIGH PRESSURE WATER VAPOR HEAT TREATMENT FOR THE PASSIVATION OF POLYCRYSTALLINE SILICON THIN FILM SOLAR CELLS  
A. Ogane, Y. Takahashi, A. Kitiyanan, Y. Uraoka and T. Fuyuki  
Nara Institute of Science and Technology (NAIST), Japan
- 
- 4P-P2-15** A NEW METHOD FOR THE PRODUCTION OF ULTRA-THIN CRYSTALLINE SI WAFERS  
F. Dross<sup>1</sup>, A. Milhe<sup>1,2</sup>, J. Robbelein<sup>1</sup>, I. Gordon<sup>1</sup>, P. O. Bouchard<sup>2</sup>, G. Beaucarne<sup>1</sup> and J. Poortmans<sup>1</sup>  
<sup>1</sup>IMEC, v.z.w., Belgium, <sup>2</sup>Ecole des Mines de Paris (CEMEF), France
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- 4P-P2-16** DETECTION OF CRACK LOCATION IN MULTICRYSTALLINE SILICON SOLAR CELLS BY ELECTROLUMINESCENCE IMAGE SUBTRACTION TECHNIQUE  
A. Kitiyanan<sup>1</sup>, K. Bothe<sup>2</sup>, Y. Takahashi<sup>1</sup>, A. Ogane<sup>1</sup> and T. Fuyuki<sup>1</sup>  
<sup>1</sup>Nara Institute of Science and Technology (NAIST), Japan, <sup>2</sup>Institut für Solarenergieforschung GmbH Hameln/Emmerthal (ISFH), Germany
- 
- 4P-P2-17** FABRICATION OF ELECTRODE GROOVES ON SILICON SOLAR CELL USING SURFACE DISCHARGE  
T. Hamada, S. Arakawa, T. Sakoda and M. Otsubo  
University of Miyazaki, Japan
- 
- 4P-P2-18** SIMULATED DESIGN DIAGRAMS FOR A ONE – DIMENSIONAL SOLAR CELL  
K. Breh, S. Shaie and M. Almotawakel  
Sana'a University, Republic of Yemen
- 
- 4P-P2-19** INKJET PRINTING FOR HIGH DEFINITION INDUSTRIAL MASKING PROCESSES FOR SOLAR CELL PRODUCTION  
D. Biro<sup>1</sup>, D. Erath<sup>1</sup>, U. Belledin<sup>1</sup>, J. Specht<sup>1</sup>, D. Stüwe<sup>1</sup>, A. Lemke<sup>1</sup>, M. Aleman<sup>1</sup>, N. Mingirulli<sup>1</sup>, J. Rentsch<sup>1</sup>, R. Preu<sup>1</sup>, R. Schlosser<sup>2</sup>, B. Bitnar<sup>3</sup> and H. Neuhaus<sup>3</sup>  
<sup>1</sup>Fraunhofer Institute for Solar Energy Systems (ISE), Germany, <sup>2</sup>SolarWorld Industries Deutschland, Germany, <sup>3</sup>Deutsche Cell GmbH, Germany
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- 4P-P2-20** IMPROVED TRANSFER PROCESS USING SELECTIVE ELECTROCHEMICAL ETCHING  
O. Tobail, M. Reuter, S. Eisele and J. H. Werner  
University of Stuttgart, Germany
- 
- 4P-P2-21** SPUTTERED PHOSPHOROUS PRECURSORS FOR LASER DOPING  
S. Eisele, G. Bilger, M. Ametowobla, J. R. Köhler and J. H. Werner  
Institut für Physikalische Elektronik, Germany
- 
- 4P-P2-22** HETEROJUNCTION SOLAR CELLS (A-SI/C-SI) PASSIVATED USING HYDROGENATED AMORPHOUS SILICON SUBOXIDE FILMS  
T. Mueller<sup>1</sup>, S. Schwertheim<sup>1</sup>, Y. Huang<sup>2</sup>, M. Scherff<sup>1</sup> and W. R. Fahrner<sup>1</sup>  
<sup>1</sup>University of Hagen, Germany, <sup>2</sup>Forschungszentrum Juelich GmbH, Germany
- 
- 4P-P2-23** EVALUATION OF INTERFACE DEFECTS IN A-SI:H/MC-SI HETEROJUNCTION SOLAR CELLS  
W. R. Fahrner, M. Scherff, T. Mueller and S. Schwertheim  
University of Hagen, Germany
- 
- 4P-P2-24** SLURRIES FOR MULTI WIRE SAWING - AN EXPERIMENTAL APPROACH -  
M. Schumann, M. Bergmann, F. Haas, T. Orellana, K. Mayer and A. Eyer  
Fraunhofer ISE, Germany
- 
- 4P-P2-25** FUNCTION OF FRONT SURFACE FIELD IN N-TYPE HIGH-EFFICIENCY BACK-JUNCTION BACK-CONTACT SILICON SOLAR CELLS  
F. Granek, C. Reichel, M. Hermle, O. Schultz and S. Glunz  
Fraunhofer ISE, Germany
- 
- 4P-P2-26** NOVEL APPROACHES OF TRI-CRYSTALLINE SILICON SURFACE TEXTURING  
K. Han<sup>1</sup>, M. Ju<sup>1,2</sup>, Y. Kim<sup>1</sup>, I. Moon<sup>1</sup>, K. Lee<sup>1,2</sup>, S. Han<sup>1,2</sup>, H. Kim<sup>2</sup>, K. Kim<sup>1</sup>, N. Lakshminarayan<sup>1</sup> and J. Yi<sup>1</sup>  
<sup>1</sup>Sungkyunkwan University, Korea, <sup>2</sup>KPE Ins., Korea
- 
- 4P-P2-27** SELECTIVE EMITTER USING POROUS SILICON FOR CRYSTALLINE SILICON SOLAR CELLS  
I. Moon<sup>1</sup>, Y. Kim<sup>1</sup>, K. Han<sup>1</sup>, D. Ai<sup>1</sup>, J. Lee<sup>1</sup>, M. Ju<sup>2</sup>, K. Lee<sup>2</sup>, H. Kim<sup>2</sup>, K. Kim<sup>1</sup>, N. Lakshminarayan<sup>1,3</sup> and J. Yi<sup>1</sup>  
<sup>1</sup>Sungkyunkwan University, Korea, <sup>2</sup>KPE Ins., Korea, <sup>3</sup>Madras Christian College, India

**4P-P2-28** NOVEL INKJET INKS TOWARDS NON-CONTACT PRINTING OF SILICON SOLAR CELLS

O. Khaselev, N. Desai, S. Devarajan, M. Bouregda, A. Lifton, S. Chatterjee, M. Marzi and B. Singh  
Cookson Electronics, USA

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**4P-P2-29** ANTIREFLECTION SUBWAVELENGTH STRUCTURE FORMED BY WET PROCESS USING NANO PARTICLES OF NOBLE METAL CATALYST

K. Nishioka<sup>1</sup>, S. Horita<sup>1</sup>, K. Ohdaira<sup>1</sup>, H. Matsumura<sup>1</sup>, Y. Takahashi<sup>2</sup> and T. Fuyuki<sup>2</sup>  
<sup>1</sup>Japan Advanced Institute of Science and Technology, Japan, <sup>2</sup>Nara Institute of Science and Technology, Japan

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**4P-P2-30** COMPARISON OF VARIOUS BACK SIDE STRUCTURES FOR IMPROVING EFFICIENCY OF CRYSTALLINE SILICON SOLAR CELLS

M. S. Jeon, P. Supajariyawichai, K. Kawachi, H. Fukaya, M. Dhamrin and K. Kamisako  
Tokyo University of Agriculture and Technology, Japan

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**4P-P2-31** CHARACTERIZATION OF HETEROJUNCTIONS IN CRYSTALLINE SILICON BASED SOLAR CELLS BY INTERNAL PHOTOEMISSION

I. Sakata, M. Yamanaka and H. Kawanami  
National Institute of Advanced Industrial Science and Technology (AIST), Japan

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**4P-P2-32** SILICON NITRIDE INDUCED HYDROGENATION OF SILICON/SILICON OXIDE INTERFACES FOR REAR SURFACE PASSIVATION OF INDUSTRIAL-TYPE THIN SOLAR CELLS

H. F. W. Dekkers, G. Agostinelli, Y. Ma and G. Beaucarne  
IMEC vzw, Belgium

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**4P-P2-33** ALTERNATIVES TO SCREEN PRINTING FOR THE FRONT SIDE METALLIZATION OF SILICON SOLAR CELLS

M. Alemán, N. Bay, A. Knorz, A. Grohe and S. W. Glunz  
Fraunhofer Institute for Solar Energy Systems, Germany

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**4P-P2-34** INKJET PRINTING FOR HIGH EFFICIENCY SILICON SOLAR CELL STRUCTURES

R. Utama, A. Lennon, A. Ho-Baillie, M. Lenio, N. Borojevic and S. Wenham  
UNSW, Australia

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**4P-P2-35** EFFECT OF ANNEALING TEMPERATURE ON A-SI:H FILMS FOR HETEROJUNCTION SOLAR CELLS

K. Kawachi, M. S. Jeon, M. Dhamrin, K. Kamisako  
Tokyo University of Agriculture & Technology, Japan

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**4P-P2-36** REAR SIDE OHMIC CONTACTS FOR THIN SI SOLAR CELLS

H. Fukaya, M. S. Jeon, M. Dhamrin and K. Kamisako  
Tokyo University of Agriculture & Technology, Japan

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**4P-P2-37** QUALITY IMPROVEMENT OF MULTICRYSTALLINE SILICON WAFERS BY BORON-GETTERING

A. Uzum<sup>1</sup>, M. Dhamrin<sup>1</sup>, T. Saitoh<sup>1</sup>, K. Kamisako<sup>1</sup> and I. Yamaga<sup>2</sup>  
<sup>1</sup>Tokyo Univ. of Agr. & Tech., Japan, <sup>2</sup>Dai-ichi Kiden Corp., Japan

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**4P-P2-38** DEPOSITION AND EVALUATION OF PASSIVATION FILMS FOR SI SOLAR CELLS BY RPECVD METHOD

Y. Suzuki, S. Maeda, M. Dhamrin, M. Suda and K. Kamisako  
Tokyo University of Agriculture and Technology, Japan

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**4P-P2-39** PHOTON CONVERTERS FOR THIN BIFACIAL SILICON SOLAR CELLS

A. C. Pan, C. del Cañizo, I. Tobías and A. Luque  
Universidad Politécnica de Madrid, Spain

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**4P-P2-40** LARGE AREA TRI-CRYSTALLINE SILICON SOLAR CELL ETCHED BY ALKALIC SOLUTION

Y. Kim<sup>1</sup>, K. Han<sup>1</sup>, I. Mun<sup>1</sup>, K. Kim<sup>1</sup>, H. Kim<sup>2</sup>, K. Lee<sup>1,2</sup>, S. Han<sup>2</sup>, M. Joo<sup>1,2</sup> and J. Yi<sup>1,2</sup>.  
<sup>1</sup>Sungkyunkwan University, Korea, <sup>2</sup>KPE ins., Korea

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**4P-P2-41** A MODEL FOR PREDICTING THE BOWING EFFECTS OF THIN SILICON SOLAR CELLS

F. Lin, F. Yeh, M. Lin and H. Hsieh  
Industrial Technology Research Institute, Taiwan

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<b>4P-P2-42</b>	EFFECTIVE MINORITY CARRIER LIFETIME OF CRYSTALLINE SILICON WAFER WITH DIFFERENT SURFACE TREATMENT AND PASSIVATION LAYERS D. Jeong <sup>1</sup> , J. Lee <sup>1</sup> , Y. Kim <sup>4</sup> , J. Yi <sup>4</sup> , M. Kang <sup>2</sup> , Y. Ok <sup>2</sup> , S. Kim <sup>3</sup> , D. Kim <sup>2</sup> , K. Yoon <sup>1</sup> and J. Song <sup>1</sup> <sup>1</sup> Korea Institute of Energy Research, Korea, <sup>2</sup> Korea University, Korea, <sup>3</sup> Gwangju Institute of Science and Technology, Korea, <sup>4</sup> School of Information & Communication Engineering, Korea
<b>4P-P2-43</b>	ROLE OF LEAD OXIDE ON THE FORMATION OF SILVER PRECIPITATES IN SCREEN PRINTED SILVER CONTACTS FOR SILICON SOLAR CELLS K. Hong <sup>1</sup> , S. Cho <sup>1</sup> , J. Huh <sup>1</sup> , J. You <sup>2</sup> and J. Jong <sup>2</sup> <sup>1</sup> Korea University, Korea, <sup>2</sup> LG Chem, Ltd. Research Park, Korea
<b>4P-P2-44</b>	MICROSCOPIC HOMOGENEITY OF EMITTERS FORMED USING IN-LINE DIFFUSION AND SPRAYED PHOSPHORIC ACID AS THE DOPANT SOURCE C. Voyer <sup>1</sup> , T. Buettner <sup>1</sup> , R. Bock <sup>2</sup> , D. Biro <sup>1</sup> and R. Preu <sup>1</sup> <sup>1</sup> Fraunhofer Institute for Solar Energy Systems ISE, Germany, <sup>2</sup> Institute for Solar Energy Research in Hameln/Emmerthal (ISFH), Germany
<b>4P-P2-45</b>	HETEROJUNCTION CRYSTALLINE SILICON SOLAR CELLS WITH A WIDEGAP HYDROGENATED NANOCRYSTALLINE SILICON CARBIDE WINDOW LAYER DEPOSITED BY VHF-PECVD S. Miyajima, A. Yamada and M. Konagai Tokyo Institute of Technology, Japan
<b>4P-P2-46</b>	SCREEN-PRINTED ELECTRODE: POSSIBILITY INSPECTION FOR SUPER THIN SUBSTRATE AND HIGH-EFFICIENCY MULTI-CRYSTALLINE SILICON SOLAR CELLS S. Okamoto, K. Wada, Y. Takaba, R. Ozaki and R. Mikami SHARP CORPORATION, Japan
<b>4P-P2-47</b>	LASER RECRYSTALLIZATION FOR SELECTIVE EMITTER IN SILICON SOLAR CELLS J. You, J. Kim, D. Lee, H. Lee, H. Park and J. Jeong LG Chem. Ltd./Research Park, Korea
<b>4P-P2-48</b>	DEVELOPMENT OF FRONT CONTACT INK FOR SHALLOW EMITTERS T. Pham, C. Khadilkar, S. Kim, N. Merchant, S. Sridharan and A. Shaikh Ferro Corporation, USA
<b>4P-P2-49</b>	PREPARATION AND CHARACTERISATION OF SiN <sub>x</sub> :H COMPLEX ANTIREFLECTION LAYERS ON POLYCRYSTALLINE SILICON SOLAR CELLS Q. Ban, F. Yun, Y. Tang and X. Wang Solarfun Power Holdings Co., China
<b>4P-P2-50</b>	EFFECT OF FIXED CHARGES IN A-SiN <sub>x</sub> :H FILMS ON SURFACE PASSIVATION OF CRYSTALLINE SILICON S. Ishikawa <sup>1</sup> , K. Fukuda <sup>1</sup> , H. Sai <sup>2</sup> , K. Arafune <sup>1</sup> , Y. Ohshita <sup>1</sup> and M. Yamaguchi <sup>1</sup> <sup>1</sup> Toyota Technological Institute, Japan, <sup>2</sup> Advanced Industrial Science and Technology, Japan
<b>4P-P2-51</b>	PURIFICATION OF METALLURGICAL-GRADE SILICON BY A HYBRID PYRO- AND HYDRO-METALLURGICAL PROCESS <b>Late News</b> S. Tsao <sup>1</sup> , D. Xiao <sup>2</sup> , F. Fong <sup>2</sup> and C. Hu <sup>1</sup> <sup>1</sup> National Tsing Hua University, Taiwan, <sup>2</sup> Industrial Technology Research Institute, Taiwan
<b>4P-P2-52</b>	SURFACE TEXTURING OF SILICON USING ZENON DIFLUORIDE <b>Late News</b> H. Takato and I. Sakata National Institute of Advanced Industrial Science and Technology (AIST), Japan
<b>4P-P2-53</b>	MINORITY CARRIER DYNAMICS IN POLYCRYSTALLINE SILICON SOLAR CELLS STUDIED BY PHOTO-ASSISTED KELVIN PROBE FORCE MICROSCOPY <b>Late News</b> M. Takihara <sup>1</sup> , T. Ujihara <sup>2</sup> and T. Takahashi <sup>1</sup> <sup>1</sup> University of Tokyo, Japan, <sup>2</sup> Nagoya University, Japan

## Poster Session 3

December 5th, Wednesday 11:00-12:30 Room: Poster I (5th Floor)

Area 5: CIGS, II-VI and Related Thin Films and Cells / Area 8: PV Programs, Industries, Market, and Environment

### Area 5

#### 5P-P3-01 EFFECTS OF Na CONTENT ON THE Mo(Se,S)<sub>2</sub> FORMATION IN CIGSeS THIN-FILM SOLAR CELLS

V. V. Hadagali<sup>1</sup>, N. G. Dhere<sup>1</sup> and H. H. Heinrich<sup>2</sup>

<sup>1</sup>Florida Solar Energy Center, USA, <sup>2</sup>Advanced Materials Processing and Analysis Center, USA

#### 5P-P3-02 CU(IN,GA)(S,SE)<sub>2</sub> THIN FILMS PREPARED BY SEQUENTIAL EVAPORATION FROM TERNARY AND BINARY COMPOUNDS

T. Yamaguchi<sup>1</sup>, A. Yoshida<sup>1</sup>, Y. Taniguchi<sup>1</sup>, K. Numata<sup>1</sup>, S. Niiyama<sup>2</sup> and T. Imanishi<sup>2</sup>

<sup>1</sup>Wakayama College of Technology, Japan, <sup>2</sup>Wakayama Industrial Technology Center, Japan

#### 5P-P3-03 CHARACTERIZATION OF EVAPORATED CUINS<sub>2</sub> FILMS ANNEALED IN HYDROGEN SULFIDE ATMOSPHERE

Y. Akaki<sup>1</sup>, K. Nomoto<sup>2</sup>, S. Nakamura<sup>3</sup>, T. Yoshitake<sup>2</sup> and K. Yoshino<sup>4</sup>

<sup>1</sup>Miyakonojo National College of Technology, Japan, <sup>2</sup>University of Kyushu, Japan, <sup>3</sup>Tsuyama National College of Technology, Japan, <sup>4</sup>University of Miyazaki, Japan

#### 5P-P3-04 MICROSTRUCTURAL PROPERTIES OF (IN, GA)<sub>2</sub>SE<sub>3</sub> PRECURSOR LAYERS FOR EFFICIENT CIGS THIN FILM SOLAR CELLS

T. Mise and T. Nakada

Aoyama Gakuin University, Japan

#### 5P-P3-05 CRYSTAL GROWTH PROMOTION OF CUINSE<sub>2</sub> ON POLYIMIDE FILM BY RAPID THERMAL ANNEALING

K. Nomura, K. Tanaka, T. Minemoto and H. Takakura

Ritsumeikan University, Japan

#### 5P-P3-06 INFLUENCE OF PULSED-LASER IRRADIATION ON CIGS THIN FILMS AND SOLAR CELLS

Y. Uchida<sup>1</sup>, N. Kawamura<sup>2</sup>, J. Noguchi<sup>2</sup>, T. Mise<sup>2</sup>, S. Shirakata<sup>3</sup> and T. Nakada<sup>2</sup>

<sup>1</sup>Teikyo Univ. of Sci. and Tech., Japan, <sup>2</sup>Aoyama Gakuin University, Japan, <sup>3</sup>Ehime University, Japan

#### 5P-P3-07 CuInSe<sub>2</sub> THIN FILM PREPARATION THROUGH A NEW SOLUTION BASED SELENISATION PROCESS

M. Kauk, M. Altosaar, L. Kaupmees and M. Grossberg

Tallinn University of Technology, Estonia

#### 5P-P3-08 PREPARATION OF CIS ABSORBER LAYER FOR SOLAR CELLS BY NON-VACUUM PROCESS

K. Kim<sup>1</sup>, R. B. V.Chalapathy<sup>2</sup>, S. Ahn<sup>3</sup>, K. Yoon<sup>3</sup> and B. Ahn<sup>2</sup>

<sup>1</sup>Youl Chon Chemical Co., Ltd, Korea, <sup>2</sup>Korea Advanced Institute of Science and Technology, Korea, <sup>3</sup>Korea Institute of Energy Research, Korea

#### 5P-P3-09 SYNTHESIS AND CHARACTERIZATION OF HIGH-QUALITY CUINS<sub>2</sub> AND CUINS<sub>2</sub>/ZNS (CORE/SHELL) LUMINESCENT NANOCRYSTALS

K. Kuo<sup>1</sup>, S. Chen<sup>1</sup> and B. Cheng<sup>2</sup>

<sup>1</sup>National Chiao Tung University Hsinchu, Taiwan, <sup>2</sup>National Synchrotron Radiation Research Center, Taiwan

#### 5P-P3-10 SOLVOTHERMAL SYNTHESIS OF CUINSE<sub>2</sub> AND CUINS<sub>2</sub> NANOPARTICLES FROM BINARY COMPOUND

Y. Liao and C. Ting

Industrial Technology Research Institute, Taiwan

#### 5P-P3-11 STUDY OF CUINS<sub>2</sub> THIN FILMS BY VACUUM ANNEALING TIMES MANUFACTURED FOR APPLICATION IN SOLAR CELL

H. Yang and G. Park

Mokpo National University, Korea

#### 5P-P3-12 EVALUATION OF CHALCOPYRITE I-III-VI<sub>2</sub> POWDERS PREPARED BY BALL-MILLING PROCESS

H. Miyazaki, M. Kubori, Y. Okamoto and J. Morimoto

National Defense Academy, Japan

**5P-P3-13 SOLVOTHERMAL SYNTHESIS OF COPPER INDIUM DISELENIDE WITH FACILE SOLUTION ROUTE**

J. Chang, H. Nam, J. Han and D. Jung  
Sungkyunkwan University, Korea

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**5P-P3-14 GROWTH CUINGASE CHALCOPYRITE STRUCTURE BY MAGNETRON SPUTTERING WITH ALLOY PRECURSOR**

Y. C. Shih<sup>1</sup>, G. S. Chen<sup>1</sup> and T. R. Huang<sup>2</sup>  
<sup>1</sup>Feng-Chia University, Taiwan, <sup>2</sup>PVT Solar Inc, Taiwan

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**5P-P3-15 PHOTOLUMINESCENCE STUDY OF CIGS THIN FILMS GROWN BY MECANOCHEMICAL PROCESS**

Y. Chiba<sup>1</sup>, A. Yamada<sup>1</sup>, M. Konagai<sup>1</sup>, Y. Matsuo<sup>2</sup> and T. Wada<sup>2</sup>  
<sup>1</sup>Tokyo Institute of Technology, Japan, <sup>2</sup>Ryukoku University, Japan

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**5P-P3-16 COMPOSITIONAL DEPENDENCE OF RAMAN SCATTERING AND PHOTOLUMINESCENCE EMISSION IN CU-GA-SE FILMS GROWN BY MOCVD**

M. Grossberg<sup>1</sup>, J. Krustok<sup>1</sup>, S. Siebentritt<sup>2</sup> and J. Albert<sup>3</sup>  
<sup>1</sup>Tallinn University of Technology, Estonia, <sup>2</sup>Université du Luxembourg, Luxembourg, <sup>3</sup>Hahn-Meitner Institut, Germany

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**5P-P3-17 BIFACIAL CIGS THIN FILM SOLAR CELLS USING HIGH MOBILITY Ti-DOPED In<sub>2</sub>O<sub>3</sub> BACK CONTACTS**

T. Miyano, R. Hashimoto, Y. Kanda, T. Mise and T. Nakada  
Aoyama Gakuin University, Japan

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**5P-P3-18 FABRICATION OF A CuInSe<sub>2</sub> *pn* JUNCTION PREPARED BY THERMAL DIFFUSION OF Zn USING DIMETHYLZINC**

A. Miyama<sup>1</sup>, T. Yasuniwa<sup>1</sup>, A. Umezawa<sup>1</sup>, H. Nakanishi<sup>1</sup>, M. Sugiyama<sup>1</sup> and S. F. Chichibu<sup>2</sup>  
<sup>1</sup>Tokyo University of Science, Japan, <sup>2</sup>Tohoku University, Japan

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**5P-P3-19 CIGS SOLAR CELLS ON STAINLESS STEEL SUBSTRATES COVERED WITH ZNO DIFFUSION BARRIERS**

C. Shi, Q. He, F. Li, J. Zhao, Y. Jiang, Z. Zhou, B. Li, T. Yu, C. Li and Y. Sun  
Nankai University, China

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**5P-P3-20 THE GROWTH OF MOLYBDENUM THIN FILMS WITH LOW RESISTIVITY AND LOW RESIDUAL STRESS BY DC-MAGNETRON SPUTTERING**

K. Lee, S. Yoon, T. Yoon, S. Yoon and J. Ha  
LG Chem, Ltd./Research Park, Korea

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**5P-P3-21 REDUCTION OF HETEROINTERFACE RECOMBINATION BY ZN<sub>1-x</sub>MG<sub>x</sub>O FOR WINDOW LAYER OF CU(IN,Ga)SE<sub>2</sub> SOLAR CELLS**

K. Tanaka, T. Minemoto and H. Takakura  
Ritsumeikan University, Japan

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**5P-P3-22 PREPARATION AND CHARACTERIZATION OF ZnS THIN FILMS ON SnO<sub>2</sub>/GLASS FOR THE BUFFER LAYER OF CIGS SOLAR CELLS BY THE CHEMICAL BATH DEPOSITION METHOD WITH SELF-CATALYST GROWTH PROCESS**

T. Iwashita and S. Ando  
Tokyo University of Science, Japan

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**5P-P3-23 ELECTRONIC STRUCTURES OF CUINSE<sub>2</sub> AND THE RELATED COMPOUNDS CALCULATED BY FIRST-PRINCIPLES SCREENED-EXCHANGE LDA METHOD**

T. Maeda and T. Wada  
Ryukoku University, Japan

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**5P-P3-24 NUMERICAL ANALYSIS OF THICKNESS AND TEMPERATURE EFFECT ON COPPER-INDIUM-SELENIUM (CIS) BASED SOLAR CELLS WITH VARIOUS BUFFER LAYERS**

N. Amin<sup>1</sup>, M. Tang<sup>2</sup> and K. Sopian<sup>1</sup>  
<sup>1</sup>National University of Malaysia, Malaysia, <sup>2</sup>Multimedia University, Malaysia

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**5P-P3-25 IMPACTS OF BAND ALIGNMENT ON PERFORMANCE OF Cu(In,Ga)Se<sub>2</sub> SOLAR CELLS**

C. Huang  
National Dong Hwa University, Taiwan

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**5P-P3-26 2-D DEVICE MODELLING AND FINITE ELEMENT SIMULATIONS FOR THIN-FILM SOLAR CELLS**

U. Malm and M. Edoff  
Uppsala University, Sweden

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**5P-P3-27** PREPARATION OF  $\text{Cu}_2\text{ZnSnS}_4$  THIN FILMS BY SULFURIZING ELECTROPLATED PRECURSORS

H. Araki, Y. Kubo, A. Mikaduki, K. Jimbo, W. S. Maw, H. Katagiri, M. Yamazaki, K. Oishi and A. Takeuchi  
Nagaoka National College of Technology, Japan

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**5P-P3-28** STRUCTURE AND PROPERTIES OF  $\text{Cu}(\text{InAl})\text{Se}_2$  THIN FILMS GROWN BY RF MAGNETRON SPUTTERING

B. Munir<sup>1,2</sup>, R. A. Wibowo<sup>2</sup> and K. Kim<sup>2</sup>  
<sup>1</sup>University of Indonesia, Indonesia, <sup>2</sup>Yeungnam University, Korea

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**5P-P3-29** EFFECT OF COMPOSITIONAL RATIO ON PROPERTIES OF  $\text{Cu}_2\text{ZnSnS}_4$  THIN FILM FABRICATED BY CO-EVAPORATION

T. Tnaka, K. Ikari, M. Nishio, Q. Guo and H. Ogawa  
Saga University, Japan

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**5P-P3-30** PREPARATION OF  $\text{Cu}_2\text{ZnSnS}_4$  THIN FILMS BY ANNEALING FROM  $\text{Zn/SnS}_2/\text{Cu}_2\text{S}$  STACKED LAYER IN SULFUR ATMOSPHERE

T. Yamaguchi<sup>1</sup>, K. Maeda<sup>1</sup>, T. Kubo<sup>1</sup>, S. Niyama<sup>2</sup>, T. Imanishi<sup>2</sup> and A. Wakahara<sup>3</sup>  
<sup>1</sup>Wakayama College of Technology, Japan, <sup>2</sup>Wakayama Industrial Technology Center, Japan, <sup>3</sup>Toyohashi University of Technology, Japan

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**5P-P3-31** STRUCTURE, ELECTRICAL AND OPTICAL PROPERTIES OF  $\text{Cu}_2\text{ZnSnSe}_4$  THIN FILM PREPARED BY PULSED LASER DEPOSITION

M. Yoon, R. A. Wibowo, B. Munir and K. Kim  
Yeungnam University, Korea

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**5P-P3-32** STOICHIOMETRIC CONTROL OF STANNITE-QUATERNARY  $\text{Cu}_2\text{ZnSnSe}_4$  THIN FILMS BY SPUTTERING METHOD

K. Kim, M. Yoon and R. A. Wibowo  
Yeungnam University, Korea

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**5P-P3-33** STRUCTURAL AND OPTICAL CHARACTERIZATION OF  $\text{AgGaSe}_2$  BULK CRYSTALS BY CHANGING  $\text{Ag/Ga}$  COMPOSITIONS.

A. Kinoshita<sup>1</sup>, S. Shirahata<sup>1</sup>, K. Yoshino<sup>1</sup>, T. Ikari<sup>1</sup>, H. Matsuo<sup>2</sup>, K. Kakimoto<sup>2</sup> and S. Seto<sup>3</sup>  
<sup>1</sup>Miyazaki Univ., Japan, <sup>2</sup>Kyusyu Univ., Japan, <sup>3</sup>Ishikawa National coll. Tech., Japan

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**5P-P3-34** PREPARATION AND PROPERTIES OF  $\text{CuAlSe}_2$  THIN FILMS

G. Cheng and B. Tseng  
National Sun Yat-Sen University, Taiwan

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**5P-P3-35** QUANTITATIVE ANALYSIS OF CELL TRANSPARENCY AND ITS IMPLICATIONS FOR THE DESIGN OF CHALCOPYRITE-BASED TANDEMS

M. Schmid<sup>1</sup>, R. Klenk<sup>2</sup> and M. Ch. Lux-Steiner<sup>1,2</sup>  
<sup>1</sup>Freie Universität Berlin, Germany, <sup>2</sup>Hahn-Meitner-Institut Berlin, Germany

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**5P-P3-36** CHEMICAL ETCHING OF  $\text{Cu}_2\text{ZnSnSe}_4$  MONOGRAIN POWDER

K. Timmo, M. Altosaar, J. Raudoja, K. Kerm, M. Grossberg and E. Mellikov  
Tallinn University of Technology, Estonia

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**5P-P3-37** HIGH-MOBILITY Ti-DOPED  $\text{In}_2\text{O}_3$  (ITiO) THIN FILMS DEPOSITED BY SPUTTERING/POST-ANNEALING TECHNIQUE

R. Hashimoto<sup>1</sup>, Y. Kanda<sup>1</sup>, Y. Abe<sup>2</sup> and T. Nakada<sup>1</sup>  
<sup>1</sup>Aoyama Gakuin University, Japan, <sup>2</sup>Sumitomo Metal Mining Co., Ltd., Japan

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**5P-P3-38** NIOBIUM-DOPED ANATASE TITANIUM OXIDE TRANSPARENT CONDUCTING FILMS

N. Yamada<sup>1</sup>, N. L. H. Hoang<sup>1,2</sup>, J. Kasai<sup>1</sup>, T. Hitosugi<sup>1,2</sup>, T. Shimada<sup>1,2</sup> and T. Hasegawa<sup>1,2</sup>  
<sup>1</sup>Kanagawa Academy of Science and Technology (KAST), Japan, <sup>2</sup>University of Tokyo, Japan

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**5P-P3-39** ANNEALING EFFECTS OF ELECTRICAL CHARACTERIZATION ON  $\text{ZnO}$  THIN FILMS

S. Oyama<sup>1</sup>, M. Kato<sup>1</sup>, M. Oshima<sup>1</sup>, K. Yoshino<sup>1</sup>, T. Ikari<sup>1</sup> and M. Yoneta<sup>2</sup>  
<sup>1</sup>University of Miyazaki, Japan, <sup>2</sup>Okayama University of Science, Japan

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**5P-P3-40** OPTICAL PROPERTY OF IN-DOPED MGZNO/GLASS TOWARD TRANSPARENT CONDUCTIVE OXIDE MATERIALS

M. Shintani<sup>1</sup>, M. Yoneta<sup>1</sup>, K. Yoshino<sup>2</sup>, M. Li<sup>1</sup>, Y. Sato<sup>1</sup>, M. Ohishi<sup>1</sup> and K. Ohmori<sup>1</sup>

<sup>1</sup>Okayama University of Science, Japan, <sup>2</sup>Miyazaki University, Japan

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**5P-P3-41** TRANSPARENT ZNO THIN FILM PREPARATION BY ANODIZATION

S. Nakamura and Y. Okamoto

Tsuyama National College of Technology, Japan

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**5P-P3-42** PHOTOCONDUCTIVITY OF SOLUTION-PROCESSED MERCURY TELLURIDE NANOPARTICLE THIN FILMS FABRICATED ON GLASS SUBSTRATES

H. Seong, K. Cho and S. Kim

Korea University, Korea

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**5P-P3-43** EFFECT OF CdCl<sub>2</sub> TREATMENT ON STRUCTURE AND PHOTOLUMINESCENCE OF CdTe FILMS WITH DIFFERENT COMPOSITIONS FABRICATED BY CMBD

T. M. Razykov<sup>1,3</sup>, G. Contreras-Puente<sup>2</sup>, G. C. Chornokur<sup>3</sup>, M. Dybjec<sup>3</sup>, Yu. Emirov<sup>3</sup>, B. Ergashev<sup>1</sup>, C. S. Ferekides<sup>3</sup>, D. Y. Goswami<sup>3</sup>, A. Hubbimov<sup>1</sup>, B. Ikramov<sup>1</sup>, K. M. Kouchkarov<sup>1</sup>, X. Mathew<sup>4</sup>, D. Morel<sup>3</sup>, S. Ostapenko<sup>3</sup>, E. Sanchez-Meza<sup>2</sup>, E. Stefanakos<sup>3</sup>, O. Vigil-Galan<sup>2</sup>, Yu. V. Vorobiev<sup>5</sup> and H. Zhao<sup>3</sup>

<sup>1</sup>Physical-Technical Institute, Uzbekistan, <sup>2</sup>National Polytechnic Institute, Mexico, <sup>3</sup>University of South Florida, USA, <sup>4</sup>CIE-UNAM, Mexico, <sup>5</sup>CINVESTAV, IPN, Mexico

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**5P-P3-44** BAND GAP ENGINEERING OF RF SPUTTERED CUINZSE<sub>2</sub> THIN FILMS FOR INDIUM-REDUCED THIN FILM SOLAR CELL APPLICATION

R. A. Wibowo and K. Kim

Yeungnam University, Korea

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**5P-P3-45** SYNTHESIS OF NANOSTRUCTURED CADMIUM SULFIDE TEMPLATED BY MESOPOROUS SILICA BY ELECTRODEPOSITION

K. Kim, H. Noh, J. Lee and D. Kim

Korea University, Korea

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**5P-P3-46** 8 MEV ELECTRON IRRADIATION STUDIES ON THE CDTE /CDS SOLAR CELLS

U. P. Singh

KIIT University, India

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**5P-P3-47** PREPARATION AND CHARACTERIZATION OF (CU,AG)INSE<sub>2</sub> FILMS BY A COMBINATION OF MECHANOCHEMICAL AND SCREEN PRINTING/SINTERING

S. Nomura<sup>1</sup>, Y. Matsuo<sup>1</sup>, T. Wada<sup>1</sup>, Y. Chiba<sup>2</sup>, A. Yamada<sup>3</sup> and M. Konagai<sup>2</sup>

<sup>1</sup>Ryukoku University, Japan, <sup>2</sup>Tokyo Institute of Technology, Japan, <sup>3</sup>Tokyo Institute of Technology, Japan

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**5P-P3-48** A STUDY ON PROPERTIES OF CUINSE<sub>2</sub> THIN FILMS BY SUBSTRATE TEMPERATURE AND ANNEALING TEMPERATURE

**Late News** H. Yang, Y. Kim, W. Jeong and G. Park

Mokpo National Univ., Korea

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**5P-P3-49** PREPARATION AND PERFORMANCE OF THIN FILM CDTE MINI-MODULE

**Late News** J. Zhang, L. Feng, Z. Lei, Y. Cai, W. Li, L. Wu, B. Li, W. Cai and J. Zheng

Sichuan University, China

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**5P-P3-50** THE FERROMAGNETISM AND INTERMEDIATE BAND STRUCTURE OF AN IRON IMPLANTED DOPED CUINSE<sub>2</sub> THIN FILM

**Late News** C. Lee<sup>1</sup>, L. Liu<sup>1</sup> and B. Tseng<sup>2</sup>

<sup>1</sup>National Tsing Hua University, Taiwan, <sup>2</sup>National Sun Yat-Sen University, Taiwan

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## Area 8

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### 5P-P3-51 RENEWABLE ENERGY GRID INTEGRATION – DISTRIBUTED PHOTOVOLTAIC STUDIES

D. Ton<sup>1</sup>, B. Kroposki<sup>2</sup>, R. Margolis<sup>2</sup>, J. Torres<sup>3</sup>, G. Kuswa<sup>3</sup> and T. Key<sup>4</sup>

<sup>1</sup>US Department of Energy, USA, <sup>2</sup>National Renewable Energy Laboratory, USA, <sup>3</sup>Sandia National Laboratories, USA, <sup>4</sup>Electric Power Research Institute, USA

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### 5P-P3-52 ELECTRIC UTILITY METERING AND INTERCONNECTION POLICIES FOR PHOTOVOLTAIC SYSTEMS IN THE UNITED STATES

M. Taylor<sup>1</sup>, S. Letendre<sup>2</sup> and Rusty Haynes<sup>3</sup>

<sup>1</sup>Solar Electric Power Association, USA, <sup>2</sup>Green Mountain College, USA, <sup>3</sup>Interstate Renewable Energy Council, USA

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### 5P-P3-53 IMPACT EVALUATION OF THE CHINESE BRIGHTNESS-PROGRAM IMPLEMENTED DURING 1996-2006

F. Haugwitz

Deutsche Gesellschaft für Technische Zusammenarbeit, China

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### 5P-P3-54 SOCIO-ECONOMIC IMPACT MONITORING OF RURAL ELECTRIFICATION PROJECTS IN YUNNAN, GANSU, QINGHAI TIBET AUTONOMOUS REGION - A CHINA CASE STUDY

F. Haugwitz

Deutsche Gesellschaft für Technische Zusammenarbeit, China

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### 5P-P3-55 DEVELOPMENT OF PHOTOVOLTAICS (2006) IN THE EUROPEAN UNION NEW MEMBER STATES

S. M. Pietruszko

Warsaw University of Technology, Poland

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### 5P-P3-56 FEED-IN TARIFF: THE BEST MARKET SUPPORT MECHANISM

S. M. Pietruszko

Warsaw University of Technology, Poland

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### 5P-P3-57 AWAKENING PV IN MEXICO

Y. Matsumoto<sup>1</sup>, J. Agredano<sup>2</sup>, A. Sánchez<sup>3</sup> and J. A. Urbano<sup>1</sup>

<sup>1</sup>CINVESTAV-IPN, Mexico, <sup>2</sup>IIE, Mexico, <sup>3</sup>CIE-UNAM, Mexico

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### 5P-P3-58 ANALYSIS OF DISSEMINATION ACCELERATION POLICY FOR RESIDENTIAL PV SYSTEMS IN JAPAN

E. Endo

National Institute of Advanced Industrial Science and Technology (AIST), Japan

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### 5P-P3-59 KOREA'S SOLAR ENERGY DEVELOPMENT PLAN AND INCENTIVE SYSTEM OF CDM & SRI

J. Lee

Myongji University, Korea

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### 5P-P3-60 PV RESOURCES ANALYSIS IN WORLD SIX DESERTS WITH DETECTING SEASONAL DIFFERENCES AMONG SATELLITE IMAGES

Y. Hamano<sup>1</sup>, M. Ito<sup>2</sup> and K. Kurokawa<sup>1</sup>

<sup>1</sup>Tokyo University of Agriculture and Technology, Japan, <sup>2</sup>Tokyo Institute of Technology, Japan

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### 5P-P3-61 withdrawn

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### 5P-P3-62 withdrawn

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### 5P-P3-63 FEASIBILITY STUDY OF PV-BASED EMERGENCY MICROGRID

T. Kato<sup>1</sup>, Y. Kondo<sup>1</sup>, Y. Suzuoki<sup>1</sup> and T. Funabashi<sup>2</sup>

<sup>1</sup>Nagoya University, Japan, <sup>2</sup>Meidensha Corporation, Japan

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**5P-P3-64** PHOTOVOLTAICS EDUCATION OUTREACH TO THE ASIA-PACIFIC REGION

R. Corkish

The University of New South Wales, Australia

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**5P-P3-65** HOW PARTICIPATORY PRODUCT DESIGN AND MICRO-ENTREPRENEURSHIP FAVOR THE DISSEMINATION OF PHOTOVOLTAIC SYSTEMS IN CAMBODIA

A. Reinders<sup>1</sup>, H. de Gooijer<sup>2</sup> and J. C. Diehl<sup>3</sup>

<sup>1</sup>University of Twente, The Netherlands, <sup>2</sup>KamWorks, Cambodia, <sup>3</sup>Delft University of Technology, The Netherlands

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**5P-P3-66** DEVELOPMENT OF LONG-TERM PV-MICRO-HYDRO HYBRID SYSTEM MANAGEMENT MODULE TO DISTRIBUTE OF KNOWLEDGE TO HILL TRIBE

K. Chomsuwan, P. Chaiprasit, R. Watchanakunant, B. Petcharanond, S. Tanchareon and S. Tia

King Mongkut's University of Technology Thonburi, Thailand

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**5P-P3-67** COST-EFFECTIVENESS OF SOLAR MODULES ON THE INTERNATIONAL PHOTOVOLTAIC MARKET

Y. Maruoka

Doitsu Giken Ltd., Japan

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**5P-P3-68** withdrawn

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**5P-P3-69** A COST ANALYSIS OF CO<sub>2</sub> REDUCTION BY UTILIZING LARGE-SCALE PV SYSTEMS IN JAPAN

M. Ito<sup>1</sup>, Y. Tsuno<sup>2</sup> and K. Kurokawa<sup>2</sup>

<sup>1</sup>Tokyo Institute of Technology, Japan, <sup>2</sup>Tokyo University of Agriculture and Technology, Japan

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**5P-P3-70** ADVERSE HEALTH EFFECTS OF CIGS PARTICLES AFTER INTRATRACHEAL INSTILLATIONS INTO THE LUNG OF RATS

A. Tanaka, M. Hirata, Y. Kiyohara, M. Shiratani and K. Koga

Kyushu University, Japan

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**5P-P3-71** DESIGN AND ECONOMIC ANALYSIS OF A STAND-ALONE PV SYSTEM TO ELECTRIFY A REMOTE AREA HOUSEHOLD IN EGYPT

A. E. A. Nafeh

Electronics Research Institute, Egypt

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**5P-P3-72** A METHOD OF ESTIMATION OF CO<sub>2</sub> EMISSION WITH REFERENCE TO BIPV STRUCTURE IN SOUTHEAST ASIA

T. Moyra<sup>1</sup>, A. Majumder<sup>2</sup> and D. Mukherjee<sup>1</sup>

<sup>1</sup>Bengal Engineering & Science University, India, <sup>2</sup>West Bengal Renewable Energy Development Agency, India

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**5P-P3-73** RECENT STATUS AND FUTURE PROSPECTS OF PHOTOVOLTAICS IN TUNISIA

**Late News** R. Andoulsi<sup>1</sup>, A. El Kazen<sup>2</sup>, A. Boutouta<sup>3</sup>, A. Ounalli<sup>2</sup>, B. Bessais<sup>1</sup> and K. Kurokawa<sup>4</sup>

<sup>1</sup>Research and Technology Centre of Energy, Tunisia, <sup>2</sup>Ministry of Industry, Tunisia, <sup>3</sup>Ministry of Agriculture and Water Exploitation, Tunisia, <sup>4</sup>Tokyo University of Agriculture and Technology, Japan

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**5P-P3-74** RAPID DEVELOPMENT OF PV INDUSTRY IN SHANGHAI AND CHINA

**Late News** G. Wei

Shanghai University, China

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**5P-P3-75** ECONOMIC ANALYSIS OF A GRID CONNECTED SOLAR HYDROGEN PV SYSTEM

**Late News** T. Marnoto, W. R. W. Daud, K. Sopian, M. N. Ab Rahman, R. Zulkifli, M. AIGHoul and N. Amin

Universiti Kebangsaan Malaysia, Malaysia

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**5P-P3-76** FINANCING A VERY LARGE SCALE PHOTOVOLTAIC SYSTEM IN GOBI DESERT

**Late News** K. Megherbi<sup>1</sup>, M. Ito<sup>2</sup>, F. D. Ferretti<sup>1</sup> and K. Kurokawa<sup>3</sup>

<sup>1</sup>Dexia Credit Local, France, <sup>2</sup>Tokyo Institute of Technology, Japan, <sup>3</sup>Tokyo University of Agriculture and Technology, Japan

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## Poster Session 4

December 5th, Wednesday 16:00-17:30 Room: Poster I (5th Floor)

Area 2: III-V Materials and Devices for Concentrator and Space PV Systems / Area 6: PV Modules and System Components

### Area 2

**5P-P4-01** ACCEPTOR LEVELS AND CONCENTRATIONS IN GAASN THIN FILMS GROWN BY CHEMICAL BEAM EPITAXY

H. Suzuki, K. Nishimura, K. Saito, T. Hashiguchi, Y. Ohshita, N. Kojima and M. Yamaguchi  
Toyota Technological Institute, Japan

**5P-P4-02** MODELING OF MULTILAYERED QUANTUM WELL PHOTOVOLTAIC CELLS

V. Iancu and L. Fara  
POLITEHNICA University of Bucharest, Romania

**5P-P4-03** THE EFFECT OF RESIDUAL IMPURITIES ON ACCEPTOR CONCENTRATION IN GAASN FILMS GROWN BY CHEMICAL BEAM EPITAXY

K. Nishimura, H. Suzuki, K. Saito, Y. Ohshita, N. Kojima and M. Yamaguchi  
Toyota Technological Institute, Japan

**5P-P4-04** IMPURITIES REDUCTION IN GAASN THIN FILMS BY FLOW RATE MODULATED CHEMICAL BEAM EPITAXY

K. Saito, K. Nishimura, H. Suzuki, Y. Ohshita, N. Kojima and M. Yamaguchi  
Toyota Technological Institute, Japan

**5P-P4-05** MOVPE GROWTH OF In-RICH InAlN FOR InAlN TANDEM SOLAR CELL

Y. Houchin, A. Hashimoto and A. Yamamoto  
University of Fukui, Japan

**5P-P4-06** MOVPE GROWTH AND Mg-doping of  $\text{In}_x\text{Ga}_{1-x}\text{N}$  ( $x \sim 0.4$ ) FOR TANDEM SOLAR CELL

M. Horie, K. Sugita, A. Hashimoto and A. Yamamoto  
University of Fukui, Japan

**5P-P4-07** INCREASED PHOTOABSORPTION IN STRAIN-COMPENSATED QUANTUM DOT SOLAR CELLS

R. Oshima, A. Takata and Y. Okada  
University of Tsukuba, Japan

**5P-P4-08** OPTIMIZATION OF STACKING HIGH-DENSITY QUANTUM DOT MOLECULES FOR PHOTOVOLTAIC EFFECT

K. Laouthaiwattana, O. Tangmattajittakul, S. Suraprapapich, S. Thainoi, P. Changmuang, S. Kanjanachuchai, S. Ratanathamphan and S. Panyakeow  
Chulalongkorn University, Thailand

**5P-P4-09** INFLUENCE OF LOCALIZED STATES IN OPTICAL PROPERTIES OF GAASN FILMS

B. Balamurugan, K. Nishimura, H. Suzuki, Y. Ohshita, and M. Yamaguchi  
Toyota Technological Institute, Japan

**5P-P4-10** RF-MBE GROWTH OF In-RICH InGaN FOR TANDEM SOLAR CELL

A. Hashimoto, K. Iwao and A. Yamamoto  
University of Fukui, Japan

**5P-P4-11** NOVEL PV DEVICE DIRECTLY EIMITTING LASER BEAM USING III-V MATERIALS FOR SPACE SOLAR POWER SYSTEM

K. Fujita<sup>1</sup>, M. Kobayashi<sup>2</sup>, H. Ohta<sup>3</sup>, H. Furukawa<sup>4</sup> and M. Niino<sup>5</sup>

<sup>1</sup>The Graduate school for the Creation of New Photonics Industries, Japan, <sup>2</sup>Waseda University, Japan, <sup>3</sup>Hamamatsu Photonics K.K., Japan, <sup>4</sup>Institute for Laser Engineering, Japan, <sup>5</sup>Japan Aerospace Exploration Agency, Japan

**5P-P4-12** AN APPROACH FOR DESIGNING AND OPTIMIZING ADVANCED MULTI-JUNCTION PHOTOVOLTAIC DEVICES FOR SPACE APPLICATIONS

S. Michael  
Naval Postgraduate School, USA



**5P-P4-13 FUNDAMENTAL PROPERTIES OF EPITAXIAL ALINN SEMICONDUCTORS**

Q. Guo, T. Tanaka, M. Nishio and H. Ogawa  
Saga University, Japan

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**5P-P4-14 FIELD TEST OF A GRID-CONNECTED 500X CONCENTRATOR PV SYSTEM WITH DOME FRESNEL LENS**

Y. Kemmoku<sup>1</sup>, K. Araki<sup>2</sup>, Y. Miyazaki<sup>3</sup> and M. Hiramatsu<sup>3</sup>  
<sup>1</sup>Toyohashi Sozo University, Japan, <sup>2</sup>Daido Steel Co. Ltd., Japan, <sup>3</sup>Daido Metal Co. Ltd., Japan

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**5P-P4-15 OVERCOMING SOLAR ARRAY ANOMALIES WITH THE STRETCHED LENS ARRAY (SLA)**

H. W. Brandhorst<sup>1</sup>, J. A. Rodiek<sup>1</sup> and M. J. O'Neill<sup>2</sup>  
<sup>1</sup>Space Research Institute, USA, <sup>2</sup>ENTECH Inc., USA

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**5P-P4-16 ACHIEVEMENT OF THE REGIONAL CONSORTIUM PROJECT IN JAPAN ON CPV SYSTEM DEVELOPMENT**

K. Araki<sup>1</sup>, M. Hiramatsu<sup>2</sup>, Y. Miyazaki<sup>2</sup>, T. Ito<sup>3</sup>, S. Yamamoto<sup>3</sup>, S. Kobayashi<sup>4</sup>, K. Yamauchi<sup>4</sup>, M. Tanemura<sup>5</sup>, M. Lei<sup>6</sup>, A. Akisawa<sup>7</sup>, Y. Kemmoku<sup>8</sup>, N. Kojima<sup>9</sup>, S. Kato<sup>10</sup>, A. Nishimura<sup>10</sup>, S. Tanemura<sup>6</sup> and M. Yamaguchi<sup>9</sup>  
<sup>1</sup>Daido Steel, Japan, <sup>2</sup>Daido Metal, Japan, <sup>3</sup>Ishizuka Glass, Japan, <sup>4</sup>Roofing Technology Laboratory, Japan, <sup>5</sup>Nagoya Institute of technology, Japan <sup>6</sup>Japan Fine Ceramics Center, Japan, <sup>7</sup>Tokyo University of Agriculture and Technology, Japan, <sup>8</sup>Toyohashi SOZO College, Japan, <sup>9</sup>Toyota Technological Institute, Japan, <sup>10</sup>Mie University, Japan

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**5P-P4-17 WHAT IS THE MAXIMUM CONCENTRATION RATIO TO PRACTICAL TERRESTRIAL PV SYSTEMS**

K. Araki  
Daido Steel, Japan

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**5P-P4-18 DESIGN OPTIMIZATION OF THE PARALLEL-LINE TRACKING FOR ROOFTOP CPV APPLICATIONS**

K. Araki  
Daido Steel, Japan

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**5P-P4-19 ANALYSIS OF THE SHADOW FROM BUILDING FAÇADES ONTO SPECTRUM SENSITIVE III-V CONCENTRATOR PV SYSTEMS**

K. Araki  
Daido Steel, Japan

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**5P-P4-20 PMMA NON-IMAGE FRESNEL LENS ARRAY FABRICATED USING AN INJECTION-MOLDED TECHNIQUE**

H. Hong, K. Kuo, H. Shin and C. Kuo  
Institute of Nuclear Energy Research, Taiwan

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**5P-P4-21 DEVELOPMENT OF TRACKING SYSTEM FOR 500X CONCENTRATOR PV MODULE WITH DOME FRESNEL LENS**

M. Hiramatsu<sup>1</sup>, Y. Miyazaki<sup>1</sup>, Y. Kato<sup>1</sup>, T. Marumo<sup>1</sup> and Y. Kemmoku<sup>2</sup>  
<sup>1</sup>Daido Metal Co. Ltd., Japan, <sup>2</sup>Toyohashi Sozo University, Japan

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**5P-P4-22 A STUDY ON CONTINUOUS FABRICATION OF FRESNEL LENS FOR CONCENTRATING SOLAR POWER GENERATION**

C. Yike  
Huaqiao University, China

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**5P-P4-23 ESD GROUND TESTS USING LARGE-SCALE SOLAR PANELS IN LEO PLASMA ENVIRONMENT**

H. Mashidori<sup>1</sup>, S. Kawakita<sup>1</sup>, K. Nitta<sup>1</sup> and K. Toyoda<sup>2</sup>  
<sup>1</sup>Japan Aerospace Exploration Agency (JAXA), Japan, <sup>2</sup>Kyushu Institute of Technology, Japan

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**5P-P4-24 RECONSIDERATION OF ELECTRON IRRADIATION TEST METHODS FOR THE EVALUATION OF SPACE SOLAR CELLS**

T. Ohshima<sup>1</sup>, S. Sato<sup>1</sup>, H. Miyamoto<sup>1,2</sup>, M. Imaizumi<sup>3</sup>, H. Hanaya<sup>1</sup> and K. Kawano<sup>2</sup>  
<sup>1</sup>Japan Atomic Energy Agency (JAEA), Japan, <sup>2</sup>The Univ. of Electro-Communications, Japan, <sup>3</sup>Japan Aerospace Exploration Agency (JAXA), Japan

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**5P-P4-25 ANALYSIS FOR RADIATION-RESISTANCE OF INGAP SUB-CELLS**

M. Yamaguchi<sup>1</sup>, N. J. Ekins-Daukes<sup>1</sup>, H. S. Lee<sup>1</sup>, M. Imaizumi<sup>2</sup>, T. Takamoto<sup>3</sup> and T. Ohshima<sup>4</sup>  
<sup>1</sup>Toyota Technological Institute, Japan, <sup>2</sup>Japan Aerospace Exploration Agency, Japan, <sup>3</sup>Sharp Corporation, Japan, <sup>4</sup>Japan Atomic Energy Research Institute, Japan

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**5P-P4-26** RESULTS OF CELL DURABILITY TESTS FOR JAXA'S HIHT PROJECTS, VENUS AND MERCURY EXPLORATION MISSIONS

M. Imaizumi, H. Toyota, H. Ogawa and M. Tajima  
Japan Aerospace Exploration Agency (JAXA), Japan

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**5P-P4-27** EFFECTS OF IRRADIATION TEMPERATURE ON THE DEGRADATION OF ELECTRICAL CHARACTERISTICS OF InGaP SOLAR CELLS

H. Miyamoto<sup>1,2</sup>, S. Sato<sup>2</sup>, T. Ohshima<sup>2</sup>, C. Morioka<sup>3</sup>, M. Imaizumi<sup>3</sup> and K. Kawano<sup>1</sup>  
<sup>1</sup>UEC, Japan, <sup>2</sup>JAEA, Japan, <sup>3</sup>JAXA, Japan

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**5P-P4-28** EFFECT OF IRRADIATION BEAM CONDITIONS ON RADIATION DEGRADATION OF SOLAR CELLS

M. Saito<sup>1</sup>, M. Imaizumi<sup>2</sup>, T. Ohshima<sup>3</sup> and Y. Ito<sup>4</sup>  
<sup>1</sup>Advanced Engineering Services (AES), Japan, <sup>2</sup>Japan Aerospace Exploration Agency (JAXA), Japan, <sup>3</sup>Japan Atomic Energy Agency (JAEA), Japan,  
<sup>4</sup>Wakasawan Energy Research Center (WERC), Japan

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**5P-P4-29** IDENTIFICATION OF SUITABLE SITE FOR SOLAR POWER SATELLITE IN INDIA AND COMPARISON OF LEO SSPS AND GEO SSPS

K. Chaudhary  
Banaras Hindu University, India

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**5P-P4-30** DIAGNOSIS OF SPACE SOLAR CELLS BY ELECTROLUMINESCENCE AND PHOTOLUMINESCENCE IMAGING

**Late News** H. Toyota<sup>1</sup>, M. Imaizumi<sup>2</sup>, Y. Nozaki<sup>3</sup> and M. Tajima<sup>1</sup>  
<sup>1</sup>ISAS/JAXA, Japan, <sup>2</sup>IAT/JAXA, Japan, <sup>3</sup>NT Space, Japan

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## Area 6

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**5P-P4-31** COMPARING THE EFFICIENCY OF TRACKING SOLAR CELL PANELS IN A TROPICAL LOCATION

P. Jumrusprasert, G. Smith and Leslie Kirkup  
UTS, Australia

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**5P-P4-32** IN-SITU SERIES CONNECTION OF FLEXIBLE SOLAR CELLS

R. Merz, M. B. Schubert, G. Bilger and J. H. Werner  
Universität Stuttgart, Germany

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**5P-P4-33** HIGH-EFFICIENCY, 0.8 M<sup>2</sup> THIN-FILM SI MODULES FABRICATED BY A BATCH PROCESS

P. Krudtad, P. Chinnavornrungeee, N. Udomdachanut, W. Tachakittiroje, C. Piromjit, N. Pingate and P. Sichanugrist  
National Science and Technology Development Agency, Thailand

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**5P-P4-34** AMORPHOUS THIN FILM ASSEMBLED SPHERICAL SOLAR CELL MODULE

K. Kawano<sup>1</sup>, M. Kaminaga<sup>1</sup>, K. Sakamoto<sup>1</sup> and K. Sasano<sup>2</sup>  
<sup>1</sup>The University of Electro-Communications, Japan, <sup>2</sup>Asahi National Broadcasting Co., Japan

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**5P-P4-35** DYNAMIC CHARACTERIZATION OF POWER CONDITIONER WITH *I*-*V* CURVE FILL FACTOR OF SOLAR CELL

Y. Hirata and T. Tani  
Tokyo University of Science, Suwa, Japan

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**5P-P4-36** EXPERIMENTAL STUDIES ON DETECTING A DISCONNECTION POSITION OF BETWEEN PV MODULES BY THE ELECTRIC CAPACITANCE MEASUREMENT

J. Yamaguchi<sup>1</sup>, T. Takashima<sup>2</sup> and M. Ishida<sup>1</sup>  
<sup>1</sup>University of Tsukuba, Japan, <sup>2</sup>AIST, Japan

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**5P-P4-37** ANALYSIS OF TEMPERATURE HISTORY OF AMORPHOUS SILICON PHOTOVOLTAIC MODULES IN OUTDOOR

S. Fukushige, K. Ichida, T. Minemoto and H. Takakura  
Ritsumeikan University, Japan

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**5P-P4-38** IMPACT OF ENVIRONMENT FACTORS ON SOLAR CELL PARAMETERS OF A-SI// $\mu$ C-SI PHOTOVOLTAIC MODULES

K. Ichida<sup>1</sup>, S. Fukushige<sup>1</sup>, A. Nakajima<sup>2</sup>, T. Minemoto<sup>1</sup> and H. Takakura<sup>1</sup>  
<sup>1</sup>Ritsumeikan University, Japan, <sup>2</sup>Kaneka Corporation, Japan

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**5P-P4-39** PV MODULE LOADING SYSTEM FOR OUTDOOR MODULE TESTING BASED ON PROGRAMMABLE LOAD AND CALIBRATED IRRADIATION SENSOR

A. Jagomägi  
Tallinn University of Technology, Estonia

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**5P-P4-40** EXPERIMENTAL RESULTS ON MODULE CHARACTERISATION FOR HOT-SPOT PROTECTION

M. C. Alonso-García<sup>1</sup>, F. Chenlo<sup>1</sup> and P. Sánchez-Friera<sup>2</sup>  
<sup>1</sup>CIEMAT, Spain, <sup>2</sup>ISOFOFOTON, Spain

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**5P-P4-41** THE EFFECTS OF TEMPERATURE AND SOLDERS ON THE WETTABILITY BETWEEN RIBBON AND SOLAR CELL

H. Hsieh, F. Lin, F. Yeh and M. Lin  
Industrial Technology Research Institute, Taiwan

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**5P-P4-42** A STUDY ON RELIABILITY ALLOCATION IN HCPV SYSTEM DESIGN

G. Lee<sup>1</sup>, J. Chen<sup>1</sup>, H. Lin<sup>1</sup>, T. Yu<sup>1</sup> and C. Ma<sup>2</sup>  
<sup>1</sup>Vanung University, Taiwan, <sup>2</sup>Nuclear Instrumentation Division, Taiwan

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**5P-P4-43** MULTI-LASER LBIC SYSTEM FOR THIN FILM PV MODULE CHARACTERISATION

P. Vorasayan, T.R. Betts, R. Gottschalg and A.N. Tiwari  
Loughborough University, UK

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**5P-P4-44** PRESUMPTIVE TECHNIQUE OF POWER GENERATION OF AMORPHOUS SILICON CELL INCLUDING VARIOUS FACTORS

E. Hirose, K. Fujiwara, Y. Ishihara and T. Todaka  
Doshisha University, Japan

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**5P-P4-45** VOLTAGE AND FREQUENCY DEPENDENT MODEL FOR PV MODULE DYNAMIC IMPEDANCE

T. Chayavanich, C. Limsakul, N. Chayavanich, D. Chenvidhya, C. Jivacate and K.Kirtikara  
King Mongkut's University of Technology Thonburi (KMUTT), Thailand

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**5P-P4-46** EVALUATION OF CURVE TRANSLATION PROCEDURES FOR CURRENT VOLTAGE CHARACTERISTICS OF PHOTOVOLTAIC DEVICES

K. Harvey, T. R. Betts and R. Gottschalg  
Loughborough University, UK

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**5P-P4-47** CORRELATION BETWEEN ELECTRICAL PARAMETERS OF SOLAR CELLS AND TEMPERATURE CHARACTERISTICS OBTAINED FROM INFRARED THERMOGRAPHY

P. Parinya, B. Wiengmoon, D. Chenvidhya, C. Jivacate, K. Kirtikara and C. Limsakul  
King Mongkut's University of Technology Thonburi, Thailand.

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**5P-P4-48** SPECTRAL RESPONSE MEASUREMENTS OF PV MODULES

Y. Hishikawa<sup>1</sup>, Y. Tsuno<sup>1,2</sup> and K. Kurokawa<sup>2</sup>

<sup>1</sup>National Institute of Advanced Industrial Science and Technology (AIST), Japan, <sup>2</sup>Tokyo University of Agriculture and Technology, Japan

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**5P-P4-49** NI SPEEDY 33 – BASED SOLAR INTEGRATOR

K. Tunlasakun  
KMUTT, Thailand

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**5P-P4-50** COST EFFICIENT AUTOMATED SUNLIGHT TRACKER FOR HIGHER POWER YIELD OF THE LARGE AREA SOLAR PV POWER STATIONS

N. Amin<sup>1</sup>, L. Yi<sup>2</sup> and K. Sopian<sup>3</sup>

<sup>1</sup>National University of Malaysia, Malaysia, <sup>2</sup>Multimedia University, Malaysia, <sup>3</sup>National University of Malaysia, Malaysia

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**5P-P4-51** A STUDY OF PHOTOVOLTAIC/THERMAL SYSTEM IN THAI HOSPITAL

K. Chumpolrat, T. Nualboonrueng and P. Sichanugrist  
National Science and Technology Development Agency, Thailand

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**5P-P4-52** RESEARCH ABOUT THE 500W C-SI PV & PEMFC HYBRID SYSTEM WITH LABVIEW

J. P. Yoon<sup>1</sup>, I. S. Cha<sup>2</sup>, J. S. Choi<sup>2</sup> and D. M. Kim<sup>2</sup>

<sup>1</sup>Fusion Information Tech. Co. Ltd., Korea, <sup>2</sup>Dongshin Univ., Korea

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**5P-P4-53** MANUFACTURING OF LARGE AREA FLEXIBLE SOLAR CELL MODULES ACCORDING TO THE NUON HELIANTHOS PROCESS

**Late News** J. M. T. Lenssen, E. A. G. Hamers, G. C. Dubbeldam, J. Winkeler, E. Sportel, W. Scheerder, S. Broekhof, A. Borreman, S. Perin, R. Schlatmann, L. A. Stigter and G. J. Jongerden  
Nuon Helianthos, The Netherlands

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**5P-P4-54** VERIFICATION OF CHANGING INTO STATE OF ASYNCHRONOUS INDUCTION GENERATOR OF INDUCTION MOTORS

**Late News** H. Igarashi, K. Miyamoto and K. Kurokawa

<sup>1</sup>Japan Electrical Safety & Environment Technology Laboratories., Japan, <sup>2</sup>Tokyo University of Agriculture and Technology, Japan

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# Poster Session 5

December 6th, Thursday 11:00-12:30 Room: Poster I (5th Floor)

Area 1: Novel Materials and Devices / Area 4: Amorphous & Nano/Microcrystalline Silicon Based Solar Cells and Related Materials

## Area 1

- 
- 6P-P5-01** INVESTIGATION ON THE RELATIONSHIP BETWEEN MICROSTRUCTURE AND PERFORMANCE OF ZINC OXIDE/N-719 PHOTOANODES  
M. Saito, K. Kakiuchi and S. Fujihara  
Keio University, Japan
- 
- 6P-P5-02** FABRICATION OF NANOPOROUS ZINC OXIDE ELECTRODES BY CHEMICAL BATH DEPOSITION FOR EFFICIENT DYE-SENSITIZED SOLAR CELLS  
S. Ueno, M. Saito and S. Fujihara  
Keio University, Japan
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- 6P-P5-03** FABRICATION OF DYE SENSITIZED SOLAR CELL USING ANODIC ALUMINUM OXIDE  
T. Lee, P. Alegaonkar and J. Yoo  
Sungkyunkwan University, Korea
- 
- 6P-P5-04** IMPEDANCE SPECTROSCOPY ON DYE-SENSITIZED SOLAR CELLS USING PEDOT:PSS COUNTER ELECTRODE AND POLYMER ELECTROLYTES  
S. Park<sup>1</sup>, Y. Cho<sup>1</sup>, K. Jung<sup>2</sup>, H. Lee<sup>2</sup>, J. Lee<sup>1</sup> and M. Kim<sup>1</sup>  
<sup>1</sup>Pusan National University, Korea, <sup>2</sup>Daehan Solvay Specialty Chemicals Co., Ltd., Korea
- 
- 6P-P5-05** DYE-SENSITIZED SOLAR CELL USING LOCALIZED SURFACE PLASMON OF Ag NANOPARTICLES WITH DIFFERENT MODULATORS  
R. Ito, K. Oryu, H. Shibuya and M. Ihara  
Tokyo Institute of Technology, Japan
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- 6P-P5-06** IN-SITU ULTRA-THIN POLYMER MENBRANE ELECTROLYTES FOR DYE-SENSITIZED SOLAR CELL  
H. Yang, O. A. Ileperuma, M. Shimomura and Kenji Murakami  
Shizuoka University, Japan
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- 6P-P5-07** EFFECT OF DIFFERENT INORGANIC NANOFILLER IN GEL ELECTROLYTE ON THE PERFORMANCE AND STABILITY OF SOLID-STATE DYE SENSITIZED SOLAR CELLS  
M. S. Akhtar, J. Chun, S. R. Dhage, K. Kim and O. Yang  
Chonbuk National University, Korea
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- 6P-P5-08** DYE-SENSITIZED SOLAR CELL PREPARED FOR RECYCLING UMEBOSHI FLAVORING LIQUID WASTE  
T. Yamaguchi<sup>1</sup>, Y. Terada<sup>1</sup>, K. Takagi<sup>1</sup>, N. Kishimoto<sup>1</sup>, S. Niiyama<sup>2</sup> and T. Imanishi<sup>2</sup>  
<sup>1</sup>Wakayama College of Technology, Japan, <sup>2</sup>Wakayama Industrial Technology Center, Japan
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- 6P-P5-09** PHOTOVOLTAIC PROPERTY OF PCBM NANOPARTICLES LINKED WITH Ru DYE  
I. Park, K. Kim and D. Kim  
Korea University, Korea
- 
- 6P-P5-10** NANOCRYSTALLINE FILM DYE-SENSITIZED SOLAR CELLS PREPARED USING DIFFERENT TiO<sub>2</sub> MATERIALS  
Q. Fan<sup>1,2</sup>, S. Zhang<sup>1</sup>, P. Holliman<sup>2</sup> and D. A. Worsley<sup>3</sup>  
<sup>1</sup>The University of Sheffield, UK, <sup>2</sup>University of Wales, UK, <sup>3</sup>Swansea University, UK
- 
- 6P-P5-11** QUARTZ REFLECTIVE COATING ON IR-EMITTERS FOR PV MANUFACTURING PROCESS  
V. Reith  
Heraeus-Noblelight, Germany
- 
- 6P-P5-12** DYE-SENSITIZED SOLAR CELLS BASED ON LOW VISCOUS PHOSPHONIUM IONIC LIQUID ELECTROLYTES  
H. Hayakawa<sup>1</sup>, K. Tsunashima<sup>2</sup>, M. Sugiya<sup>2</sup> and Y. Kunugi<sup>1</sup>  
<sup>1</sup>Tokai University, Japan, <sup>2</sup>Nippon Chemical Industrial Co., Ltd., Japan
- 
- 6P-P5-13** A STUDY ON THE DYE-ABSORPTION CHARACTERISTICS OF DYE-SENSITIZED SOLAR CELL BY APPLYING ELECTRIC FIELD  
H. Seo, M. Kim, J. Hong, K. Prabakar and H. Kim  
Pusan National University, Korea
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**6P-P5-14** HYDROTHERMAL SYNTHESIS OF ANATASE TiO<sub>2</sub> NANOTUBES AND THE APPLICATION IN DYE-SENSITIZED SOLAR CELLS

N. Cai, Y. Zhao, Y. Zhang and J. Zhang  
Nankai University, China

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**6P-P5-15** COATING AL<sub>2</sub>O<sub>3</sub> BLOCKING LAYER ON NANOPOROUS TiO<sub>2</sub> FILM BY ATOMIC LAYER DEPOSITION

C. Lee<sup>1</sup>, M. Lee<sup>1</sup>, F. Tsai<sup>2</sup> and C. Lin<sup>2</sup>  
<sup>1</sup>Industrial Technology Research Institute, Taiwan, <sup>2</sup>National Taiwan University, Taiwan

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**6P-P5-16** IMPACTS OF SURFACE TREATMENTS FOR TiO<sub>2</sub> FILMS ON PERFORMANCE OF DYE-SENSITIZED SOLAR CELLS

C. Huang, H. Cheng, Y. S. Lo, Y. Jan and Y. C. Huang  
National Dong Hwa University, Taiwan

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**6P-P5-17** HIGHLY DURABLE INVERTED TYPE ORGANIC SOLAR CELL USING AMORPHOUS TITANIUM OXIDE AS ELECTRON COLLECTION ELECTRODE INSERTING BETWEEN ITO AND ORGANIC LAYER

T. Kuwabara, Y. Sigeyama, T. Yamaguchi and K. Takahashi  
Kanazawa University, Japan

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**6P-P5-18** DYE SENSITIZED EFFECT ON TiO<sub>2</sub>/POLY(3-HEXYLTHIOPHENE) HETERO JUNCTION SOLAR CELL

T. Iizawa, D. Suzuki and H. Nagayoshi  
Tokyo National College of Technology, Japan

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**6P-P5-19** NANO-SIZED SINGLE CRYSTALS OF FULLERENE : NEW MATERIAL FOR BULK HETEROJUNCTION DONOR-ACCEPTOR TYPE 3D SOLAR CELLS

S. P. Somani, P. R. Somani and M. Umeno  
Chubu University, Japan

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**6P-P5-20** MULTIWALL CARBON NANOTUBE (MWCNTs) COATED WITH COPPER PHTHALOCYANINE (CuPc) AND n-Si HETEROJUNCTION PHOTOVOLTAIC DEVICE

G. Kalita<sup>1</sup>, S. Adhikari<sup>1</sup>, H. R. Aryal<sup>1</sup>, M. Sharon<sup>2</sup> and M. Umeno<sup>1</sup>  
<sup>1</sup>Chubu University, Japan, <sup>2</sup>Birla College, India

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**6P-P5-21** MULTIWALLED CARBON NANOTUBES DECORATED WITH FULLERENE : NOVEL NEW MATERIAL FOR ORGANIC SOLAR CELLS

P. R. Somani, S. P. Somani and M. Umeno  
Chubu University, Japan

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**6P-P5-22** PHOTOVOLTAIC RESPONSE OF NITROGENATED AMORPHOUS CARBON FILMS DEPOSITED BY MICROWAVE SURFACE WAVE PLASMA CVD

S. Adhikari, D. C. Ghimire, H. R. Aryal, G. Kalita, H. Uchida, M. Noda and M. Umeno  
Chubu University, Japan

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**6P-P5-23** CONDUCTIVITY CONTROL OF C<sub>60</sub> THIN FILMS BY Mg DOPING

N. Kojima, T. Terayama, H. Suzuki, M. Natori and M. Yamaguchi  
Toyota Technological Institute, Japan

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**6P-P5-24** CRYSTAL STRUCTURES OF COPPER PHTHALOCYANINE ON C60 (111) SURFACE GROWN BY MOLECULAR BEAM EPITAXY

H. Suzuki, Y. Yamashita, N. Kojima and M. Yamaguchi  
Toyota Technological Institute, Japan

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**6P-P5-25** NEW DONOR AND ACCEPTOR MATERIALS FOR ORGANIC THIN-FILM PHOTOVOLTAIC CELLS

T. Toru, S. P. Singh, D. Sukeguchi, H. Yoshiyama, H. Inukai, H. Sakuragi, S. Nakamura, N. Shibata, Y. Hayashi and T. Soga  
Nagoya Institute of Technology, Japan

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**6P-P5-26** SYNTHESIS AND PROPERTY OF SOLUTION PROCESSED ZNPC/PCBM BULK HETERO-JUNCTION ORGANIC SOLAR CELLS

Y. Hayashi, H. Inukai, H. Sakuragi, D. Sukeguchi, H. Yoshiyama, S. Nakamura, N. Shibata, T. Soga and T. Toru  
Nagoya Institute of Technology, Japan

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**6P-P5-27** DOPING EFFECTS FOR ORGANIC PHOTOVOLTAIC CELLS BASED ON SMALL MOLECULAR WEIGHT SEMICONDUCTORS

T. Taima<sup>1</sup>, J. Sakai<sup>2</sup>, T. Yamanari<sup>1</sup> and K. Saito<sup>1</sup>  
<sup>1</sup>National Institute of Advanced Industrial Science and Technology (AIST), Japan, <sup>2</sup>Matsushita Electric Works, Ltd., Japan

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**6P-P5-28 ANNEALING EFFECT IN THE SEXITHIOPHENE : C<sub>70</sub> BULK-HETEROJUNCTION ORGANIC PHOTOVOLTAIC CELLS**

J. Sakai<sup>1</sup>, T. Taima<sup>2</sup>, T. Yamanari<sup>2</sup> and K. Saito<sup>2</sup>

<sup>1</sup>Matsushita Electric Works, Ltd., Japan, <sup>2</sup>National Institute of Advanced Industrial Science and Technology (AIST), Japan

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**6P-P5-29 NANOSTRUCTURED POLYMER BLENDS/INORGANIC TITANIA HYBRID PHOTOVOLTAIC DEVICES**

M. Wu, H. Lo, H. Liao, Y. Chen, C. Chen and W. Su

National Taiwan University, Taiwan

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**6P-P5-30 ORGANIC DYE WAVELENGTH CONVERSION SOLAR CELLS**

K. Kawano, B. C. Hong, S. Kohketsu, Y. Nakamura and K. Sakamoto

The University of Electro-Communications, Japan

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**6P-P5-31 ENHANCEMENT OF COPPER PATHLOCYANINE/C<sub>60</sub> ORGANIC BI-LAYER SOLAR CELL PERFORMANCE BY GRADED BANDGAP LIGHT ABSORPTION LAYERS**

Y. Kim<sup>1</sup>, T. N. T. Nguyen<sup>1</sup>, M. L. Monroe<sup>2</sup>, T. J. Anderson<sup>2</sup> and C. Park<sup>1</sup>

<sup>1</sup>Yeungnam University, Korea, <sup>2</sup>University of Florida, USA

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**6P-P5-32 INFLUENCE OF DONOR LAYER THICKNESS ON THE PROPERTIES OF PENTACENE/FULLERENE C<sub>60</sub> ORGANIC PHOTOVOLTAIC DEVICES**

Y. Xu<sup>1,2</sup>, C. Jiang<sup>2</sup>, X. W. Sun<sup>1,2</sup> and T. K. S. Wong<sup>1</sup>

<sup>1</sup>Nanyang Technological University, Singapore, <sup>2</sup>Institute of Microelectronics, Singapore

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**6P-P5-33 CURRENT-VOLTAGE CHARACTERISTICS OF P3HT/CdS NANO-ROD STRUCTURE MADE BY NANO-IMPRINTING AND ELECTRODEPOSITION**

H. Noh, K. Han, K. Kim, H. Lee and D. Kim

Korea University, Korea

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**6P-P5-34 SYNTHESIS OF CdSe/CdTe TYPE-II HETEROJUNCTION NANOCRYSTALS FOR PV APPLICATIONS**

H. Lee, J. Park and D. Kim

Korea University, Korea

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**6P-P5-35 A GOLD NANOPARTICLE-SENSITIZED TITANIUM(IV) DIOXIDE SOLAR CELL USING ELECTROLYTE SOLUTIONS CONTAINING S<sub>X</sub><sup>2-</sup>/S<sup>2-</sup> AS A REDOX PAIR**

T. Kiyonaga, H. Okamoto, H. Matsui, M. Yoshihara and H. Tada

Kinki University, Japan

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**6P-P5-36 N-TYPE β-FeSi<sub>2</sub>/P-TYPE Si HETEROJUNCTION SOLAR CELL FABRICATED BY FACING-TARGET DC SPUTTERING**

M. Shaban, K. Nakashima, K. Nomoto and T. Yoshitake

Kyushu University, Japan

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**6P-P5-37 EFFICIENT CHARGE SEPARATION AND TRANSPORT IN THE POLY(3-HEXYLTHIOPHENE)/TiO<sub>2</sub> NANORODS BULK HETEROJUNCTION SOLAR CELLS**

T. Zeng, T. Huang, H. Lo, C. Chen, Y. Lin, C. Chang, Y. Lin and W. Su

National Taiwan University, Taiwan

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**6P-P5-38 FABRICATION OF TEXTURED SURFACE FOR PHOTOVOLTAIC CELLS**

H. Nam, J. Chang, J. Han, Y. Kim, J. Yi and D. Jung

Sungkyunkwan University, Korea

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**6P-P5-39 HYBRID PHOTOVOLTAIC DEVICE BASED ON Na-DOPED ZnO NANOWIRES AND ZINC PHTHALOCYANINES (ZnPc)**

Z. Q. Ma, X. Tang, C. Y. Zhou, F. Xu and F. Li

Shanghai University, China

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**6P-P5-40 FABRICATION OF NANO-PATTERNED INDIUM-TIN OXIDE ELECTRODES USING BLOCK COPOLYMER LITHOGRAPHY FOR SOLAR CELLS**

S. Park, T. Kim, J. Bang and D. Kim

Korea University, Korea

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**6P-P5-41 FABRICATION OF CADMIUM SULFIDE NANOSTRUCTURES ON ITO/GLASS USING ANODIC ALUMINUM OXIDE TEMPLATE FOR SOLAR CELL APPLICATIONS**

N. Kim<sup>1</sup>, Y. Han<sup>2</sup> and D. Kim<sup>1</sup>

<sup>1</sup>Korea University, Korea, <sup>2</sup>P&I Corporation, Korea

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**6P-P5-42** A NOVEL FABRICATION TECHNIQUE OF A NEW TRANSPARENT CONDUCTING ANODE: ALUMINIUM-DOPED ZINC OXIDE (AZO)

**Late News** W. M. Tsang, F. L. Wong, M. K. Fung, C. S. Lee and S. T. Lee  
City University of Hong Kong, Hong Kong SAR, China

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**6P-P5-43** PLATINUM COATING ON POLYMER COUNTER ELECTRODE PREPARED BY MAGNETRON SPUTTER FOR PLASTIC DYE-SENSITIZED SOLAR CELLS

**Late News** M. Goto, Y. Xu, A. Kasahara and M. Tosa  
National Institute for Materials Science, Japan

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**6P-P5-44** HYBRID SOLAR CELLS OF LAYER-BY-LAYER THIN FILM WITH POLYMER/FULLERENE BULK HETEROJUNCTION

**Late News** K. Masuda, M. Ogawa, H. Benten, H. Ohkita and S. Ito  
Kyoto University, Japan

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#### **Area 4**

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**6P-P5-45** SIMULATION OF A SOLAR CELL PRODUCTION PROCESS TO DETERMINE THE STRESS IN A NON-PLANAR THIN FILM SOLAR CELL

I. C. Brazil and M. A. Green  
University of New South Wales, Australia

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**6P-P5-46** POLYSILICON FABRICATED TEST STRUCTURES TO DETERMINE THE STRESS IN A THIN-FILM SOLAR CELL

I. C. Brazil, I. Perez-Wurfl and M. A. Green  
University of New South Wales, Australia

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**6P-P5-47** MECHANICAL AND MICRO-STRUCTURAL CHARACTERISATION OF A THIN FILM POLYSILICON SOLAR CELL

I. C. Brazil and M. A. Green  
University of New South Wales, Australia

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**6P-P5-48** THIN FILM SILICON SOLAR CELLS PREPARED BY TEMPERATURE CONTROLLED HOT-WIRE CHEMICAL VAPOR DEPOSITION

M. M. Adachi<sup>1</sup> and K. S. Karim<sup>2</sup>  
<sup>1</sup>Simon Fraser University, Canada, <sup>2</sup>University of Waterloo, Canada

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**6P-P5-49** EFFECTS OF TOTAL GAS FLOW RATE ON CRYSTALLINITY OF SI THIN FILMS PREPARED BY HOT WIRE CHEMICAL VAPOR DEPOSITION

W. Zi, Y. Zhou, F. Liu, Z. Sun and M. Zhu  
Chinese Academy of Sciences, China

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**6P-P5-50** RESEARCH ON NEW STRUCTURE OF P-LAYERS IN FLEXIBLE THIN FILM SOLAR CELLS

R. Lin<sup>1,2</sup>, D. Zhang<sup>2</sup>, H. Cai<sup>2</sup>, C. Shi<sup>2</sup> and S. Zhang<sup>1</sup>  
<sup>1</sup>Beihang University, China, <sup>2</sup>Nankai University, China

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**6P-P5-51** DECREASE THE AMORPHOUS INITIAL INCUBATION LAYER IN HIGH-RATE DEPOSITED MICROCRYSTALLINE SILICON SOLAR CELLS

Q. Guo<sup>1,2</sup>, X. Geng<sup>1</sup>, Y. Zhao<sup>1</sup>, C. Wei and L. Guo<sup>2</sup>  
<sup>1</sup>Nankai University, China, <sup>2</sup>Shanghai Topsolar Green energy Co., Ltd., China

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**6P-P5-52** STRUCTURAL CONTROL OF HIGH-RATE DEPOSITED MICROCRYSTALLINE SILICON FOR HIGH EFFICIENCY SOLAR CELL

G. Hou, X. Han, Q. Guo, X. Zhang, N. Cai, C. Wei, Y. Zhao and X. Geng  
Nankai University, China

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**6P-P5-53** THE PERFORMANCE IMPROVEMENT OF HIGH RATE GROWTH MICROCRYSTALLINE SILICON SOLAR CELL BY INSERTION OF BUFFER LAYER TO P/I INTERFACE

X. Han, X. Zhang, G. Hou, Y. Yuan, D. Zhang, C. Wei, J. Sun, J. Xue, Y. Zhao and X. Geng  
Nankai University, China

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**6P-P5-54** HIGH RATE DEPOSITION OF MICRO-CRYSTALLINE SILICON BY RF-PECVD: THE FUNCTION OF PRESSURE AND POWER AND THE DEPOSITION PHASE DIAGRAM

Z. Sun, F. Liu, W. Zi, Y. Zhou and M. Zhu  
Chinese Academy of Sciences, China

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**6P-P5-55** STUDY OF SILICON BASED THIN FILM SOLAR CELLS ON POLYIMIDE SUBSTRATE

K. Tao, Q. Xi, H. Cai, Y. Xue, Y. Jiang, C. Shi and D. Zhang  
Nankai University, China

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**6P-P5-56** STUDY OF TEXTURED PLASTIC SUBSTRATES AND BACK CONTACTS FOR AMORPHOUS SOLAR CELLS

H. Cai<sup>1,2</sup>, D. Zhang<sup>2</sup>, K. Tao<sup>2</sup>, Q. Xi<sup>2</sup>, Y. Xue<sup>2</sup>, C. Shi<sup>1</sup> and Y. Sun<sup>1</sup>

<sup>1</sup>Nankai University, China, <sup>2</sup>Nankai University, China

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**6P-P5-57** SOLID PHASE CRYSTALLIZATION OF AMORPHOUS SILICON ON ZNO:AL FOR THIN FILM SOLAR CELLS

C. Becker<sup>1</sup>, K. Y. Lee<sup>1</sup>, P. Dogan<sup>1</sup>, F. Fenske<sup>1</sup>, M. Berginski<sup>2</sup>, J. Hüpkes<sup>2</sup>, S. Gall<sup>1</sup> and B. Rech<sup>1</sup>

<sup>1</sup>Hahn-Meitner-Institut GmbH, Germany, <sup>2</sup>Forschungszentrum Jülich GmbH, Germany

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**6P-P5-58** STRUCTURAL STUDY OF THE DEVICE QUALITY SILICON GERMANIUM THIN FILMS DEPOSITED BY PULSED RF PLASMA CVD

P. Chaudhuri<sup>1</sup>, A. Bandyopadhyay<sup>1</sup>, A. Bhaduri<sup>1</sup> and D. Williamson<sup>2</sup>

<sup>1</sup>Indian Association for the Cultivation of Science, India, <sup>2</sup>Colorado School of Mines, USA

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**6P-P5-59** MICROSTRUCTURE AND RESIDUAL STRESS IN NANOCRYSTALLINE SILICON FILMS: MATERIALS FOR SOLAR CELLS

S. Ray, A. Chowdhury and S. Sengupta

Indian Association for the Cultivation of Science, India

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**6P-P5-60** THERMAL POST-ANNEALING EFFECT ON PHOTOVOLTAIC PROPERTIES OF *n*-TYPE  $\beta$ -FeSi<sub>2</sub>/*p*-TYPE Si HETEROJUNCTION

K. Nomoto, M. Shaban, K. Nakashima and T. Yoshitake

Kyushu University, Japan

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**6P-P5-61** MICROCRYSTALLINE SILICON THIN FILMS WERE DEPOSITED BY THE REACTIVE RF MAGNETRON SPUTTERING SYSTEM

Y. Tomita and M. Isomura

Tokai University, Japan

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**6P-P5-62** EFFECTS OF ACETYLENE GAS ON THE PROPERTIES OF AMORPHOUS CARBON FILMS GROWN BY MICROWAVE SURFACE WAVE PLASMA CVD

D. C. Ghimire, S. Adhikari, H. R. Aryal, H. Uchida and M. Umeno

Chubu University, Japan

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**6P-P5-63** EFFECTS OF HIGH PRESSURE H<sub>2</sub>O VAPOR TREATMENT ON POLYCRYSTALLINE SILICON-GERMANIUM THIN FILMS

Y. Sano and M. Isomura

Tokai University, Japan

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**6P-P5-64** GAS PHASE DIAGNOSIS FOR REACTIVE SPUTTERING OF MICROCRYSTALLINE SILICON GERMANIUM

Y. Uesaka, H. Kawauchi and M. Isomura

Tokai University, Japan

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**6P-P5-65** CORRELATION BETWEEN PHOTOCARRIER DIFFUSION LENGTH AND LATERAL SIZE OF HIGH-GROWTH-RATE MICROCRYSTALLINE SILICON

M. Nishino, T. Kawabe, Y. Sobajima, T. Toyama and H. Okamoto

Osaka University, Japan

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**6P-P5-66** HIGH QUALITY P-TYPE A-SI:H THIN FILM FOR HETEROJUNCTION SOLAR CELL PREPARED BY REMOTE PECVD

P. Supajariyawichai, M. S. Jeon, M. Dhamrin, M. Suda and K. Kamisako

Tokyo University of Agriculture and Technology, Japan

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**6P-P5-67** PREPARATION OF TITANIUM DIOXIDE THIN FILMS BY MEANS OF ELECTRON BEAM EVAPORATION FOR PROTECTING MATERIAL AGAINST ATOMIC HYDROGEN

S. Ogawa, M. Tobita, T. Iida, T. Narita, H. Kuze, T. Masuda, R. Koie, N. Yoshida and S. Nonomura

Gifu University, Japan

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**6P-P5-68** FAST DEPOSITION OF MICROCRYSTALLINE SILICON FILMS FROM SiH<sub>2</sub>Cl<sub>2</sub> UTILIZING THE HIGH-DENSITY MICROWAVE PLASMA

J. K. Saha<sup>1</sup>, N. Ohse<sup>1</sup>, K. Hamada<sup>1</sup>, T. Kobayashi<sup>2</sup> and H. Shirai<sup>1</sup>

<sup>1</sup>Saitama University, Japan, <sup>2</sup>The Institute of Physics and Chemical Research (RIKEN), Japan

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**6P-P5-69** RAPID CRYSTALLIZATION OF AMORPHOUS SILICON UTILIZING THE RF PLASMA TORCH

H. Shirai<sup>1</sup>, Y. Takemura<sup>2</sup>, K. Haruta<sup>1</sup>, M. Yeo, Y. Ding<sup>1</sup> and T. Kobayashi<sup>3</sup>

<sup>1</sup>Saitama University, Japan, <sup>2</sup>Japan Science and Technology Agency (JST), Japan, <sup>3</sup>The Institute of Physics and Chemical Research (RIKEN), Japan

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<b>6P-P5-70</b>	PREPARATION OF HYDROGENATED MICROCRYSTALLINE SILICON THIN FILMS BY HOT WIRE CVD UNDER HELIUM-DILUTED CONDITION  M. Tomita, S. Hiza, A. Yamada and M. Konagai  Tokyo Institute of Technology, Japan
<b>6P-P5-71</b>	HYDROGENATED MICROCRYSTALLINE SILICON SOLAR CELLS PREPARED ON LOW-TEMPERATURE-DEPOSITED ZINC OXIDE FILM WITH VARIOUS TEXTURES  S. Hiza, T. Hayashi, A. Yamada and M. Konagai  Tokyo Institute of Technology, Japan
<b>6P-P5-72</b>	IN SITU MONITORING OF NANOPARTICLES AND Silyl RADICAL DURING HYDROGENATED MICROCRYSTALLINE SILICON GROWTH  T. Nagai, A. H. M. Smets, H. Fujiwara and M. Kondo  National Institute of Advanced Industrial Science and Technology (AIST), Japan
<b>6P-P5-73</b>	SYNTHESIS OF NANOCRYSTALLINE-FESi <sub>2</sub> /SI HETEROJUNCTIONS FOR PHOTOVOLTAIC APPLICATIONS BY FACING TARGET DC SPUTTERING  H. Kondo, M. Shaban, K. Nakashima and T. Yoshitake  Kyushu University, Japan
<b>6P-P5-74</b>	OPTICAL ABSORPTION SPECTRA OF HIGH-GROWTH-RATE MICROCRYSTALLINE SILICON THIN-FILMS  T. Fukumori, M. Kurihara, Y. Sobajima, T. Toyama and H. Okamoto  Osaka University, Japan
<b>6P-P5-75</b>	FEASIBILITY STUDY ON HIGH EFFICIENCY POLY-SI THIN FILM SOLAR CELLS FORMED BY FLASH LAMP ANNEALING OF CAT-CVD AMORPHOUS SILICON  T. Fujiwara, Y. Endo, S. Nishizaki, K. Ohdaira, K. Nishioka and H. Matsumura  JAIST (Japan Advanced Institute of Science and Technology), Japan
<b>6P-P5-76</b>	FREE CARRIER ABSORPTION IN GA-DOPED MICROCRYSTALLINE ZINC OXIDE FILMS  K. Matsuyama, Y. Wakazono, S. Maehara, T. Itoh and K. Shimakawa  Gifu University, Japan
<b>6P-P5-77</b>	IMPROVEMENT OF LIGHT-TRAPPING EFFECT ON MICROCRYSTALLINE SILICON THIN FILM SOLAR CELLS FABRICATED ON HIGH HAZE TRANSPARENT CONDUCTIVE OXIDE FILMS  M. Kambe, K. Masumo, N. Taneda, T. Oyama and K. Sato  Asahi Glass Co., Ltd., Japan
<b>6P-P5-78</b>	SILICON-HETEROJUNCTION CELLS WITH WIDE-BANDGAP MICROCRYSTALLINE FRONT EMITTERS  J. J. Gandía, R. Barrio, I. Torres, J. Cárabe and N. González  CIEMAT, Spain
<b>6P-P5-79</b>	LIGHT INDUCED DEGRADATION IN NANOCRYSTALLINE Si FILMS AND RELATED SOLAR CELLS: ROLE OF CRYSTALLINE FRACTION  <b>Late News</b> S. Mukhopadhyay, R. Goswami and S. Ray  Indian Association for the Cultivation of Science, India
<b>6P-P5-80</b>	NOVEL ACRYLIC POLYMER SUBSTRATE WITH FINE TEXTURE AND APPLICATION TO SUPERSTRATE-TYPE AMORPHOUS SILICON SOLAR CELLS  <b>Late News</b> K. Katsuma <sup>1</sup> , S. Hayakawa <sup>1</sup> , T. Matsui <sup>2</sup> , A. Masuda <sup>2</sup> and M. Kondo <sup>2</sup>  <sup>1</sup> The Nippon Synthetic Chemical Industry Co., Ltd., Japan, <sup>2</sup> National Institute of Advanced Industrial Science and Technology, Japan
<b>6P-P5-81</b>	NANO-SCALE CHARACTERIZATION OF MICROCRYSTALLINE SILICON SOLAR CELLS BY SCANNING NEARFIELD OPTICAL MICROSCOPY  <b>Late News</b> T. Gotoh <sup>1</sup> , Y. Yamamoto <sup>2</sup> , Z. Shen <sup>2</sup> , S. Ogawa <sup>2</sup> , N. Yoshida <sup>2</sup> , T. Itoh <sup>2</sup> and S. Nonomura <sup>2</sup>  <sup>1</sup> Gunma University, Japan, <sup>2</sup> Gifu University, Japan

# Poster Session 6

December 6th, Thursday 16:00-17:30 Room: Poster II (5th Floor)

Area 1: Novel Materials and Devices / Area 4: Amorphous & Nano/Microcrystalline Silicon Based Solar Cells and Related Materials

## Area 1

### 6P-P6-01 MONOLITHICALLY SERIES-INTERCONNECTED TRANSPARENT MODULES OF DYE-SENSITIZED SOLAR CELLS

Y. Takeda<sup>1</sup>, N. Kato<sup>1</sup>, K. Higuchi<sup>1</sup>, A. Takeichi<sup>1</sup>, T. Motohiro<sup>1</sup>, S. Fukumoto<sup>2</sup>, T. Sano<sup>2</sup> and T. Toyoda<sup>2</sup>

<sup>1</sup>Toyota Central Research and Development Laboratories, Japan, <sup>2</sup> AISIN SEIKI Co., Ltd., Japan

### 6P-P6-02 LONG-TERM DURABILITY AND DEGRADATION MECHANISM OF DYE SENSITIZED SOLAR CELLS SENSITIZED WITH MEROCYANINE DYES

H. Tanaka<sup>1</sup>, A. Takeichi<sup>1</sup>, K. Higuchi<sup>1</sup>, T. Motohiro<sup>1</sup>, M. Takata<sup>2</sup>, N. Hirota<sup>2</sup>, J. Nakajima<sup>3</sup> and T. Toyoda<sup>3</sup>

<sup>1</sup>Toyota Central Research and Development Laboratories, Japan, <sup>2</sup>Mitsubishi Paper Mills Ltd., Japan, <sup>3</sup> AISIN SEIKI Co., Ltd., Japan

### 6P-P6-03 STUDY ON DYE SENSITIZED SOLAR CELL USING NOVEL INFRARED DYE

T. Ono, T. Yamaguchi and H. Arakawa

Tokyo University of Science, Japan

### 6P-P6-04 THERMAL STABILITY OF DYE-SENSITIZED SOLAR CELLS WITH CURRENT COLLECTING GRID

H. Matsui, K. Okada and T. Kitamura

Fujikura Ltd., Japan

### 6P-P6-05 NOVEL RUTHENIUM SENSITIZERS WITH TETRADENTATE POLYPYRIDINE LIGANDS FOR NANOCRYSTALLINE DYE-SENSITIZED SOLAR CELLS

K. Kasuga<sup>1</sup>, M. Yanagida<sup>1</sup>, T. Nagatani<sup>2</sup>, M. Kasuya<sup>1</sup>, R. Katoh<sup>1</sup>, N. Onozawa-Komatsuzaki<sup>1</sup>, Y. Himeda<sup>1</sup>, T. Gunji<sup>2</sup>, Y. Abe<sup>2</sup>, O. Kitao<sup>1</sup>, K. Sayama<sup>1</sup> and H. Sugihara<sup>1</sup>

<sup>1</sup>National Institute of Advanced Industrial Science and Technology (AIST), Japan, <sup>2</sup>Tokyo University of Science, Japan

### 6P-P6-06 DEPENDENCE OF THE PHOTOVOLTAIC PROPERTIES OF CDSE QUANTUM DOT-SENSITIZED SOLAR CELLS ON THE THICKNESS OF TiO<sub>2</sub> ELECTRODES

T. Toyoda, T. Uehata, L. J. Diguna, Q. Shen

The University of Electro-Communications, Japan

### 6P-P6-07 RUTHENIUM(II) COMPLEXES WITH $\pi$ EXPANDED LIGAND HAVING PHENYLENE-ETHYNYLENE MOIETY AS SENSITIZERS FOR DYE-SENSITIZED SOLAR CELL

T. Funaki, M. Yanagida, N. Onozawa-Komatsuzaki, Y. Kawanishi, K. Kasuga and H. Sugihara

National Institute of Advanced Industrial Science and Technology (AIST), Japan

### 6P-P6-08 DEVELOPMENT OF HIGHLY EFFICIENT PLASTIC DYE SENSITIZED SOLAR CELL

N. Tobe, D. Matsumoto, T. Nagai, T. Yamaguchi and H. Arakawa

Tokyo University of Science, Japan

### 6P-P6-09 NOVEL PHOTOVOLTAIC CELL WITH MESOSCOPIC ELECTRODES SENSITIZED BY LEAD-HALIDE COMPOUNDS (8)

A. Kojima<sup>1</sup>, K. Teshima<sup>3</sup>, Y. Shirai<sup>4</sup> and T. Miyasaka<sup>1,2,3</sup>

<sup>1</sup>The University of Tokyo, Japan, <sup>2</sup>Toin University of Yokohama, Japan, <sup>3</sup>Peccell Technologies, Inc., Japan, <sup>4</sup>Tokyo Polytechnic University, Japan

### 6P-P6-10 SERIES-CONNECTED TANDEM DYE-SENSITIZED SOLAR CELL FOR IMPROVING EFFICIENCY MORE THAN 10%

T. Yamaguchi, Y. Uchida, S. Agatsuma and H. Arakawa

Tokyo University of Science, Japan

### 6P-P6-11 MULTI-WALLED CARBON NANOTUBES AS A COUNTER ELECTRODE OF DYE-SENSITIZED SOLAR CELLS

S. K. Lee<sup>1</sup>, S. H. Hwang<sup>1</sup>, J. H. Moon<sup>1</sup>, K. S. Noh<sup>1</sup>, D. Y. Lee<sup>2</sup>, D. H. Kim<sup>1</sup>, K.Y. Sohn<sup>1</sup> and M. H. Jeon<sup>1</sup>

<sup>1</sup>Inje University, Korea, <sup>2</sup>Korea Electrotechnology Research Institute, Korea

### 6P-P6-12 PHOTORECHARGEABLE PROPERTIES OF PHOTOCAPACITOR CONSISTED OF RuO<sub>2</sub> / ACTIVE CARBON COMPOSITE AS ELECTRIC STORAGE MATERIAL

K. Teshima<sup>1</sup>, H. Shinohara<sup>1</sup>, J. Suzuki<sup>2</sup> and T. Miyasaka<sup>1,2</sup>

<sup>1</sup>Peccell Technologies, Inc., Japan, <sup>2</sup>Toin University of Yokohama, Japan

### 6P-P6-13 NON-ZERO CHEMICAL POTENTIAL OF SOLAR RADIATION IN GIBB'S METHOD

V. Laptev

University of Stuttgart, Germany

**6P-P6-14** BLOCKING LAYER INSERTION EFFECT ON DYE SENSITIZED SOLAR CELLS

H. Nagayoshi, T. Iizawa, R. Midoh and K. Sadakuni  
Tokyo National College of Technology, Japan

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**6P-P6-15** TEMPERATURE DEPENDENCE OF OPEN-CIRCUIT VOLTAGE IN DYE-SENSITIZED SOLAR CELLS

A. Usami, S. Seki, Y. Mita, H. Kobayashi, H. Miyashiro and N. Terada  
Central Research Institute of Electric Power Industry, Japan

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**6P-P6-16** QUASI SOLID-STATE SOLAR CELLS SENSITIZED WITH ORGANIC DYE

O. A. Ieperuma, H. Yang, R. G. Asoka Kumara, M. Shimomura, M. Okuya, A. Konno and K. Murakami  
Shizuoka University, Japan

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**6P-P6-17** EFFECT OF ELECTROLYTE IN ELECTROSPUN POLY(VINYLDENE FLUORIDE-HEXAFLUORO PROPYLENE) NANOFIBERS ON DYE-SENSITIZED SOLAR CELLS

J. U. Kim, S. H. Park, S. Y. Lee, J. K. Lee and M. R. Kim  
Pusan National University, Korea

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**6P-P6-18** FTO TRANSPARENT CONDUCTING LAYER FOR DYE-SENSITIZED SOLAR CELLS

M. Okuya, K. Ohashi and T. Yamamoto  
Shizuoka University, Japan

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**6P-P6-19** INFLUENCE OF RAPID THERMAL ANNEALING ON CNT BASED ELECTRODES FOR IMPROVED PHOTOVOLTAIC PERFORMANCE OF DSSC

J. H. Moon<sup>1</sup>, S. H. Hwang<sup>1</sup>, S. K. Lee<sup>1</sup>, D. Y. Lee<sup>2</sup>, D. H. Kim<sup>1</sup>, W. B. Choi<sup>3</sup>, M. H. Jeon<sup>1</sup>  
<sup>1</sup>Inje University, Korea, <sup>2</sup>Korea Electrotechnology Research Institute, Korea, <sup>3</sup>Florida International University, USA

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**6P-P6-20** THE ANALYSIS OF DYE-SENSITIZED SOLAR CELLS with metal substrates BY ELECTROCHEMICAL IMPEDANCE SPECTROSCOPY

Y. Jun and M. Kang  
Electronics and Telecommunications Research Institute, Korea

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**6P-P6-21** ULTRAFAST CHARGE SEPARATION AND EXCITON FORMATION IN POLYTHIOPHENE–FULLERENE BLEND FILMS

J. Guo, H. Ohkita, H. Benten and S. Ito  
Kyoto University, Japan

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**6P-P6-22** FABRICATION AND PROPERTIES OF P3HT-PCBM AND PVCZ-PCBM BASED BULK-HETEROJUNCTION SOLAR CELLS

N. Kuretake<sup>1</sup>, Y. Horii<sup>2</sup>, H. Kusano<sup>2</sup> and M. Kitagawa<sup>1</sup>  
<sup>1</sup>Tottori University, Japan, <sup>2</sup>Research Institute of Technology of Tottori Prefecture, Japan

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**6P-P6-23** POLYMER PHOTOVOLTAIC CELLS WITH MODIFIED ANODE BUFFER LAYER

Y. Chen, Y. Lin, B. Ko and C. Ting  
Industrial Technology Research Institutes, Taiwan

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**6P-P6-24** SOLUTION-PROCESSED MULTILAYERED POLYMER SOLAR CELLS

H. Ohkita, M. Ogawa, H. Benten and S. Ito  
Kyoto University, Japan

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**6P-P6-25** ENCAPSULATION OF POLYMER SOLAR CELLS ON FLEXIBLE SUBSTRATES

T. Chen, D. Wu, C. Wu, C. Lin and R. Horng  
National Chung Hsing University, Taiwan

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**6P-P6-26** SYNTHESIS OF NOVEL DONOR-ACCEPTOR DYAD TOWARDS APPLICATION FOR ORGANIC THIN FILM SOLAR CELLS

T. Nishizawa, K. Tajima and K. Hashimoto  
The University of Tokyo, Japan

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**6P-P6-27** SYNTHESIS OF CROSS-LINKABLE POLYTHIOPHENES AND ITS APPLICATION TO ORGANIC PHOTOVOLTAIC CELLS

S. Miyanishi, K. Tajima and K. Hashimoto  
The University of Tokyo, Japan

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**6P-P6-28** USE OF ZNO NANOSTRUCTURE TOWARDS HIGH EFFICIENCY INORGANIC/ORGANIC HYBRID THIN FILM SOLAR CELLS

K. Takanezawa, K. Tajima and K. Hashimoto  
The University of Tokyo, Japan

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**6P-P6-29** BULK HETEROJUNCTION MEH-PPV:TiO<sub>2</sub> POROUS STRUCTURED SOLAR CELLS

K. Inpor<sup>2</sup>, S. Reabanko<sup>1</sup>, P. Boonchan<sup>1</sup>, C. Junin<sup>1</sup>, C. Euvananont<sup>1</sup>, S. Sahasithiwat<sup>1</sup>, P. Limthongkul<sup>1</sup>, C. Sae-Kung<sup>2</sup>, P. Sichanugrist<sup>2</sup> and C. Thanachayanont<sup>1</sup>  
<sup>1</sup>National Metal and Materials Technology Center, Thailand, <sup>2</sup>National Science and Technology Development Agency, Thailand

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**6P-P6-30** PHOTOACTIVE HYBRIDS PREPARED BY ELECTROCHEMICAL POLYMERIZATION OF POLYBITHIOPHENE FROM NANOPOROUS TITANIA FILMS

P. Y. Lan, W. F. Su and L. Wang  
National Taiwan University, Taiwan

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**6P-P6-31** HIGH PERFORMANCE POLYMER SOLAR CELL WITH TiO<sub>x</sub> LAYER

O. Yoshikawa, T. Sagawa and S. Yoshikawa  
Kyoto University, Japan

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**6P-P6-32** IMPACT IONIZATION AND AUGER RECOMBINATION AT HIGH CARRIER TEMPERATURES

Y. Takeda<sup>1</sup>, T. Ito<sup>1</sup>, R. Suzuki<sup>1</sup>, T. Motohiro<sup>1</sup>, S. Shrestha<sup>2</sup> and G. Conibeer<sup>2</sup>  
<sup>1</sup>Toyota Central Research and Development Laboratories, Inc., Japan, <sup>2</sup>The University of New South Wales, Australia

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**6P-P6-33** PHOTOCURRENT CHARACTERISTICS OF CLOSE-PACKED HgSe NANOPARTICLE FILMS FABRICATED ON FLEXIBLE PLASTIC SUBSTRATES

J. Jang, K. Cho and S. Kim  
Korea University, Korea

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**6P-P6-34** CARBON NANOTUBE FILMS GROWN BY PULSED LASER DEPOSITION TECHNIQUE FOR SOLAR CELL

R. A. Afre<sup>1</sup>, M. Rusop<sup>3</sup>, T. Soga<sup>1</sup>, T. Jimbo<sup>1</sup> and M. Sharon<sup>2</sup>  
<sup>1</sup>Nagoya Institute of Technology, Japan, <sup>2</sup>Birla College, India, <sup>3</sup>University Technology Mara, Malaysia

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**6P-P6-35** STRUCTURAL AND OPTICAL PROPERTIES OF PHOSPHORUS DOPED SILICON QUANTUM DOT SUPPERLATTICE FOR ALL SILICON TANDEM SOLAR CELL

X. Hao<sup>1</sup>, E. Cho<sup>1</sup>, G. Scardera<sup>1</sup>, E. Bellet<sup>2</sup>, D. Bellet<sup>2</sup>, S. Park<sup>3</sup>, G. Conibeer<sup>1</sup> and M. A. Green<sup>1</sup>  
<sup>1</sup>University of New South Wales, Australia, <sup>2</sup>Laboratoire GPM2-ENSPG, France, <sup>3</sup>Samsung Advanced Institute of Technology, Korea

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**6P-P6-36** SYNTHESIS AND CHARACTERIZATION OF SILICON NANOWIRES FOR SOLAR CELL APPLICATION

M. S. Jeon, T. Suzuki, Y. Tomitsuka and K. Kamisako  
Tokyo University of Agriculture and Technology, Japan

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**6P-P6-37** SPIRAL HETEROSTRUCTURE-BASED NEW SOLAR CELL TO BE FABRICATED IN CLEAN-UNIT SYSTEM PLATFORM

N. Kawaguchi, Md. D. Rahaman, K. Gomita, H. Kaiju and A. Ishibashi  
Hokkaido University, Japan

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**6P-P6-38** MICROSTRUCTURE AND OPTICAL PROPERTIES OF CARBON FILM DEPOSITED BY PULSED DISCHARGE PLASMA CVD

M. Noda, T. Yoshida, P. R. Somani and M. Umeno  
Chubu University, Japan

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**6P-P6-39** SUBSTRATE TEMPERATURE EFFECTS IN EXCIMER LASER DEPOSITED FULLERENE FILMS FOR PHOTOVOLTAIC APPLICATION

S. M. Mominuzzaman<sup>1,2</sup>, T. Soga<sup>1</sup> and T. Jimbo<sup>1</sup>  
<sup>1</sup>Nagoya Institute of Technology, Japan, <sup>2</sup>Bangladesh University of Engineering and Technology, Bangladesh

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**6P-P6-40** SILICON QUANTUM DOT SUPERLATTICES IN SIC MATRIX FOR ALL SILICON TANDEM CELLS

Y. Cho, D. Song, E. Cho, G. Conibeer and M. A. Green  
University of New South Wales, Australia

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**6P-P6-41** SCANNING NEAR-FIELD AND CONFOCAL RAMAN MICROSCOPIC INVESTIGATION ON MULTI-WALLED CARBON NANOTUBES IN POLYMER PHOTOVOLTAIC DEVICE

S. Chen, M. Wu, Y. Lin, Y. Chen, C. Chen and W. Su  
National Taiwan University, Taiwan

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**6P-P6-42** FABRICATION OF  $\beta$ -FeSi<sub>2</sub> NANOPARTICLES/Si COMPOSITE FILM BY USING SCANNING ANNEALING

S. Terasawa, T. Inoue, A. Genseki and M. Ihara  
Tokyo institute of technology, Japan

**6P-P6-43** USING N3 DYE MOLECULES TO IMPROVE THE COMPATIBILITY OF INORGANIC ZNO AND CONJUGATED POLYMER BULK-HETEROJUNCTION HYBRID PHOTOVOLTAIC DEVICE

**Late News** C. Hsu and L. Wang  
National Taiwan University, Taiwan

**6P-P6-44** IMPROVEMENT OF POLYMER/FULLERENE SOLAR CELLS BY CONTROLLING GEOMETRY OF ITO SUBSTRATE SURFACE

**Late News** H. Yano, D. Kouro, N. Sasaki and S. Muramatsu  
Tokushima Bunri University, Japan

**6P-P6-45** THE DYE SENSITIZED SOLAR CELL PERFORMANCE USING SMALLER TiO<sub>2</sub> POWDERS IN A DOUBLE LAYERED PHOTOELECTRODE

**Late News** M. Sangklinhom, J. Yamada and R. Imai  
Shibaura Institute of Technology, Japan

**6P-P6-46** EFFICIENCY IMPROVEMENT OF ORGANIC SOLAR CELLS BY ANNEALING TREATMENT FOR ACTIVE LAYER

**Late News** Y. Tsai<sup>1</sup>, W. Chu<sup>1</sup>, C. Chen<sup>1</sup>, F. Juang<sup>1</sup>, M. Chang<sup>2</sup> and M. Liu<sup>2</sup>  
<sup>1</sup>National Formosa University, Taiwan, <sup>2</sup>Industrial Technology Research Institute, Taiwan

**6P-P6-47** IN-SITU STUDIES OF DYE DEGRADATION MECHANISMS IN DYE-SENSITIZED SOLAR CELLS BY SPECTRAL ANALYSIS

**Late News** T. C. K. Yang<sup>1</sup>, S. Wang<sup>1</sup>, S. P. Fu<sup>2</sup> and S. Y. Tsai<sup>2</sup>  
<sup>1</sup>National Taipei University of Technology, Taiwan, <sup>2</sup>Industrial Technology Research Institute, Taiwan

**Area 4**

**6P-P6-48** MEDIUM RANGE ORDER OF NANO-CRSTALLINE SILICON FILMS DEPOSITED BY MULTI-HOLLOW DISCHARGE PLASMA CVD

M. Shiratani<sup>1</sup>, W. M. Nakamura<sup>1</sup>, H. Miyahara<sup>1</sup>, K. Koga<sup>1</sup>, S. Nunomura<sup>2</sup> and M. Kondo<sup>2</sup>  
<sup>1</sup>Kyushu University, Japan, <sup>2</sup>Advanced Industrial Science and Technology, Japan

**6P-P6-49** EVALUATION OF VOLUME FRACTION OF CLUSTERS INTO A-SI:H FILMS

W. M. Nakamura, H. Miyahara, K. Koga and M. Shiratani  
Kyushu University, Japan

**6P-P6-50** THE FABRICATION OF THIN FILM SOLAR CELLS USING MICROCRYSTALLINE CUBIC SILICON CARBIDE AS A DOPING LAYER

S. Ogawa, Y. Ikeda, T. Itoh, N. Yoshida and S. Nonomura  
Gifu University, Japan

**6P-P6-51** THEORETICAL SIMULATION OF 4-TERMINAL TANDEM SOLAR CELL WITH IDEAL OPTICAL PARAMETERS

Y. Eo, J. Ko, M. Kwon, K. Ahn, H. Lee and D. Lee  
LG Electronics Institute of Technology, Korea

**6P-P6-52** CHARACTERISATION OF TRANSPARENT CONDUCTING ZnO:Al THIN FILMS FORMED ON PET BY DC MAGNETRON SPUTTERING

D. Ai<sup>1</sup>, K. Kim<sup>1</sup>, J. Lee<sup>2</sup>, N. Lakshminarayan<sup>1,3</sup> and J. Yi<sup>1</sup>  
<sup>1</sup>Sungkyunkwan University, Korea, <sup>2</sup>Kunsan National University, Korea, <sup>3</sup>Madras Christian College, India

**6P-P6-53** MANUFACTURING THE LOW COST AND HIGH EFFICIENT SOLAR CELL USING HYPERTHERMAL NEUTRAL BEAM

B. J. Lee<sup>1</sup>, K. S. Oh<sup>1</sup>, S. W. Choi<sup>2</sup>, D. C. Kim<sup>1</sup>, Y. W. Kim<sup>1</sup>, Y. C. Park<sup>2</sup>, S. J. Yoo<sup>1</sup> and M. P. Hong<sup>3</sup>  
<sup>1</sup>Nuclear Fusion Research Center, Korea, <sup>2</sup>Han-Dong Global University, Korea, <sup>3</sup>Korea University, Korea

**6P-P6-54** LATERAL SCATTERING EFFECT DURING I-V MEASUREMENT OF SILICON THIN-FILM SOLAR CELLS

J. Lee<sup>1</sup>, J. Jang<sup>1</sup>, J. Yi<sup>2</sup>, J. Song<sup>1</sup> and K. Yoon<sup>1</sup>  
<sup>1</sup>Korea Institute of Energy Research, Korea, <sup>2</sup>Sungkyunkwan University, Korea

**6P-P6-55** EFFECTS OF THE FILM THICKNESS ON THE OPTICAL, STRUCTURAL AND ELECTRICAL PROPERTIES OF Al DOPED ZnO THIN FILMS PREPARED USING RF-MAGNETRON SPUTTERING METHOD

C. Kim<sup>1</sup>, C. Jeong<sup>2</sup>, S. Boo<sup>2</sup>, J. Moon<sup>1</sup> and J. Kim<sup>1</sup>  
<sup>1</sup>Chonnam National University, Korea, <sup>2</sup>KITECH, Korea

- 6P-P6-56** STRUCTURAL STUDY OF A HIGH STABILIZED HYDROGENATED AMORPHOUS SILICON THIN FILM AS A FUNCTION OF H<sub>2</sub> / SIH<sub>4</sub> RATIO  
H. S. Lee, B. S. Kim, J. H. Yun, H. N. Kim, S. K. Kwon, H. M. Lee and D. H. Lee  
LG Electronics Institute of Technology, Korea
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- 6P-P6-57** ZnO:Al/p INTERFACE PROPERTIES AND THEIR EFFECT ON SUPERSTRATE PIN a-Si:H SOLAR CELLS  
J. Lee<sup>1,2</sup>, J. Lee<sup>1</sup>, B. Oh<sup>2</sup>, J. Song<sup>1</sup> and K. Yoon<sup>1</sup>  
<sup>1</sup>Korea Institute of Energy Research, Korea, <sup>2</sup>Chung-Nam National University, Korea
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- 6P-P6-58** HIGH RATE DEPOSITION OF MICROCRYSTALLINE SILICON THIN-FILMS BY HOT WIRE CVD  
S. Baek, S. Park, S. Na, J. Lee, J. Song and K. Yoon  
Korea Institute of Energy Research, Korea
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- 6P-P6-59** CONTROL OF SURFACE MORPHOLOGY AND LIGHT SCATTERING OF TEXTURED ZNO:AL FOR SILICON THIN-FILM SOLAR CELLS  
Y. Kim<sup>1,2</sup>, J. Lee<sup>1</sup>, J. Wang<sup>2</sup>, J. Song<sup>1</sup> and K. Yoon<sup>1</sup>  
<sup>1</sup>Korea Institute of Energy Research, Korea, <sup>2</sup>Chungnam National University, Korea
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- 6P-P6-60** EFFECT OF INTERFACIAL REACTION OF ITO AND ZNO ON AMORPHOUS SILICON IN SI HETEROJUNCTION SOLAR CELLS  
M. Kang<sup>1</sup>, Y. Ok<sup>1</sup>, S. Tark<sup>1</sup>, J. Lee<sup>2</sup>, K. Yoon<sup>2</sup>, J. Song<sup>2</sup> and D. Kim<sup>1</sup>  
<sup>1</sup>Korea University, Korea, <sup>2</sup>Korea Institute of Energy Research, Korea
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- 6P-P6-61** EFFECT OF TUNNEL RECOMBINATION JUNCTION ON ELECTRICAL AND OPTICAL PERFORMANCES OF a-Si:H/ $\mu$ c-Si:H THIN-FILM TANDEM SOLAR CELLS  
J. Jang, J. Lee, J. Song and K. Yoon  
Korea Institute of Energy Research, Korea
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- 6P-P6-62** ELECTRICAL AND OPTICAL PROPERTIES OF HYDROGEN-TREATED ZnO:Al FILMS  
S. Tark<sup>1</sup>, M. Kang<sup>1</sup>, S. Lee<sup>2</sup>, W. Kim<sup>2</sup> and D. Kim<sup>1</sup>  
<sup>1</sup>Korea University, Korea, <sup>2</sup>Korea Institute of Science and Technology, Korea
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- 6P-P6-63** DEVELOPMENT AND PERFORMANCE EVALUATION OF LEAD-FREE SILVER PASTES OPTIMIZED VIA DESIGN OF COMPOSITION FOR FABRICATION OF SCREEN-PRINTED SI SOLAR CELLS HAVING HIGH FILL FACTORS  
S. Jeon<sup>1</sup>, S. Hwang<sup>2</sup> and S. Koo<sup>1</sup>  
<sup>1</sup>Hanyang University, Korea, <sup>2</sup>Taiyo Ink MFG. Co., Ltd, Korea
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- 6P-P6-64** DEPOSITION OF POLYCRYSTALLINE SILICON FILM AT LOW TEMPERATURE BY PULSED DISCHARGE SPUTTERING IN HYDROGEN  
M. Noda, T. Suzuki and M. Umeno  
Chubu University, Japan
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- 6P-P6-65** THIN FILM SILICON n-i-p SOLAR CELLS DEPOSITED BY VHF PECVD AT 100°C SUBSTRATE TEMPERATURE  
M. Brinza, J. K. Rath and R. E. I. Schropp  
Utrecht University, The Netherlands
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- 6P-P6-66** OPTIMIZATION OF MAGNETRON SPUTTERED ZnO:Al AS A BACK REFLECTOR IN a-Si:H SOLAR CELLS  
A. M. K. Dagamseh, B. Vet and M. Zeman  
Delft University of Technology, The Netherlands
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- 6P-P6-67** FLEXICOAT300: A NEW PILOT ROLL-TO-ROLL PECVD SYSTEM FOR FABRICATION OF THIN FILM SILICON SOLAR CELLS ON FOIL  
W. Soppe<sup>1</sup>, H. Schlemm<sup>2</sup>, C. Devilee<sup>1</sup>, J. Löffler<sup>1</sup>, M. Heijna<sup>1</sup>, M. Dörenkämper<sup>1</sup> and B. B. Van Aken<sup>1</sup>  
<sup>1</sup>ECN Solar Energy, The Netherlands, <sup>2</sup>Roth&Rau AG, Germany
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- 6P-P6-68** RESPONSE TO OUTDOOR IRRADIATION CONDITIONS OF THIN FILM SILICON BASED TRIPLE BAND GAP, TRIPLE JUNCTION SOLAR CELLS  
P. Krishnan, J. W. A. Schüttauf, C. H. M. van der Werf, B. Houshyani, W. G. J. H. M. van Sark and R. E. I. Schropp  
Utrecht University, The Netherlands
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- 6P-P6-69** DEVICE RELEVANT MATERIAL PROPERTIES OF POLY-SI FILMS OBTAINED FROM OPTICAL TRANSMISSION AND REFLECTION  
B. Hoex<sup>1</sup>, S. He<sup>2</sup>, O. Kunz<sup>2</sup>, D. Inns<sup>2</sup>, W. M. M. Kessels<sup>1</sup>, M. C. M. van de Sanden<sup>1</sup> and A. G. Aberle<sup>2</sup>  
<sup>1</sup>Eindhoven University of Technology, The Netherlands, <sup>2</sup>The University of New South Wales, Australia

<b>6P-P6-70</b>	FRONT- AND BACK-SURFACE RECOMBINATION IN SILICON-HETEROJUNCTION CELLS
	R. Barrio <sup>1</sup> , J. J. Gandía <sup>1</sup> , J. Cárabe <sup>1</sup> , N. González <sup>1</sup> , C. Voz <sup>2</sup> and D. Muñoz <sup>2</sup> <sup>1</sup> CIEMAT, Spain, <sup>2</sup> Universitat Politècnica de Catalunya, Spain
<b>6P-P6-71</b>	DEPOSITION OF MICROCRYSTALLINE SILICON THIN FILM WITH HIGH DEPOSITION RATE AND INVISIBLE INCUBATION LAYER
	C. Huang, J. Liu, T. Wong, J. Wu, Y. Luo, H. Yang and C. Chen Industrial Technology Research Institute, Taiwan
<b>6P-P6-72</b>	FABRICATION OF $\mu\text{C-SI/C-SI}$ SOLAR CELLS BY HOT-WIRE CHEMICAL VAPOR DEPOSITION AND LASER ANNEALING
	B. Wu <sup>1</sup> , D. Wu <sup>1</sup> , S. Lien <sup>1</sup> , H. Mao <sup>1</sup> and M. Tseng <sup>2</sup> <sup>1</sup> National Chung Hsing University, Taiwan, <sup>2</sup> National Formosa University, Taiwan
<b>6P-P6-73</b>	HIGH DEPOSITION RATE MICROCRYSTALLINE SILICON FILMS PREPARED BY CONVENTIONAL PECVD
	C. Yang, P. Yang, Y. Jiang, C. Hsueh and S. Lee National Taiwan University, Taiwan
<b>6P-P6-74</b>	THE EFFECT OF BACK CONTACT ZNO:AL DEPOSITION CONDITION ON AMORPHOUS SILICON THIN-FILM SOLAR CELLS
	H. Yang, Y. Luo, J. Wu, J. Liu and C. Chen Industrial Technology Research Institute, Taiwan
<b>6P-P6-75</b>	TUNGSTEN FILAMENT EFFECT ON ELECTRONIC PROPERTIES OF HOT-WIRE CVD FABRICATED SI HETEROJUNCTION SOLAR CELL
	M. Tseng <sup>1</sup> , H. Yu <sup>1</sup> , S. Lien <sup>2</sup> , C. Lee <sup>3</sup> and D. Wu <sup>2</sup> <sup>1</sup> National Formosa University, Taiwan, <sup>2</sup> National Chung Hsing University, Taiwan, <sup>3</sup> National Kaohsiung Marine University, Taiwan
<b>6P-P6-76</b>	GROWTH AND CHARACTERIZATION OF NANOCRYSTALLINE SILICON GERMANIUM FILMS FROM A MIXTURE OF SILANE AND MONOMETHYLGERMANE
	Y. Yashiki, S. Miyajima, A. Yamada and M. Konagai Tokyo Institute of Technology, Japan
<b>6P-P6-77</b>	INTEGRATION OF MICROCRYSTALLINE SILICON FILMS DEPOSITED AT VERY HIGH DEPOSITION RATES INTO PIN SOLAR CELLS USING THE MHC-VHF TECHNIQUE
	A. Smets, T. Matsui and M. Kondo National Institute of Advanced Industrial Science and Technology, Japan
<b>6P-P6-78</b>	COMPOSITION DEPENDENCE OF ESR SPIN DENSITIES IN HYDROGENATED MICROCRYSTALLINE SILICON-GERMANIUM ALLOY THIN FILMS
	C. W. Chang <sup>1,2,3</sup> , T. Matsui <sup>1</sup> , H. Fujiwara <sup>1</sup> and M. Kondo <sup>1,3</sup> <sup>1</sup> National Institute of Advanced Industrial Science and Technology (AIST), Japan, <sup>2</sup> Industrial Technology Research Institute (ITRI), Taiwan, <sup>3</sup> Tokyo Institute of Technology, Japan
<b>6P-P6-79</b>	FABRICATION OF HIGH OPEN-CIRCUIT VOLTAGE $\alpha\text{-SiO:H}$ SOLAR CELLS
	K. Sriprapha, S. Inthisang, A. Yamada and M. Konagai Tokyo Institute of Technology, Japan
<b>6P-P6-80</b>	STRUCTURAL INVESTIGATION OF POLYCRYSTALLINE SILICON FILMS FORMED ON GLASS SUBSTRATES BY FLASH LAMP ANNEALING OF PRECURSOR AMORPHOUS SILICON
<b>Late News</b>	K. Ohdaira, T. Fujiwara, Y. Endo, S. Nishizaki, K. Nishioka and H. Matsumura Japan Advanced Institute of Science and Technology, Japan
<b>6P-P6-81</b>	LOW TEMPERATURE FABRICATION OF HYDROGENATED MICROCRYSTALLINE SILICON THIN FILMS USING RF MAGNETRON SPUTTERING
<b>Late News</b>	H. Wang, C. Han, S. Chen and C. Lee National Central University, Taiwan
<b>6P-P6-82</b>	ARRAY ANTENNA VHF-PCVD SYSTEM FOR MICROCRYSTALLINE SILICON SOLAR CELLS
<b>Late News</b>	N. Yamamoto, T. Takagi, Y. Iwasaki and A. Yoshinouch IHI Corporation, Japan
<b>6P-P6-83</b>	CHAMBER CLEANING FOR CHEMICAL VAPOR DEPOSITION USING PULSE TIME MODULATED F2 GAS PLASMA
<b>Late News</b>	A. Sato <sup>1</sup> , Y. Hoshino <sup>2</sup> , T. Ozaki <sup>1</sup> , M. Kondo <sup>3</sup> and S. Samukawa <sup>1</sup> <sup>1</sup> Tohoku Univ., Japan, <sup>2</sup> SHOWA DENKO K.K., Japan, <sup>3</sup> AIST, Japan



Feedstock, Slice, Impurities and Defects in Si				
Area 3 December 3rd, Monday 9:00-10:15 (Room B)				
Chs: Y. Yoshida Shizuoka Institute of Science and Technology, Japan				
R. Einhaus Apollonsolar, France				
30-B1-01		BORON REMOVAL FROM MOLTEN SILICON WITH SILICATE SLAG	L. A. V. Teixeira and K. Morita	The University of Tokyo, Japan
30-B1-02		STUDY ON SILICON-SLICING TECHNIQUE USING PLASMA-ETCHING PROCESSING	M. Yamaguchi <sup>1,2</sup> , Y. Abe <sup>1</sup> , T. Kimura <sup>1</sup> , A. Masuda <sup>2</sup> and M. Kondo <sup>2</sup>	<sup>1</sup> Toyo Advanced Technologies Co., Ltd., Japan, <sup>2</sup> National Institute of Advanced Industrial Science and Technology (AIST), Japan
30-B1-03		EFFECT OF CRUCIBLE PURITY ON MULTICRYSTALLINE SI INGOT QUALITY DURING UNIDIRECTIONAL SOLIDIFICATION	M. Dhamrin <sup>1</sup> , T. Saitoh <sup>1</sup> , K. Kamisako <sup>1</sup> , K. Yamada <sup>2</sup> , H. Suzuki <sup>2</sup> , N. Araki <sup>2</sup> and I. Yamaga <sup>2</sup>	<sup>1</sup> Tokyo University of Agriculture and Technology, Japan, <sup>2</sup> Dai-ichi Kiden Corp., Japan
30-B1-04		EFFECT OF CRUCIBLE ROTATION ON IMPURITIES DISTRIBUTIONS IN CAST GROWN POLYCRYSTALLINE SILICON INGOTS	K. Arafune, T. Higo, F. Kusuoka, Y. Ohshita and M. Yamaguchi	Toyota Technological Institute, Japan
30-B1-05		OXYGEN INCORPORATION MECHANISM FROM A CRUCIBLE IN MULTICRYSTALLINE SILICON FOR SOLAR CELLS	H. Matsuo <sup>1</sup> , R. Bairava Ganesh <sup>1,2</sup> , S. Nakano <sup>1</sup> , L. Liu <sup>1</sup> , Y. Kangawa <sup>1</sup> , K. Arafune <sup>3</sup> , Y. Ohshita <sup>3</sup> , M. Yamaguchi <sup>3</sup> and K. Kakimoto <sup>1</sup>	<sup>1</sup> Kyushu University, Japan, <sup>2</sup> Anna University, India, <sup>3</sup> Toyota Technological Institute, Japan

PV Industries and Market (1)				
Area 8 December 3rd, Monday 9:00-10:15 (Room C)				
Chs: K. Komoto Mizuho Information & Research Institute, Inc., Japan				
R. Hass Vienna University of Technology, Austria				
30-C1-01		ENERGY FROM THE DESERT - A HUGE POTENTIAL FOR SOCIO-ECONOMIC DEVELOPMENT -	P. van der Vleuten	Free Energy International BV, The Netherlands
30-C1-02		A PV MARKET: THE CASE OF GREECE	G. C. Dimitriou	German-Hellenic Chamber of Industry and Commerce, Greece
30-C1-03	Invited	INTERNATIONAL TRENDS IN PHOTOVOLTAIC MARKETS	P. Hüsser <sup>1</sup> , G. Watt <sup>2</sup> , I. Kaizuka <sup>3</sup> and P. Cowley <sup>4</sup>	<sup>1</sup> Nova Energie, Switzerland, <sup>2</sup> Australian PVPS Consortium, Australia, <sup>3</sup> RTS Corporation, Japan, <sup>4</sup> IT Power, Australia
30-C1-04	Invited	PV MARKET IN JAPAN AND ACTIVITIES OF JPEA	J. Honda	Japan Photovoltaic Energy Association (JPEA), Japan
30-C1-05	Invited	TBD	M. Cameron	Phoenix Solar AG., Germany

Dye Sensitized Solar Cell				
Area 1 December 3rd, Monday 10:15-11:45 (Room A)				
Chs: S. Hayase Kyushu Institute of Technology, Japan				
A. Hinsch Fraunhofer Institute for Solar Energy Systems, Germany				
30-A2-01	Invited	DYE SOLAR MODULES FOR FACADE APPLICATIONS: RECENT RESULTS FROM PROJECT COLORSOL	A. Hinsch <sup>1</sup> , H. Brandt <sup>1</sup> , S. Hemming <sup>1</sup> , M. Nittel <sup>1</sup> , U. Würfel <sup>2</sup> , P. Putyra <sup>2</sup> , C. Lang-Koetz <sup>3</sup> , M. Stabe <sup>3</sup> , S. Beuker <sup>4</sup> and K. Fichter <sup>4</sup>	<sup>1</sup> Fraunhofer Institute for Solar Energy Systems, Germany, <sup>2</sup> Freiburger Material Research Center FMF, Germany, <sup>3</sup> Fraunhofer Institute for Industrial Engineering, Germany, <sup>4</sup> Border Step Institute, Germany
30-A2-02		FABRICATION OF EFFICIENT DSC SUB-MODULE AND ITS LONG-TERM STABILITY	T. Sutoh, Y. Koishi, T. Yamaguchi and H. Arakawa	Tokyo University of Science, Japan
30-A2-03		LONG-TERM STABILITY OF DYE-SENSITIZED SOLAR CELL MODULE UNDER OUTDOOR WORKING CONDITION	N. Kato <sup>1</sup> , Y. Takeda <sup>1</sup> , K. Higuchi <sup>1</sup> , A. Takeichi <sup>1</sup> , E. Sudo <sup>1</sup> , H. Tanaka <sup>1</sup> , T. Motohiro <sup>1</sup> , T. Sano <sup>2</sup> and T. Toyoda <sup>2</sup>	<sup>1</sup> TOYOTA CENTRAL R&D LABS., INC., Japan, <sup>2</sup> AISIN SEIKI Co., Ltd., Japan
30-A2-04		PROPOSAL FOR HIGH EFFICIENCY DYE SENSITIZED SOLAR CELL STRUCTURE	S. Hayase, Y. Ogomi, Y. Kashiwa and Y. Noma	Kyushu Institute of Technology, Japan
30-A2-05		HIGH EFFICIENT DYE-SENSITIZED SOLAR CELLS AND INTEGRATED MODULES	L. Han, N. Koide, A. Fukui, Y. Chiba, A. Islam, R. Komiya, N. Fuke and R. Yamanaka	Sharp Corporation, Japan
30-A2-06		PHOTOINDUCED ELECTRON INJECTION IN BLACK-DYE-SENSITIZED NANOCRYSTALLINE TiO2 FILMS STUDIED BY TRANSIENT ABSORPTION SPECTROSCOPY	R. Katoh <sup>1</sup> , A. Furube <sup>1</sup> , M. Kasuya <sup>1</sup> , N. Fuke <sup>2</sup> , N. Koide <sup>2</sup> and L. Han <sup>2</sup>	<sup>1</sup> National Institute of Advanced Industrial Science and Technology (AIST), Japan, <sup>2</sup> SHARP corporation, Japan

Solar Cells and Related Science & Technologies				
Area 4 December 3rd, Monday 10:15-11:30 (Room B)				
Chs: E. Maruyama Sanyo Electric Co., Ltd, Japan				
L. Felknecht ersol ThinFilm GmbH, Germany				
30-B2-01		OPTIMIZATION OF INTERFACE STRUCTURES IN CRYSTALLINE SILICON HETEROJUNCTION SOLAR CELLS	H. Fujiwara, T. Koida and M. Kondo	National Institute of Advanced Industrial Science and Technology (AIST), Japan
30-B2-02		HETEROJUNCTION SOLAR CELL EFFICIENCY IMPROVEMENT ON VARIOUS C-SI SUBSTRATES BY INTERFACE RECOMBINATION MODELLING	S. Olibet <sup>1</sup> , E. Vallat-Sauvain <sup>1</sup> , C. Ballif <sup>1</sup> , L. Korte <sup>2</sup> and L. Fesquet <sup>1</sup>	<sup>1</sup> University of Neuchâtel, Switzerland, <sup>2</sup> Hahn-Meitner-Institut, Germany
30-B2-03		ADVANCES IN A-SI/C-SI HETEROJUNCTION SOLAR CELL FABRICATION AND CHARACTERIZATION	L. Korte, E. Conrad, I. Didschuns, H. Angermann and M. Schmidt	Hahn-Meitner-Institut Berlin GmbH, Germany
30-B2-04		DOPING INDUCED PASSIVATION LOSSES OF a-Si:H / c-SI HETEROSTRUCTURES	S. De Wolf and M. Kondo	National Institute of Advanced Industrial Science and Technology (AIST), Japan
30-B2-05		A-SI/C-SI INTERFACE EFFECTS ON PERFORMANCE OF SILICON HETEROJUNCTION SOLAR CELLS	D. Wu, S. Lien, B. Wu, C. Shen and F. Yu	National Chung Hsing University, Taiwan

PV Industries and Market (2)				
Area 8 December 3rd, Monday 10:15-12:00 (Room C)				
Chs: I. Kaizuka RTS Corporation, Japan				
P. Mints Navigant Consulting, USA				
30-C2-01	Invited	SANYO'S PHOTOVOLTAIC BUSINESS OVERVIEW	K. Wakisaka	SANYO Electric Co., Ltd., Japan
30-C2-02	Invited	TBD	Z. Shi	Suntech Power Co., Ltd., China
30-C2-03	Invited	TBD	Y. Tsuo	Motech Industries, Inc., Taiwan
30-C2-04	Invited	FIRST SOLAR COMPANY OVERVIEW	M. Gloeckler	First Solar, Inc., USA
30-C2-05	Invited	TBD	B. Sandberg	Q-cells Japan, Japan
30-C2-06	Invited	GERMANY - THE NUMBER ONE LOCATION FOR BUSINESS IN THE FIELD OF SOLAR ENERGY	D. Wortmann	Invest in Germany GmbH, Germany
30-C2-07	Invited	ADDED VALUES OF PV SYSTEMS FROM THE SOCIETYS AND UTILITIES VIEWPOINTS	D. Suna, R. Haas and A. Lopez-Polo	Vienna University of Technology, Austria

**Opening Ceremony**

**Chs: H. Okamoto** Osaka University, Japan  
**D. Flood** Vanguard Solar, Inc., USA  
**W. Palz** World Council for Renewable Energy, Belgium

**Opening Address**

**December 3rd, Monday 13:00-13:10 (Main Hall)**

**General Chairperson: M. Yamaguchi** Toyota TI, Japan

Welcome Address-1	T. Ueda	Director-General, Agency for Natural Resources and Energy, Japan
Welcome Address-2	W. Asou (Tentative)	Fukuoka Prefectural Governor

**Opening Lecture**

**December 3rd, Monday 13:40-14:40 (Main Hall)**

OL-1	A CONVENIENT THROUGHWAY FOR SOLAR ELECTRICITY	T. Tomita	Sharp, Japan
OL-2	RENEWABLE ENERGIES- THE SOLUTION FOR CLIMATECHANGE AND SECURITY OF ENERGY SUPPLY	H. J. Fell	Member of the German Parliament, Germany

**Keynote Speech**

**December 3rd, Monday 15:10-16:40 (Main Hall)**

**Chs: H. Fukuda** NEDO, Japan  
**L. Kazmerski** NREL, USA

Keynote Speech-1	TRENDS IN JAPAN'S MEASURES FOR PHOTOVOLTAIC POWER GENERATION AND NEW ENERGY	S. Watanabe	Director, Agency for Natural Resources and Energy, Japan
Keynote Speech-2	DEVELOPMENTS IN SILICON SOLAR CELLS	R. Swanson	SunPower, USA

**Ch: M. Konagai** Tokyo Institute of Technology, Japan  
**H. Ossenbrink** EC-JRC

Keynote Speech-3	R&D STATUS AND INDUSTRIALIZATION OF THIN FILM SILICON PHOTOVOLTAICS	J. Meier	Oerlikon Solar Lab, Switzerland
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**PVSEC Award / PVSEC Special Award**

**December 3rd, Monday 17:00-17:30 (Main Hall)**

**Chs: Y. Hamakawa** Ritsumeikan University, Japan  
**T. Saltoh** TUAT, USA

**Plenary 1**

**Area 1 December 4th, Tuesday 8:00-9:30 (Main Hall)**

**Chs: S. Hayase Kyushu Institute of Technology, Japan**

**K. Saito AIST, Japan**

PL1-1		MESOSCOPIC SOLAR CELLS FOR THE 21st CENTURY	M. Grätzel	Swiss Federal Institute of Technology, Switzerland
PL1-2		ORGANIC PHOTOVOLTAICS – PROGRESS AND PROSPECT ON TECHNOLOGY, APPLICATION AND COMMERCIALIZATION	J. Gui, C. Brabec and S. Spitzer	Konarka Technologies Inc., USA
PL1-3		SILICON-BASED TANDEM AND HOT CARRIER CELLS	M. A. Green	The University of New South Wales, Australia

**Plenary 5**

**Area 5 December 4th, Tuesday 9:30-10:45 (Main Hall)**

**Chs: T. Nakada Aoyama Gakuin University, Japan**

**J. R. Sites Colorado State University, USA**

PL5-1		CHALCOPYRITE (CIGS) BASED SOLAR CELLS, DEVELOPMENTS AND PRODUCTION IN EUROPE	H. Schock	Hahn-Meitner-Institut Berlin GmbH, Germany
PL5-2		KEY NEAR-TERM R&D ISSUES FOR CONTINUOUS IMPROVEMENT IN CIS-BASED THIN-FILM PV MODULES	K. Kushiya	Showa Shell Sekiyu K. K., Japan
PL5-3		THE NEXT GENERATION IN THIN-FILM PHOTOVOLTAIC PROCESS TECHNOLOGY	J. van Duren, D. Jackrel, F. Jacob, C. Leidholm, A. Pudov, M. Robinson and Y. Roussillon	Nanosolar, USA

**Dye Sensitized Solar Cell**

**Area 1 December 4th, Tuesday 11:00-12:30 (Room A)**

**Chs: H. Arakawa Tokyo University of Science, Japan**

**Z. Wang AIST, Japan**

40-A3-01		MOLECULAR DESIGN OF COUMARIN DYES FOR EFFICIENT DYE-SENSITIZED SOLAR CELLS	Z. Wang <sup>1</sup> , Y. Cui <sup>1</sup> , Y. Dan-oh <sup>2</sup> , C. Kasada <sup>2</sup> , A. Shinpo <sup>2</sup> and K. Hara <sup>1</sup>	<sup>1</sup> National Institute of Advanced Industrial Science and Technology (AIST), Japan, <sup>2</sup> Hayashibara Biochemical Laboratories, Inc., Japan
40-A3-02		SCANNING PROBE MICROSCOPE STUDY OF DYE-SENSITIZED TiO <sub>2</sub> (110)	A. Sasahara <sup>1,2</sup> , M. Ikeda <sup>1</sup> , N. Koide <sup>3</sup> , L. Han <sup>3</sup> and H. Onishi <sup>1</sup>	<sup>1</sup> Kobe University, Japan, <sup>2</sup> Japan Science and Technology Agency, Japan, <sup>3</sup> Sharp Corporation, Japan
40-A3-03		PHOTOVOLTAIC PROPERTIES OF ORGANIC DYE-SENSITIZED SOLAR CELLS USING MAGNESIUM-MODIFIED TITANIA ELECTRODES	Y. Sazanami <sup>1</sup> , T. Kadota <sup>1</sup> , S. Iwamoto <sup>1</sup> , M. Inoue <sup>1</sup> , T. Inoue <sup>2</sup> , T. Hoshi <sup>2</sup> , K. Shigaki <sup>2</sup> and M. Kaneko <sup>2</sup>	<sup>1</sup> Kyoto University, Japan, <sup>2</sup> Nippon Kayaku Co.,Ltd., Japan
40-A3-04		ALL-SOLID-STATE IODINE-FREE DYE SENSITIZED SOLAR CELLS	S. Yanagida	Osaka University, Japan
40-A3-05		HIGH-EFFICIENCY DYE-SENSITIZED SOLAR CELLS BASED ON HIGH-ASPECT-RATIO TITANIA (TiO <sub>2</sub> ) NANOTUBE ARRAYS	C. Bae, H. Yoo and H. Shin	Kookmin University, Korea (South)
40-A3-06		ORGANIC DYE SENSITIZED SOLID-STATE SOLAR CELLS	A. Konno and G. R. Asoka Kumara	Shizuoka University, Japan

**Materials Preparation and Characterization**

**Area 4 December 4th, Tuesday 11:00-12:35 (Room B)**

**Chs: A. Takano Fuji Electric Systems Co., Ltd., Japan**

**C. Teplin National Renewable Energy Lab, USA**

40-B3-01	Invited	FABRICATION OF AMORPHOUS SILICON CARBIDE FILMS USING VHF-PECVD FOR TRIPLE JUNCTION THIN FILM SOLAR CELL APPLICATIONS	I. A. Yunaz, K. Hashizume, S. Miyajima, A. Yamada and M. Konagai	Tokyo Inst. of Technology, Japan
40-B3-02		MAGNETICALLY ENHANCED MULTI-HOLLOW DISCHARGE PLASMA CVD METHOD FOR DEPOSITING HIGHLY STABLE A-Si:H FILMS	K. Koga, W. M. Nakamura, H. Miyahara and M. Shiratani	Department of Electronics, Kyushu University, Japan
40-B3-03		LOW TEMPERATURE CONTACTS THROUGH SixNy-ANTIREFLECTION COATINGS FOR INVERTED a Si:H/c Si HETEROCONTACT SOLAR CELLS	F. Wünsch <sup>1</sup> , D. Klein <sup>1</sup> , A. Podlasly <sup>2</sup> , A. Ostmann <sup>2</sup> , M. Schmidt <sup>1</sup> and M. Kunst <sup>1</sup>	<sup>1</sup> Hahn-Meitner-Institut, Germany, <sup>2</sup> Fraunhofer IZM, Germany
40-B3-04		WIDE-OPTICAL BANDGAP WITH IMPROVED CONDUCTIVITY p- $\mu$ c-Si:Ox:H FILMS PREPARED BY Cat-CVD	Y. Matsumoto and M. Ortega	CINVESTAV-IPN, Mexico
40-B3-05		DAMP HEAT STABILITY OF LPCVD ZNO:B	J. Steinhäuser <sup>1</sup> , S. Fay <sup>1</sup> , D. Zimin <sup>2</sup> , U. Kroll <sup>3</sup> and C. Ballif <sup>1</sup>	<sup>1</sup> University of Neuchâtel, Switzerland, <sup>2</sup> OC Oerlikon Balzers AG, Liechtenstein, <sup>3</sup> Oerlikon Solar-Lab SA, Switzerland
40-B3-06		MEASUREMENT OF EXCESS CARRIER LIFETIME IN EPITAXIAL SILICON THIN FILMS	M. Shanmugam <sup>1</sup> , M. F. Baroughi <sup>1</sup> , R. S. Tarighat <sup>2</sup> and S. Sivorthman <sup>2</sup>	<sup>1</sup> South Dakota State University, USA, <sup>2</sup> University of Waterloo, Canada

**Thin Film Process and Characterization**

**Area 5 December 4th, Tuesday 11:00-12:30 (Room C)**

**Chs: C. Kaufmann Hahn-Meitner-Institut Berlin, Germany**

**S. Niki AIST, Japan**

40-C3-01		LARGE GRAIN Cu(In,Ga)Se <sub>2</sub> THIN FILM GROWTH USING A Se-RADICAL BEAM SOURCE	S. Ishizuka, A. Yamada, H. Shibata, P. Fons, K. Sakurai, K. Matsubara and S. Niki	National Institute of Advance Industrial Science and Technology (AIST), Japan
40-C3-02		GROWTH OF CIGS THIN FILMS USING CRACKED SELENIUM	M. Kawamura, T. Nakashiba, Y. Chiba, A. Yamada and M. Konagai	Tokyo Institute of Technology, Japan
40-C3-03		HIGH EFFICIENCY CIGS THIN FILM SOLAR CELLS BY LASER-ASSISTED DEPOSITION TECHNIQUE	Y. Ishii, J. Hirata, T. Mise and T. Nakada	Aoyama Gakuin University, Japan
40-C3-04		OPEN-SAPCE SELENIZATION FABRICATING CIGS ABSORBER WITH Ar AND H <sub>2</sub>	T. Yu, B. Li, F. Li, Q. He, C. Li, Z. Zhou, C. Shi, G. Liu and Y. Sun	Nankai University, China (PRC)
40-C3-05		DEVELOPMENT OF Cu <sub>2</sub> ZnSnS <sub>4</sub> THIN FILMS AND SOLAR CELLS: AN APPROACH FROM EPITAXIAL GROWTH	K. Oishi, G. Saito, M. Nagahashi, K. Jimbo, W. Maw, H. Katagiri, M. Yamazaki, H. Araki and A. Takeuchi	Nagaoka National College of Technology, Japan
40-C3-06		ANNEALING EFFECT ON ELECTRICAL PROPERTIES OF Cu(In,Ga)Se <sub>2</sub> THIN FILMS	T. Sakurai <sup>1</sup> , M. D. Islam <sup>1</sup> , S. Ishizuka <sup>2</sup> , N. Ishida <sup>1</sup> , A. Kasai <sup>1</sup> , K. Matsubara <sup>2</sup> , K. Sakurai <sup>2</sup> , A. Yamada <sup>2</sup> , S. Niki <sup>2</sup> and K. Akimoto <sup>1</sup>	<sup>1</sup> University of Tsukuba, Japan, <sup>2</sup> National Institute of Advanced Industrial Science and Technology (AIST), Japan

**Dye Sensitized Solar Cell**

**Area 1 December 4th, Tuesday 14:00-15:30 (Room A)**

**Chs: T. Miyasaka Toin University of Yokohama, Japan**

**A. Konno Shizuoka University, Japan**

40-A4-01		CARBON-BASED SOLIDIFICATION OF DYE-SENSITIZED SOLAR CELLS AND APPLICATIONS TO PLASTIC CELL ASSEMBLING	T. Miyasaka, N. Ikeda and M. Ikegami	Toin University of Yokohama, Japan
40-A4-02		POSSIBLE LARGE SIZED SOLAR CELLS USING METALLIC TITANIUM SHEET AS A SUBSTRATE FOR A PHOTOELECTRODE OF DYE SENSITIZED SOLAR CELLS	K. Onoda, S. Ngamsinlapasathian and S. Yoshikawa	Kyoto University, Japan
40-A4-03		EFFECT OF SURFACE MODIFICATION ON THE PHOTOVOLTAIC PROPERTIES OF CDSE QUANTUM DOT-SENSITIZED TiO <sub>2</sub> INVERSE OPAL SOLAR CELLS	L. J. Diguna, Q. Shen, J. Kobayashi, T. Toyoda	The University of Electro-Communications, Japan
40-A4-04		PLASTIC SOLAR CELLS EMPLOYING ELECTRODEPOSITED ZNO AND ORGANIC PHOTOSENSITIZER DYES	T. Yoshida <sup>1</sup> , M. Matsui <sup>1</sup> , K. Funabiki <sup>1</sup> , H. Miura <sup>2</sup> and Y. Fujishita <sup>3</sup>	<sup>1</sup> Gifu University, Japan, <sup>2</sup> Chemireca Inc., Japan, <sup>3</sup> Sekisui Jushi Corp., Japan
40-A4-05		IMPROVEMENT IN DURABILITY OF FLEXIBLE PLASTIC DYE-SENSITIZED SOLAR CELL MODULES	M. Ikegami <sup>1</sup> , K. Teshima <sup>2</sup> and T. Miyasaka <sup>1,2</sup>	<sup>1</sup> Toin University of Yokohama, Japan, <sup>2</sup> Peccell Technologies, Inc., Japan
40-A4-06		THEORETICAL STUDY OF TWO-PHOTON ABSORPTION PROPERTIES OF ORGANIC CONJUGATED MATERIALS FOR PHOTOVOLTAIC DEVICES	W. Wang <sup>1</sup> , V. Khadka <sup>2</sup> , Z. Hu <sup>1,2</sup> , X. Yan <sup>1,2</sup> , M. Ropp <sup>1,2</sup> and D. Galipeau <sup>1,2</sup>	<sup>1</sup> South Dakota State University, USA, <sup>2</sup> PANS Research Cluster, USA

**Materials Preparation and Characterization**

**Area 4 December 4th, Tuesday 14:00-15:35 (Room B)**

**Chs: T. Takagi IHI Corporation, Japan**

**J. Bailat University of Neuchâtel, Switzerland**

40-B4-01	Invited	ULTRAFAST DEPOSITION OF MICROCRYSTALLINE SILICON FILMS USING HIGH DENSITY MICROWAVE PLASMA	H. Jia <sup>1</sup> , H. Kuraseko <sup>2,3</sup> , H. Fujiwara <sup>1</sup> and M. Kondo <sup>1,3</sup>	<sup>1</sup> National Institute of Advanced Industrial Science and Technology (AIST), Japan, <sup>2</sup> The Furukawa Electric Co., Ltd., Japan, <sup>3</sup> Tokyo Institute of Technology, Japan
40-B4-02		LARGE-AREA HIGH-SPEED DEPOSITION OF $\mu\text{c-Si}$ THIN FILMS BY 915 MHz SURFACE WAVE PLASMA	H. Sugai <sup>1</sup> , T. Ishijima <sup>2</sup> , H. Toyoda <sup>2</sup> , A. Masuda <sup>3</sup> and M. Kondo <sup>3</sup>	<sup>1</sup> Chubu University, Japan, <sup>2</sup> Nagoya University, Japan, <sup>3</sup> National Institute of Advanced Industrial Science and Technology, Japan
40-B4-03		INCREASED DEPOSITION RATES OF $\mu\text{c-Si}$ I-LAYERS DEPOSITED WITH VHF-PECVD UNDER HIGH-PRESSURE CONDITIONS AND THE INFLUENCE ON SOLAR CELL PERFORMANCE	A. Gordijn, A. Pollet-Villard, A. Lambertz and F. Finger	Forschungszentrum Juelich GmbH, Germany
40-B4-04		DEVELOPMENT OF EFFICIENT PRODUCTION TECHNOLOGY OF THIN FILM SILICON SOLAR CELLS USING A LOCALIZED PLASMA CONFINEMENT (LPC)-CVD METHOD	Y. Aya, M. Matsumoto, K. Murata, S. Ogasahara, M. Nakagawa, A. Terakawa and M. Tanaka	Sanyo Electric Co., Ltd., Japan
40-B4-05		ALUMINUM INDUCED CRYSTALLIZATION OF AMORPHOUS SILICON FOR THIN FILM SILICON SOLAR CELLS	H. Kuraseko <sup>1</sup> , N. Orita <sup>1</sup> , H. Koaizawa <sup>1</sup> and M. Kondo <sup>2</sup>	<sup>1</sup> The Furukawa Electric Co, Ltd., Japan, <sup>2</sup> AIST, Japan

Buffer and Interface				
Area 5 December 4th, Tuesday 14:00-15:35 (Room C)				
Chs: H. W. Schock Hahn-Meitner-Institut Berlin, Germany				
A. Yamada Tokyo Institute of Technology, Japan				
4O-C4-01	Invited	STUDY OF BAND ALIGNMENT AT CBD-ZnS(O, OH)/CIGS INTERFACE BY PES/IPES	N. Terada <sup>1,2</sup> , H. Kashiwbara <sup>1</sup> , S. Teshima <sup>1</sup> , T. Okuda <sup>1</sup> , K. Obara <sup>1</sup> , T. Yagioka <sup>3</sup> and T. Nakakda <sup>3</sup>	1Kagoshima University, Japan, 2AIST, Japan, 3Aoyama Gakuin University, Japan
4O-C4-02		PHYSICAL VAPOUR DEPOSITION OF COMPOUND INDIUM SULPHIDE AS BUFFER LAYER IN CU(IN,GA)SE <sub>2</sub> SOLAR CELLS: MATERIAL CHARACTERISATION AND DEVICE PERFORMANCE	P. Pistor <sup>1</sup> , R. Caballero <sup>1</sup> , D. Hariskos <sup>2</sup> , V. Izquierdo-Roca <sup>3</sup> , R. Wächter <sup>4</sup> and Reiner Klenk <sup>1</sup>	1Hahn-Meitner-Institut, Germany, 2Zentrum fuer Sonnenenergie-und Wasserstoff-Forschung, Germany, 3Universitat de Barcelona, Spain, 4Würth Solar GmbH & Co. KG, Germany
4O-C4-03		IMPROVED INTERFACE QUALITY BETWEEN MOCVD-ZNO BUFFER AND CIS-BASED ABSORBER	K. Tabuchi, Y. Fujiwara, H. Hakuma and K. Kushiya	Showa Shell Sekiyu K. K., Japan
4O-C4-04		CIGS SOLAR CELL WITH MBE GRWON ZNS BUFFER LAYER	M. M. Islam <sup>1</sup> , S. Ishizuka <sup>2</sup> , A. Yamada <sup>2</sup> , K. Sakurai <sup>2</sup> , S. Niki <sup>2</sup> , T. Sakurai <sup>1</sup> and K. Akimoto <sup>1</sup>	1The University of Tsukuba, Japan, 2National Institute of Advanced Industrial Science and Technology (AIST), Japan
4O-C4-05		EFFECTS OF CdS BUFFER LAYERS ON PHOTOLUMINESCENCE PROPERTIES OF Cu(In,Ga)Se <sub>2</sub> SOLAR CELLS	S. Shirakata <sup>1</sup> , K. Ohkubo <sup>1</sup> , Y. Ishii <sup>2</sup> and T. Nakada <sup>2</sup>	1Ehime University, Japan, 2Aoyama Gakuin University, Japan
4O-C4-06		CHARACTERIZATION OF ELECTRONIC STRUCTURE OF GRAIN BOUNDARY IN CBD-CdS/CIGS BY UHV-KPFM	K. Masamoto <sup>1</sup> , Y. Watanabe <sup>1</sup> , H. Kashiwbara <sup>1</sup> , T. Okuda <sup>1</sup> , K. Sakurai <sup>2</sup> , A. Yamada <sup>2</sup> , S. Ishizuka <sup>2</sup> , K. Matsubara <sup>2</sup> , S. Niki <sup>2</sup> , S. Nakamura <sup>3</sup> , Y. Yoshimura <sup>3</sup> and N. Terada <sup>1,2</sup>	1Kagoshima Univ., Japan, 2AIST, Japan, 3Kagoshima Pref. Inst. of Industrial Technology, Japan

Dye Sensitized Solar Cell and Organic Thin Film Solar Cell				
Area 1 December 4th, Tuesday 16:00-17:45 (Room A)				
Chs: L. Han SHARP Corporation, Japan				
S. Yoshikawa Kyoto University, Japan				
4O-A5-01		BACK CONTACT DYE-SENSITIZED SOLAR CELLS	N. Fuke, A. Fukui, Y. Chiba, R. Komiya, R. Yamanaka and L. Han	Sharp Corporation, Japan
4O-A5-02		PVDF-HFP/TiO <sub>2</sub> COMPOSITE MEMBRANE ELECTROLYTES FOR DYE-SENSITIZED SOLAR CELLS	H. Yang, O. A. Ileperuma, M. Shimomura and K. Murakami	Shizuoka University, Japan
4O-A5-03		ORIGIN OF THE OPEN-CIRCUIT VOLTAGE OF THE ORGANIC THIN-FILM SOLAR CELLS BASED ON CONJUGATED POLYMERS	T. Yamanari <sup>1</sup> , T. Taima <sup>1</sup> , J. Sakai <sup>2</sup> and K. Saito <sup>1</sup>	1National Institute of Advanced Industrial Science and Technology (AIST), Japan, 2Matsushita Electric Works, Japan
4O-A5-04		SCANNING NEAR-FIELD AND CONFOCAL RAMAN MICROSCOPIC INVESTIGATION OF DIFFERENT MOLECULAR WEIGHT P3HT AND TiO <sub>2</sub> SYSTEMS FOR PHOTOVOLTAIC DEVICES	M. Wu, H. Lo, S. Chen, Y. Huang, Y. Chen, C. Chen and W. Su	National Taiwan University, Taiwan
4O-A5-05		A MICRON SIZE CHARACTERISATION OF ORGANIC SOLAR CELL BLEND FILMS	S. Cook, R. Katoh and A. Furube	National Institute of Advanced Industrial Science and Technology (AIST), Japan
4O-A5-06		THE SUPRA-HIERARCHICAL NANO-STRUCTURED CELL AS A FEASIBLE HIGH PERFORMANCE ORGANIC THIN-FILM SOLAR CELL	S. Yoshikawa	Kyoto University, Japan

Special Session of Japanese Industrial Sectors				
Area 4 December 4th, Tuesday 16:00-17:20 (Room B)				
Chs: M. Isomura Tokai University, Japan				
A. Masuda AIST, Japan				
4O-B5-01	Invited	REQUIREMENTS FOR TCO SUBSTRATE IN SI-BASED THIN FILM SOLAR CELLS - TOWARD TANDEM	T. Oyama, N. Taneda, M. Kambe, K. Sato	Asahi Glass Co., Ltd., Japan
4O-B5-02	Invited	TCO COATED GLASS PRODUCTS FOR THE THIN FILM SILICON PV INDUSTRY	M. Hirata and M. Hyodo	NIPPON SHEET GLASS CO., LTD, Japan
4O-B5-03	Invited	PRODUCTION AND APPLICATION OF FILM SOLAR CELLS	R. Sakai, T. Ishikawa, S. Kawano, M. Shimosawa, T. Nakamura, A. Takano, T. Kamoshita, M. Miyagi and J. Saito	Fuji Electric Systems Co., Ltd., Japan
4O-B5-04	Invited	ENHANCEMENT OF LIGHT TRAPPING IN THE THIN FILM SILICON HYBRID SOLAR CELLS	M. Ichikawa, T. Meguro, F. Sezaki and K. Yamamoto	Kaneka Corporation, Japan
4O-B5-05	Invited	THIN FILM SILICON SOLAR CELL AND MODULE APPLICATIONS	K. Nomoto	Sharp Corporation, Japan

Cell Fabrication and Modeling				
Area 5 December 4th, Tuesday 16:00-17:35 (Room C)				
Chs: V. Kapur International Solar Electric Technology Inc. (ISET), USA				
T. Negami Matsushita Electric Works, Ltd., Japan				
4O-C5-01	Invited	VOLTAGE LIMITATIONS FOR CIGS AND CdTe SOLAR CELLS	J. R. Sites	Colorado State University, USA
4O-C5-02		EFFECT OF MODIFIED STRUCTURE OF MOLYBDENUM BACK CONTACT ON CU(IN,GA)SE <sub>2</sub> PREFERRED ORIENTATION	D. Shin <sup>1</sup> , M. Kim <sup>1</sup> , J. Yun <sup>2</sup> and B. Ahn <sup>1</sup>	1Korea Advanced Institute of Science and Technology, Korea (South), 2Korea Institute of Energy Research, Korea (South)
4O-C5-03		EFFECTS OF THE MORPHOLOGY OF Mo BACK CONTACT ON THE CELL PERFORMANCE OF CIGS DEVICES	T. Morimoto, T. Mise and T. Nakada	Aoyama Gakuin University, Japan
4O-C5-04		SUPPRESSING ZINC DIFFUSION FROM ZNO BACK CONTACTS IN BIFACIAL CIGS SOLAR CELLS	K. Sakurai <sup>1</sup> , M. Yonemura <sup>2</sup> , S. Ishizuka <sup>1</sup> , H. Nakanishi <sup>2</sup> and S. Niki <sup>1</sup>	1AIST, Japan, 2Tokyo Univ. of Science, Japan
4O-C5-05		EFFECT OF COMPOSITION GRADIENT IN CU(IN,AL)SE <sub>2</sub> SOLAR CELLS	T. Hayashi, T. Minemoto, K. Tanaka, S. Yamada, T. Araki and H. Takakura	Ritsumeikan University, Japan
4O-C5-06		DEPTH PROFILING OF CIGS THIN FILMS GROWN AT LOW TEMPERATURES	C. A. Kaufmann, R. Caballero, T. Unold, R. Hesse, M. Nichterwitz and H. W. Schock	Hahn-Meitner-Institut Berlin GmbH, Germany

<b>Plenary 3</b> <b>Area 3 December 5th, Wednesday 8:30-9:30 (Main Hall)</b> <b>Chs: R. Swanson SunPower Corporation, USA</b> <b>T. Saitoh Tokyo University of Agriculture and Technology, Japan</b>				
PL3-1		MASS-PRODUCTION PROCESS FOR 18.0% HIGH EFFICIENCY MULTI-CRYSTALLINE SILICON SOLAR CELL	H. Morikawa, T. Sato, S. Matsuno and S. Arimoto	Mitsubishi Electric Corporation, Japan
PL3-2		ADVANCES IN HIGH EFFICIENCY CRYSTALLINE SILICON SOLAR CELLS	G. Willeke, S. Glunz and O. Schultz	Fraunhofer ISE, Germany
PL3-3		EMITTER-WRAP-THROUGH BACK-CONTACT MULTICRYSTALLINE-SILICON SOLAR CELLS AND MODULES	J. M. Gee, P. Hacke and M. Hilali	Advent Solar, Inc., USA

<b>Plenary 4</b> <b>Area 4 December 5th, Wednesday 9:30-10:30 (Main Hall)</b> <b>Chs: S. Nonomura Gifu University, Japan</b> <b>R. Schropp Utrecht University, The Netherlands</b>				
PL4-1		THIN FILM SILICON SOLAR CELLS: LATEST DEVELOPMENT AND FUTURE PROSPECT	M. Kondo	National Institute of Advanced Industrial Science and Technology (AIST), Japan
PL4-2		THIN FILM SILICON SOLAR CELLS: LATEST DEVELOPMENTS IN EUROPE	J. Bailat, D. Dominé, P. Buehlmann, A. Billet, A. Feltrin, F. Meillaud, T. Söderström, X. Niquille, F. J. Haug, V. Daudrix-Terrazoni, N. Wyrsh and C. Ballif	Université de Neuchâtel, Switzerland
PL4-3		TOWARD FILM CRYSTAL SILICON ON GLASS FOR PHOTOVOLTAICS: PROGRESS ON EPITAXY AND INSIGHTS INTO CVD DEPOSITION	C. W. Teplin, P. Stradins, Q. Wang, K. M. Jones, C. Jiang, V. Yost and H. M. Branz	National Renewable Energy Laboratory, USA

<b>Crystal Growth, Impurities and Defects in Si</b> <b>Area 3 December 5th, Wednesday 11:00-12:30 (Main Hall)</b> <b>Chs: N. Usami Tohoku University, Japan</b> <b>M. Hofmann Fraunhofer-Institut für Solare Energiesysteme ISE, Germany</b>				
50-M1-01		UNIDIRECTIONAL SOLIDIFICATION GROWTH OF MULTICRYSTALLINE SILICON USING ACCELERATED CRUCIBLE ROTATION TECHNIQUE (ACRT)	R. Bairava Ganesh <sup>1,2</sup> , H. Matsuo <sup>1</sup> , Y. Kangawa <sup>1</sup> , K. Arafune <sup>3</sup> , Y. Ohshita <sup>3</sup> , M. Yamaguchi <sup>3</sup> and K. Kakimoto <sup>1</sup>	1Kyushu University, Japan, 2Anna University, India, 3Toyota Technological Institute, Japan
50-M1-02		INNOVATIVE CRYSTALLISATION OF MULTI-CRYSTALLINE SILICON	R. Einhaus <sup>1</sup> , J. Kraiem <sup>1</sup> and F. Lissalde <sup>2</sup>	1APOLLON SOLAR, France, 2CYBERSTAR, France
50-M1-03		FLOATING CAST METHOD (FCM) AS A NEW GROWTH METHOD TO REALIZE HIGH-QUALITY BULK MULTICRYSTALLINE SILICON FOR SOLAR CELLS	I. Takahashi <sup>1</sup> , N. Usami <sup>1</sup> , R. Yokoyama <sup>1</sup> , Y. Nose <sup>2</sup> , K. Fujiwara <sup>1</sup> and K. Nakajima <sup>1</sup>	1Tohoku University, Japan, 2Kyoto University, Japan
50-M1-04		FE MAPPING IMAGES OF MC-SILICON WAFERS OBSERVED BY MÖSSBAUER MICROSCOPE	Y. Yoshida, K. Sakata, M. Adachi and K. Suzuki	Shizuoka Institute of Science and Technology, Japan
50-M1-05		QUANTITATIVE ANALYSIS OF GRAIN BOUNDARY RECOMBINATION IN MULTI-CRYSTALLINE SILICON WAFERS	A. R. Burgers <sup>1</sup> , L. J. Geerligs <sup>1</sup> , D. H. Macdonald <sup>2</sup> and A. Azzizi <sup>1</sup>	1ECN Solar Energy, The Netherlands, 2Australian National University, Australia
50-M1-06		IMPROVED SOLAR CELL EFFICIENCIES VIA LOW-TEMPERATURE ANNEALING GUIDED BY THE IRON "TIME-TEMPERATURE-TRANSFORMATION DIAGRAM"	T. Buonassisi <sup>1</sup> , M. D. Pickett <sup>2</sup> , S. M. Heald <sup>3</sup> , B. Lai <sup>3</sup> and Z. Cai <sup>3</sup>	1Massachusetts Institute of Technology, USA, 2University of California, Berkeley, USA, 3Argonne National Laboratory, USA

<b>Organic Thin Film Solar Cell</b> <b>Area 1 December 5th, Wednesday 11:00-12:30 (Room A)</b> <b>Chs: C. Park Yeungnam University, Korea (South)</b> <b>Y. Nishikitani Nippon Oil Corporation, Japan</b>				
50-A6-01		CONTROLLING THE MORPHOLOGY OF NANOCRYSTAL-POLYMER COMPOSITE FOR BULK HETERO-JUNCTION SOLAR CELLS	T. N. T. Nguyen, U. Farva, Y. Kim, Y. Na and C. Park	Yeungnam University, Korea (South)
50-A6-02		APPLICATION OF CARBON NANOMATERIALS FOR SOLAR ENERGY CONVERSION	M. Umeno and P. R. Somani	Chubu University, Japan
50-A6-03		ORGANIC THIN-FILM SOLAR CELL EMPLOYING A NOVEL ELECTRON-DONOR MATERIAL	H. Kanno, M. Shirakawa, D. Fujishima, T. Kinoshita, H. Sakata, E. Maruyama and M. Tanaka	Sanyo Electric Co., Ltd., Japan
50-A6-04	Invited	SYNTHESIS OF HIGHLY REGIOREGULAR POLY[(2-METHOXY-5-ALKYLOXY)-1,4-PHENYLENEVINYLENE]S (PPVS) BY HORNER REACTION AND THEIR APPLICATION FOR EFFICIENT PHOTOVOLTAIC DEVICES	K. Tajima, Y. Suzuki and K. Hashimoto	The University of Tokyo, Japan
50-A6-05		SPONTANEOUS FORMATION OF BUFFER LAYERS IN ORGANIC SOLAR CELLS	Q. Wei, K. Tajima and K. Hashimoto	The University of Tokyo, Japan

<b>Fundamental Science and Innovative Concepts</b> <b>Area 4 December 5th, Wednesday 11:00-12:35 (Room B)</b> <b>Chs: H. Fujiwara AIST, Japan</b> <b>S. Higashi Hiroshima University, Japan</b>				
50-B6-01	Invited	LIGHT SCATTERING EFFECTS OF HIGHLY TEXTURED TRANSPARENT CONDUCTIVE OXIDES FILMS	N. Taneda, T. Oyama and K. Sato	Asahi Glass Co., Ltd., Japan
50-B6-02		HIGH MOBILITY HYDROGEN-DOPED IN <sub>2</sub> O <sub>3</sub> TRANSPARENT CONDUCTIVE OXIDE FOR A-SI/H <sub>2</sub> C-SI HETEROJUNCTION SOLAR CELLS	T. Koida, H. Fujiwara and M. Kondo	National Institute of Advanced Industrial Science and Technology (AIST), Japan
50-B6-03		BACK SURFACE REFLECTOR WITH PERIODIC TEXTURES FABRICATED BY SELF-ORDERING PROCESS FOR LIGHT TRAPPING IN MICROCRYSTALLINE SILICON SOLAR CELLS	H. Sai, H. Fujiwara and M. Kondo	National Institute of Advanced Industrial Science & Technology (AIST), Japan
50-B6-04		THE NUCLEATION AND GRAIN GROWTH OF HIGH-GROWTH-RATE (7 NM/S) MICROCRYSTALLINE SILICON PHOTOVOLTAIC FILMS	S. Nakano, W. Yoshida, Y. Sobajima, T. Toyama and H. Okamoto	Osaka University, Japan
50-B6-05		HIGH QUALITY POLYCRYSTALLINE SILICON FILMS WITH LONG CARRIER LIFETIME PREPARED BY FLASH LAMP ANNEALING OF CAT-CVD AMORPHOUS SILICON AND SUCCESSIONAL HIGH-PRESSURE WATER VAPOR ANNEALING	Y. Endo, T. Fujiwara, S. Nishizaki, K. Ohdaira, K. Nishioka and H. Matsumura	Jpn. Adv. Inst. Sci. & Tech. (JAIST), Japan
50-B6-06		TWO-DIMENSIONAL PHOTON-COUNTING LASER-LIGHT-SCATTERING METHOD FOR DETECTING NANO-PARTICLES IN CVD PLASMAS	S. Iwashita, M. Morita, K. Koga and M. Shiratani	Kyushu University, Japan

<b>Grid Connected Systems</b> <b>Area 7 December 5th, Wednesday 11:00-12:30 (Room C)</b> <b>Chs: K. Komoto Mizuho Information &amp; Research Institute, Inc., Japan</b> <b>G. Makrides University of Cyprus, Cyprus</b>				
50-C6-01		ECONOMIC ANALYSIS OF 10.56KWp GRID CONNECTED PHOTOVOLTAIC SYSTEMS AT THE UNIVERSITY OF MASSACHUSETTS LOWELL	A. Cultura II and Z. Salameh	University of Massachusetts Lowell, USA
50-C6-02		STATISTICAL EVALUATION OF VOLTAGE VARIATION OF POWER DISTRIBUTION SYSTEM WITH CLUSTERED RESIDENTIAL PV SYSTEMS	T. Kato, A. Minagata and Y. Suzuoki	Nagoya University, Japan
50-C6-03		ESTIMATING THE CAPACITY VALUE AND PEAK-SHAVING POTENTIAL OF PHOTOVOLTAICS IN ONTARIO: A CASE-STUDY FOR THE CITY OF TORONTO	S. Pelland <sup>1</sup> and I. Abboud <sup>2</sup>	<sup>1</sup> CANMET Energy Technology Centre-Varennes, Canada, <sup>2</sup> Environment Canada Experimental Studies Division ARQX, Canada
50-C6-04		INTRODUCTION OF WAKKANAI MEGA-SOLAR PROJECT	S. Miwa, N. Matsuno and H. Mizunaga	Hokkaido Electric Power Co. Ltd., Japan
50-C6-05		INTRODUCTION OF HOKUTO MEGA-SOLAR PROJECT	H. Konishi, R. Tanaka and T. Shiraki	NTT FACILITIES INC., Japan
50-C6-06		A POWER QUALITY STUDY OF A PV GRID-CONNECTED SYSTEM DUE TO LOAD CONDITIONS	N. Ruangrotsin, D. Chenvidhya, K. Kirtikara, K. Wattanavichian and E. Pakpairote	King Mongkut's University of Technology Thonburi, Thailand

<b>Passivation, Antireflection</b> <b>Area 3 December 5th, Wednesday 14:00-15:30 (Main Hall)</b> <b>Chs: T. Warabisako AIST, Japan</b> <b>A. Cuevas The Australian National University, Australia</b>				
50-M2-01	Invited	RECENT DEVELOPMENTS IN REAR SURFACE PASSIVATION AT FRAUNHOFER ISE	M. Hofmann, C. Schmidt, S. Kambor, N. Kohn, J. Rentsch, S. Glunz and R. Preu	Fraunhofer Institute for Solar Energy Systems, Germany
50-M2-02		PASSIVATION OF P-TYPE EMITTERS AND SOLAR CELLS BY ALD GROWN Al <sub>2</sub> O <sub>3</sub>	B. Hoex <sup>1</sup> , J. Schmidt <sup>2</sup> , A. Merkle <sup>2</sup> , R. Brendel <sup>2</sup> , M. C. M. van de Sanden <sup>1</sup> and W. M. M. Kessels <sup>1</sup>	<sup>1</sup> Eindhoven University of Technology, The Netherlands, <sup>2</sup> Institut für Solarenergieforschung Hameln/Emmerthal (ISFH), Germany
50-M2-03		PREPARATION OF a-SiO:H REAR SIDE PASSIVATION LAYER FOR CAST POLY CRYSTALLINE SILICON SOLAR CELLS	H. Yamamoto <sup>1</sup> , T. Sugiura <sup>1</sup> , A. Limmanee <sup>1</sup> , T. Sato <sup>2</sup> , S. Miyajima <sup>1</sup> , A. Yamada <sup>1</sup> and M. Konagai <sup>1</sup>	<sup>1</sup> Tokyo Institute of Technology, Japan, <sup>2</sup> Mitsubishi Electric Corporation, Japan
50-M2-04		EFFECTIVE SURFACE PASSIVATION OF SCREEN-PRINTED AL-DOPED P+-EMITTERS FOR N-TYPE C-SI SOLAR CELLS USING A-SI	R. Bock, J. Schmidt and R. Brendel	Institut für Solarenergieforschung Hameln/Emmerthal (ISFH), Germany
50-M2-05		REAR SURFACE SIN PASSIVATED MONOCRYSTALLINE SILICON THIN FILM SOLAR CELLS WITH LASER FIRED PROCESS	Y. Takahashi, A. Ogane, K. Horiuchi, Y. Kishiyama, A. Kitiyanan, Y. Uraoka and T. Fuyuki	Nara Institute of Science and Technology, Japan
50-M2-06		EXPERIMENTAL COMPARISON OF ALUMINIUM BSF AND OXIDE PASSIVATED REAR SURFACE FOR CRYSTALLINE SILICON SOLAR CELLS	O. Schultz <sup>1</sup> , A. Mette <sup>1,2</sup> and S. W. Glunz <sup>1</sup>	<sup>1</sup> Fraunhofer ISE, Germany, <sup>2</sup> Q-Cells AG, Germany

<b>Organic Thin Film Solar Cell and Next Generation Inorganic Solar Cell</b> <b>Area 1 December 5th, Wednesday 14:00-15:30 (Room A)</b> <b>Chs: T. Kitamura Fujikura Ltd., Japan</b> <b>V. Švrček AIST, Japan</b>				
50-A7-01		HIGH EFFICIENCY OF BULK HETERO-JUNCTION SOLAR CELLS	N. Koide <sup>1</sup> , L. Han <sup>1</sup> , H. Lee <sup>2</sup> and T. Arai <sup>2</sup>	<sup>1</sup> SHARP CORPORATION, Japan, <sup>2</sup> International Center for Materials Research (ICMR), Japan
50-A7-02		OPTICAL STUDY OF NANOSTRUCTURE P3HT/PCBM HYBRID PHOTOVOLTAIC DEVICE	Y. Huang, M. Wu, C. Chen and W. Su	National Taiwan University, Taiwan
50-A7-03		INFLUENCE OF ANNEALING TEMPERATURES ON THE STRUCTURAL AND OPTICAL PROPERTIES OF CdSe NANOPARTICLES	U. Farva, Y. Na and C. Park	Yeungnam University, Korea (South)
50-A7-04		MODIFICATION OF ELECTRONIC PROPERTIES IN SILICON QUANTUM DOT SUPERLATTICE	E. Cho, X. Hao, S. Park, I. P. Wurfl, G. Conibeer and M. A. Green	University of New South Wales, Australia
50-A7-05		FABRICATION OF CRYSTALLINE TYPE-CONTROLLED NANOCRYSTALS EMBEDDED IN SIC MATRIX FOR THIRD GENERATION PHOTOVOLTAICS	D. Song, E. Cho, G. Conibeer, G. Scardera and M. A. Green	University of New South Wales, Australia
50-A7-06		ELECTRICAL PROPERTIES OF N-TYPE SILICON QUANTUM DOTS AND P-TYPE CRYSTALLINE SILICON HETEROJUNCTION DEVICES	S. Park, E. Cho, X. Hao, G. Scardera, D. Song, G. Conibeer and M. A. Green	University of New South Wales, Australia

<b>Solar Cells and Related Science &amp; Technologies</b> <b>Area 4 December 5th, Wednesday 14:00-15:35 (RoomB)</b> <b>Chs: K. Yamamoto Kaneka Corporation, Japan</b> <b>Y. Matsumoto National Polytechnic Institute, Japan</b>				
50-B7-01	Invited	NANOSTRUCTURED THIN FILMS FOR MULTIBANDGAP SILICON TRIPLE JUNCTION SOLAR CELLS	R. E. I. Schropp, H. Li, R. H. J. Franken, J. K. Rath, C. H. M. van der Werf, J. A. Schüttauf, and R. L. Stolk	Utrecht University, The Netherlands
50-B7-02		THIN FILM SOLAR CELLS BASED ON MICROCRYSTALLINE SILICON-GERMANIUM NARROW GAP ABSORBERS	T. Matsui <sup>1</sup> , C.W. Chang <sup>1</sup> , T. Takada <sup>1,2</sup> , M. Isomura <sup>2</sup> , H. Fujiwara <sup>1</sup> and M. Kondo <sup>1</sup>	<sup>1</sup> National Institute of Advanced Industrial Science and Technology (AIST), Japan, <sup>2</sup> Tokai University, Japan
50-B7-03		PERFORMANCE OF SUPERSTRATE MULTI-JUNCTION AMORPHOUS SILICON BASED SOLAR CELLS USING OPTICAL LAYERS FOR CURRENT MANAGEMENT	C. Das, M. Berginski, A. Doumit, A. Lambertz, F. Finger, A. Gordijn, H. Stiebig, J. Huepkes, J. Kirchoff and W. Reetz	Forschungszentrum Juelich, Germany
50-B7-04		6.3% EFFICIENCY SOLAR CELL EMPLOYING HIGH DEPOSITION RATE (8 NM/S) MICROCRYSTALLINE SILICON PHOTOVOLTAIC LAYER	Y. Sobajima, M. Nishino, T. Fukumori, T. Higuchi, S. Nakano, T. Toyama and H. Okamoto	Osaka University, Japan
50-B7-05		N/I 'SEED LAYER' FOR N-SIDE ILLUMINATED HIGH-EFFICIENCY N-I-P MICROCRYSTALLINE SILICON SOLAR CELLS WITH HOT WIRE-DEPOSITED MICROCRYSTALLINE SILICON CARBIDE WINDOW LAYERS	Y. Huang <sup>1</sup> , A. Dasgupta <sup>1</sup> , T. Chen <sup>1,2</sup> , F. Finger <sup>1</sup> , A. Gordijn <sup>1</sup> , M. Luysberg <sup>1</sup> , L. Houben <sup>1</sup> and R. Carius <sup>1</sup>	<sup>1</sup> Forschungszentrum Jülich, Germany, <sup>2</sup> Zhejiang University, China (PRC)



**Grid Connected Systems & Hybrid Systems**

**Area 7 December 5th, Wednesday 14:00-15:30 (Room C)**

**Chs: K. Kurokawa Tokyo University of Agriculture and Technology, Japan**

**Z. Salameh University of Massachusetts Lowell, USA**

50-C7-01	Invited	DEVELOPMENT OF A DISTRIBUTION SYSTEM VOLTAGE CONTROL METHOD FOR PV SYSTEMS – A NEW REACTIVE POWER CONTROL METHOD FOR RESTRAINING VOLTAGE RISE –	Y. Hirabaru, H. Hatta and H. Kobayashi	Central Research Institute of Electric Industry, Japan
50-C7-02		OPERATION DESIGN OF STORAGE BATTERY STATION IN PV CLUSTER	S. Wakao and A. Otani	Waseda University, Japan
50-C7-03		OPERATING CONTROL STRATEGIES FOR AUTONOMOUS PHOTOVOLTAIC SYSTEMS AND HYBRID PV MINI-GRIDS — OVERVIEW ON ADJUSTED SOLUTIONS FOR DIFFERENT APPLICATIONS	M. Vetter, G. Bopp and S. Schwunk	Fraunhofer Institute for Solar Energy Systems ISE, Germany
50-C7-04		VERIFICATION OF PROPOSED ACTIVE OPERATION OF POWER GRID WITH PV SYSTEMS BY SCALED-DOWN DISTRIBUTION NETWORK EQUIPMENT	Y. Hayashi <sup>1</sup> , S. Sakai <sup>1</sup> , J. Matsuki <sup>1</sup> , Y. Fuwa <sup>2</sup> and K. Mori <sup>2</sup>	1 University of Fukui, Japan, 2 Tokyo Electric Power Company, Japan
50-C7-05		BREAKTHROUGH TO A NEW ERA OF PV-HYBRID SYSTEMS WITH THE HELP OF STANDARDISED COMPONENTS COMMUNICATION	M. Müller <sup>1</sup> and G. Bopp <sup>2</sup>	1Steca GmbH, Germany, 2Fraunhofer Institut Solare Energiesysteme ISE, Germany

**Modeling, Characterization**

**Area 3 December 5th, Wednesday 16:00-17:30 (RoomM)**

**Chs: S. Arimoto Mitsubishi Electric Corporation, Japan**

**Y. Ma IMEC vzw, Belgium**

50-M3-01		SIMULATING SUNS-VOC SILICON SOLAR CELL CHARACTERISATION WITH A NEW QSS-MODEL	A. Cuevas and J. Tan	The Australian National University, Australia
50-M3-02		ANALYSIS OF N-TYPE MULTICRYSTALLINE SILICON WAFERS FOR SOLAR CELLS BY PHOTOLUMINESCENCE IMAGING WITH HF IMMERSION	H. Sugimoto <sup>1</sup> , M. Tajima <sup>1</sup> , I. Yamaga <sup>2</sup> , M. Dhamrin <sup>3</sup> , K. Kamisako <sup>3</sup> and T. Saitoh <sup>3</sup>	1ISAS/JAXA, Japan, 2Dai-ichi Kiden Co., Japan, 3TUAT, Japan
50-M3-03		TEMPERATURE-DEPENDENT ELECTROLUMINESCENCE CHARACTERISATION OF SILICON SOLAR CELLS	K. Bothe <sup>1</sup> , D. Hinken <sup>1</sup> , K. Ramspeck <sup>1</sup> , A. Kitoiyanan <sup>2</sup> and T. Fuyuki <sup>2</sup>	1Institut für Solarenergieforschung Hameln/Emmerthal (ISFH), Germany, 2Nara Institute of Science and Technology (NAIST), Japan
50-M3-04		SERIES RESISTANCE IMAGING OF SOLAR CELLS BY VOLTAGE DEPENDENT ELECTROLUMINESCENCE	D. Hinken <sup>1</sup> , K. Bothe, K. Ramspeck and R. Brendel	Institut für Solarenergieforschung Hameln/Emmerthal (ISFH), Germany
50-M3-05		RECOMBINATION CURRENT AND SERIES RESISTANCE IMAGING ON MULTICRYSTALLINE SILICON SOLAR CELLS	K. Ramspeck, K. Bothe, D. Hinken, J. Schmidt, B. Fischer and R. Brendel	Institut für Solarenergieforschung Hameln (ISFH), Germany
50-M3-06		NEW CONCEPT TO IMPROVE THE SPECIFIC CONTACT RESISTANCE AND FINGER CONDUCTIVITY OF THE SCREEN-PRINTED AG METAL CONTACTS FOR THE SILICON SOLAR CELLS	P. N. Vinod	Naval Physical and Oceanographic Laboratory, India

**Next Generation Inorganic Solar Cell**

**Area 1 December 5th, Wednesday 16:00-17:45 (Room A)**

**Ch: M. Umeno Chubu University, Japan**

**D. Kim Korea University, Japan**

50-A8-01	Invited	PROGRESS ON HOT CARRIER CELLS	G. Conibeer <sup>1</sup> , J. F. Guillemoles <sup>2</sup> , D. König <sup>1</sup> , S. Shrestha <sup>1</sup> and M. A. Green <sup>1</sup>	1ARC Photovoltaics Centre of Excellence, Australia, 2 IRDEP: joint CNRS-EDF-ENSCP, France
50-A8-02		NITROGEN INCORPORATION IN C60 FILMS FOR THE PHOTOVOLTAIC APPLICATION	S. M. Mominuzzaman <sup>1,2</sup> , T. Soga <sup>1</sup> , and T. Jimbo <sup>1</sup>	1Nagoya Institute of Technology, Japan, 2Bangladesh University of Engineering and Technology, Bangladesh
50-A8-03		IMPACT OF INTERFACE ON THE EFFECTIVE BAND GAP OF Si QUANTUM DOTS	D. König, J. Rudd, M. A. Green and G. Conibeer	The University of New South Wales, Australia
50-A8-04		LUMINESCENT PROPERTIES OF DOPED FREESTANDING SILICON NANOCRYSTALS EMBEDDED IN MEH-PPV	V. Švrček, H. Fujiwar and M. Kondo	National Institute of Advanced Industrial Science and Technology (AIST), Japan
50-A8-05		STRUCTURAL, OPTICAL AND ELECTRICAL PROPERTIES OF INDIUM SULFIDE THIN FILMS DEPOSITED BY PULSED ELECTROCHEMICAL DEPOSITION	A. M. Abdel Haleem and M. Ichimura	Nagoya Institute of Technology, Japan
50-A8-06		ZINC OXIDE NANOROD ARRAYS FOR SOLAR CELLS WITH EXTREMELY THIN SULFIDIC ABSORBER	A. Belaidi <sup>1</sup> , Th. Dittrich <sup>1</sup> , D. Kieven <sup>1</sup> , J. Tornow <sup>1</sup> , K. Schwarzburg <sup>1</sup> , M. Kunst <sup>1</sup> , N. Allsop <sup>1</sup> and S. Gavrilov <sup>2</sup>	1Hahn-Meitner-Institut, Germany, 2Moscow Institute of Electronic Technology, Russia

**Solar Cells and Related Science & Technologies**

**Area4 December 5th, Wednesday 16:00-17:35 (Room B)**

**Chs: M. Shiratani Kyushu University, Japan**

**T. Toyama Osaka University, Japan**

50-B8-01	Invited	DEVELOPMENT OF HIGH EFFICIENCY MICROMORPH TANDEM SOLAR CELLS ON FLEXIBLE LOW COST PLASTIC SUBSTRATES	F. J. Haug, V. Terrazzoni-Daudrix, T. Söderström, X. Niquille and C. Ballif	University of Neuchâtel, Switzerland
50-B8-02		MONOLITHIC SERIES INTERCONNECTION OF THIN-FILM SILICON SOLAR CELLS ON FLEXIBLE SUBSTRATES	J. Löffler <sup>1</sup> , C. Ballif <sup>2</sup> , K. Brecl <sup>3</sup> , K. Brooks <sup>4</sup> , C. Finck <sup>5</sup> , D. Fischer <sup>4</sup> , F. J. Haug <sup>2</sup> , R. Mayerhofer <sup>5</sup> , W. J. Soppe <sup>1</sup> , M. Späth <sup>1</sup> , M. Topic <sup>3</sup> and M. Wutz <sup>5</sup>	1ECN, The Netherlands, 2University of Neuchâtel, Switzerland, 3University of Ljubljana, Slovenia, 4 VHF Technologies S.A., Switzerland, 5Rofin / Baasel Lasertech, Germany
50-B8-03		EXPERIMENTAL STUDIES OF THE LIGHT TRAPPING AND OPTICAL LOSSES IN MICROCRYSTALLINE SILICON SOLAR CELLS	M. Berginski <sup>1</sup> , J. Hüpkes <sup>1</sup> , A. Gordijn <sup>1</sup> , W. Reetz <sup>1</sup> and M. Wuttig <sup>2</sup>	1Forschungszentrum Jülich GmbH, Germany, 2RWTH Aachen University, Germany
50-B8-04		POLYCRYSTALLINE SILICON THIN-FILM SOLAR CELLS ON GLASS	S. Gall, C. Becker, E. Conrad, P. Dogan, F. Fenske, B. Gorka, K. Y. Lee, B. Rau, F. Ruske and B. Rech	Hahn-Meitner-Institut Berlin, Germany
50-B8-05		A-Si:H SINGLE JUNCTION AND A-Si:H/UC-Si:H TANDEM SOLAR CELLS FABRICATED USING LARGE AREA (GEN8 SIZE) PECVD SYSTEMS	L. Li, Y. Chae, S. Sheng, T. Won, A. Kadam, J. Chen, S. Choi and J. M. White	AKT/Applied Materials, USA
50-B8-06		MILESTONES AND KEY PARAMETERS OF THE 'NOVA' AMORPHOUS SILICON PRODUCTION LINE OF ERSOL THIN FILM	L. Feitknecht and L. Mittelstädt	Ersol Thin Film GmbH, Germany

**Grid Connected Systems & PV System Codes and Standards**

**Area 7 December 5th, Wednesday 16:00-17:30 (Room C)**

**Chs: S. Nishikawa Nihon University, Japan**

**K. Kirtikara King Mongkut's University of Technology Thonburi, Thailand**

50-C8-01	Invited	PERFORMANCE OF GRID CONNECTED PV INVERTERS DURING DISTURBED GRID CONDITIONS - CURRENT STATE OF PLAY & RECOMMENDATIONS FOR OPTIMAL PRODUCT DESIGN	R. Bruendinger, B. Bletterie and C. Mayr	arsenal research, Austria
50-C8-02		AN ANALYSIS OF ELECTRICITY COST OF PHOTOVOLTAIC SYSTEMS ON THE FIELD TEST PROJECT IN JAPAN	T. Oozeki <sup>1</sup> , T. Yamada <sup>1</sup> , K. Kato <sup>1</sup> and T. Yamamoto <sup>2</sup>	1National Institute of Advanced Industrial Science and Technology, Japan, 2New Energy and Industrial Technology Development Organization (NEDO), Japan
50-C8-03		UNCERTAINTY IN MEASURED PERFORMANCE PHOTOVOLTAIC PERFORMANCE PARAMETERS – DEPENDENCE ON LOCATION AND MATERIAL	M. B. Strobel <sup>1</sup> , R. Gottschalg <sup>1</sup> , G. Friesen <sup>2</sup> and H. G.Beyer <sup>3</sup>	1Loughborough University, UK, 2SUPSI-LEEE, Switzerland, 3Hochschule Magdeburg-Stendal, Germany
50-C8-04		GRID COMPATIBILITY OF DISTRIBUTED PHOTOVOLTAIC SYSTEMS	G. H. Atmaram	Florida Solar Energy Center, USA
50-C8-05		PERFORMANCE ANALYSIS OF VARIOUS SYSTEM CONFIGURATIONS ON GRID-CONNECTED RESIDENTIAL PV SYSTEMS	Y. Ueda <sup>1</sup> , K. Kurokawa <sup>1</sup> , K. Kitamura <sup>2</sup> , M. Yokota <sup>3</sup> , K. Akanuma <sup>3</sup> and H. Sugihara <sup>3</sup>	1Tokyo University of Agriculture and Technology, Japan, 2MEIDENSHA CORPORATION, Japan, 3Kandenko co., Ltd., Japan
50-C8-06		TEMPERATURE BEHAVIOUR OF DIFFERENT PHOTOVOLTAIC SYSTEMS INSTALLED IN CYPRUS AND GERMANY	G. Makrides <sup>1</sup> , B. Zinsser <sup>2</sup> , G. E. Georghiou <sup>1</sup> and J. Werner <sup>2</sup>	1University of Cyprus, Cyprus, 2Institute of Physical Electronics, Germany

Plenary 2				
Area 2 December 6th, Thursday 8:30-9:30 (Main Hall)				
Chs: S. Kurtz NREL, USA				
A. Yamamoto University of Fukui, Japan				
PL2-1		PROGRESS IN HIGH-CONCENTRATION PHOTOVOLTAIC SYSTEMS	J. Luther	Fraunhofer Institute for Solar Energy Systems ISE, Germany
PL2-2		PRODUCTION AND DEVELOPMENT ACTIVITIES IN MULTI-JUNCTION SOLAR CELLS FOR CONCENTRATOR PHOTOVOLTAICS	D. D. Krut, R. R. Kindg, G. S. Kinsley, P. Pien, P. Hebert, R. A. Sherif, J. Lacey, R. Brandt, N. H. Karam and B. T. Cavicchi	Spectrolab, Inc., USA
PL2-3		OVERVIEW OF HIGH EFFICIENCY III-V CELL ACTIVITIES	T. Takamoto	Sharp Corporation, Japan

Plenary 6				
Area 6 December 6th, Thursday 9:30-10:30 (Main Hall)				
Chs: Y. Ishihara Doshisha University, Japan				
W. Bower Sandia National Laboratories, USA				
PL6-1		PV MODULE RECYCLING	K. Wambach, S. Schlenker and A. Müller	Deutsche Solar AG, Germany
PL6-2		APPLICATION OF BATTERY TO THE PHOTOVOLTAIC SYSTEM - UTILITY PEAK-SHAVING SYSTEM WITH NI-MH BATTERY	M. Ryoji <sup>1</sup> and N. Tokuda <sup>2</sup>	1Kawasaki Heavy Industries, Ltd., Japan, 2Kawasaki Plant Systems, Ltd., Japan

High Efficiency Solar Cells; Heterojunction, N Type Si				
Area 3 December 6th, Thursday 11:00-12:30 (Main Hall)				
Chs: H. Fujiwara AIST, Japan				
P. Fath GP Solar GmbH, Germany				
6O-M4-01	Invited	22%-EFFICIENCY HIT SOLAR CELL	Y. Tsunomura, Y. Yoshimine, M. Taguchi, T. Kinoshita, H. Kanno, H. Sakata, E. Maruyama and M. Tanaka	Sanyo Electric Co., Ltd., Japan
6O-M4-02		HOMOGENEOUS P+ EMITTER DIFFUSED USING BORON TRIBROMIDE FOR RECORD 15.6% SCREEN PRINTED LARGE AREA N-TYPE MC-SI SOLAR CELL	Y. Komatsu <sup>1</sup> , V. D. Mihailitchi <sup>1</sup> , L. J. Geerligs <sup>1</sup> , B. van Dijk <sup>2</sup> , J. B. Rem <sup>2</sup> and M. Harris <sup>2</sup>	1ECN Solar Energy, The Netherlands, 2Tempress Systems B.V., The Netherlands
6O-M4-03		A-SI:H/C-SI HETEROJUNCTION SOLAR CELLS ON P-TYPE C-SI WAFERS	P. J. Rostan <sup>1</sup> , J. Maier <sup>1</sup> , T. Kirchartz <sup>2</sup> , U. Rau <sup>2</sup> , F. Einsele <sup>3</sup> , R. Merz <sup>3</sup> , M. B. Schubert <sup>3</sup> and J. H. Werner <sup>3</sup>	1centrotherm photovoltaics technology GmbH, Germany, 2Forschungszentrum Jülich GmbH, Germany, 3Universität Stuttgart, Germany
6O-M4-04		FABRICATION OF N- AND P-TYPE HETEROJUNCTION SOLAR CELLS BY USING HYDROGENATED MICROCRYSTALLINE SILICON OXIDE FILM AS AN EMITTER	J. Sriharathikun, A. Yamada and M. Konagai	Tokyo Institute of Technology, Japan
6O-M4-05		INTERDIGITATED BACK CONTACT AMORPHOUS/CRYSTALLINE SILICON HETEROJUNCTION SOLAR CELLS	S. De Lulius <sup>1</sup> , G. de Cesare <sup>2</sup> , M. Ceccarelli <sup>2</sup> , L. Serenelli <sup>3</sup> , L. J. Geerligs <sup>1</sup> and M. Tucci <sup>3</sup>	1ECN Solar Energy, The Netherlands, 2University "Sapienza", Italy, 3ENEA Research Center Casaccia, Italy
6O-M4-06		LARGE AREA N-TYPE REAR JUNCTION MULTICRYSTALLINE SILICON SOLAR CELLS	R. H. Franken, F. Dross, E. van Kerschaver and G. Beaucarne	IMEC, v.z.w., Belgium

PV Modules and BOS Components				
Area 6 December 6th, Thursday 11:00-12:30 (Room A)				
Chs: S. Nishikawa Nihon University, Japan				
D. Ton U.S. Department of Energy, USA				
6O-A9-01	Invited	DEVELOPMENT OF THIN FILM Si HYBRID SOLAR MODULE	A. Nakajima, M. Gotoh, T. Sawada, S. Fukuda, M. Yoshimi and T. Nomura	Kaneka Corporation, Japan
6O-A9-02		IMPROVEMENT IN LIGHT TRAPPING BY USING TEXTURED COVER GLASSES	W. A. Nositschka, D. Neumann, M. O. Prast and F. Gromball	Saint-Gobain Vitrage Herzogenrath R&D Center, Germany
6O-A9-03		A NOVEL MODULE ASSEMBLY LINE USING BACK CONTACT SOLAR CELLS	M. Späth <sup>1</sup> , P.C. de Jong <sup>1</sup> and J. Bakker <sup>2</sup>	1ECN Module Technology, The Netherlands, 2TTA / Eurotron, The Netherlands
6O-A9-04		ADVANCING LASER JOINING IN SOLAR MODULE MANUFACTURING	A. Moalem <sup>1</sup> , A. Schoonderbeek <sup>1</sup> , R. Kling <sup>1</sup> , A. Ostendorf <sup>1</sup> , M. Gast <sup>2</sup> , R. Grischke <sup>2</sup> and R. Brendel <sup>2,3</sup>	1Laser Zentrum Hannover (LZH), Germany, 2Institut für Solarenergieforschung Hameln/Emmerthal (ISFH), Germany, 3Leibniz Univ. Hannover, Germany
6O-A9-05		DEVELOPMENT OF NEW PACKAGING METHODS FOR CIS-BASED THIN-FILM PV CIRCUITS	H. Nishi <sup>1</sup> , H. Suzuki <sup>2</sup> and K. Kushiya <sup>1</sup>	1Showa Shell Sekiyu K.K., Japan, 2Showa Shell Solar K.K., Japan
6O-A9-06		ADVANCED INTEGRATED INVERTERS AND ENERGY MANAGEMENT SYSTEMS	W. Bower <sup>1</sup> , D. Ton <sup>2</sup> , M. Ropp <sup>3</sup> , S. Gonzalez <sup>1</sup> and J. Torres <sup>1</sup>	1Sandia National Laboratories, USA, 2US Department of Energy, USA, 3South Dakota State University, USA

**III-V Materials and Devices**

**Area 2 December 6th, Thursday 11:00-12:30 (Room B)**

**Chs: N. J. Ekins-Daukes Imperial College London, UK**

**Y. Okada University of Tsukuba, Japan**

6O-B9-01	Invited	STATUS AND ISSUES IN HIGH-EFFICIENCY III-V SOLAR CELLS	S. Kurtz, J. Geisz, W. McMahon, M. Wanlass, K. Jones, R. Reedy, S. Ward, A. Duda, J. Olson, D. Friedman, A. Kibbler, T. Moriarty and J. Kiehl	National Renewable Energy Laboratory, USA
6O-B9-02	Invited	APPLICATION OF GROUP III-NITRIDE ALLOYS FOR MULTI-JUNCTION SOLAR CELLS	W. Walukiewicz, J. W. Ager and K. Man Yu	Lawrence Berkeley National Laboratory, USA
6O-B9-03		FABRICATION OF HOMOJUNCTION GaInNAs SOLAR CELLS BY ATOMIC HYDROGEN-ASSISTED MOLECULAR BEAM EPITAXY	Y. Shimizu <sup>1,2</sup> , S. Niki <sup>2</sup> and Y. Okada <sup>1</sup>	1University of Tsukuba, Japan, 2National Institute of Advanced Industrial Science and Technology, Japan
6O-B9-04		CHARACTERIZATION OF CARRIER RECOMBINATION IN LATTICE-MISMATCHED INGaAs SOLAR CELLS ON GaAs SUBSTRATES	T. Sasaki <sup>1</sup> , K. Arafune <sup>1</sup> , T. Takamoto <sup>2</sup> , W. Metzger <sup>3</sup> , M. J. Romero <sup>3</sup> , K. Jones <sup>3</sup> , M. Al-Jassim <sup>3</sup> , Y. Ohshita <sup>1</sup> and M.	1Toyota Technological Institute, Japan, 2Sharp Corporation, Japan, 3National Renewable Energy Laboratory, USA
6O-B9-05	Invited	DIAGNOSTIC CHARACTERIZATION OF SPACE SOLAR CELLS AND THEIR MATERIALS BY LUMINESCENCE SPECTROSCOPY AND TOPOGRAPHY	M. Tajima, H. Toyota, H. Sugimoto, K. Yoshida and H. Nakayama	JAXA, Japan

**Environmental Issues and LCA**

**Area 8 December 6th, Thursday 11:00-12:30 (Room C)**

**Chs: C. Herig Segue energy Consulting, LLC, USA**

**K. Sakuta AIST, Japan**

6O-C9-01	Invited	A PRELIMINARY LIFE-CYCLE ANALYSIS OF A MEGA-SOLAR SYSTEM IN JAPAN	M. Ito <sup>1</sup> , M. Kudo <sup>2</sup> and K. Kurokawa <sup>3</sup>	1Tokyo Institute of Technology, Japan, 2NTT Facilities, Inc., Japan, 3Tokyo University of Agriculture and Technology, Japan
6O-C9-02 has been changed to 3O-C2-07 (December 3rd, Monday 10:15-12:00 (Room C))				
6O-C9-03		EVALUATION OF GHG EMISSION REDUCTION POTENTIALS OF PV SYSTEMS INTRODUCTION SCENARIOS USING POWER MIX OPTIMIZATION MODELS	Y. Fukushima and Y. Kuo	National Cheng Kung University, Taiwan
6O-C9-04		AN ENVIRONMENTAL POTENTIAL OF PV SYSTEMS IN JAPAN BY UTILIZING THE ECOLOGICAL FOOTPRINT	N. Yamashita <sup>1</sup> , M. Ito <sup>2</sup> , K. Komoto <sup>3</sup> and K. Kurokawa <sup>1</sup>	1Tokyo University of Agriculture and Technology, Japan, 2Tokyo Institute of Technology, Japan, 3Mizuho Information & Research Institute, Japan
6O-C9-05		ENVIRONMENTAL POTENTIAL OF VERY LARGE SCALE PHOTOVOLTAIC POWER GENERATION (VLS-PV) SYSTEMS ON DESERTS	K. Komoto <sup>1</sup> , M. Ito <sup>2</sup> , N. Yamashita <sup>3</sup> and K. Kurokawa <sup>3</sup>	1Mizuho Information & Research Institute, Inc., Japan, 2Tokyo Institute of Technology, Japan, 3Tokyo University of Agriculture and Technology, Japan

**High Efficiency Solar Cells; Back Contact**

**Area 3 December 6th, Thursday 14:00-15:30 (Main Hall)**

**Chs: S. Okamoto SHARP Corporation, Japan**

**J. Gee Advent Solar, Inc., USA**

6O-M5-01	Invited	HIGH EFFICIENCY MULTICRYSTALLINE SILICON BACK CONTACT SOLAR CELLS	N. Nakatani, T. Sakamoto, K. Fukui and K. Shirasawa	Kyocera Corporation, Japan
6O-M5-02		0.4 % EFFICIENCY GAIN BY NOVEL BACK CONTACT	C. Ehling <sup>1</sup> , M. B. Schubert <sup>1</sup> , R. Merz <sup>1</sup> , P. J. Rostan <sup>1,2</sup> and J. H. Werner <sup>1</sup>	1Universität Stuttgart, Germany, 2centrotherm photovoltaics technology GmbH, Germany
6O-M5-03		INDUSTRIALLY FEASIBLE MULTI CRYSTALLINE METAL WRAP THROUGH (MWT) SILICON SOLAR CELLS EXCEEDING 16 % EFFICIENCY	F. Clement, M. Lutsch, T. Kubera, H. Wirth, C. Harmel, W. Wolke, D. Biro and R. Preu	Fraunhofer Institute for Solar Energy Systems (ISE), Germany
6O-M5-04		UPDATE ON DEVELOPMENT OF BACK CONTACT SI SOLAR CELL IN PILOT PRODUCTION LINE	K. Nakamura, M. Kohira, Y. Abiko, T. Isaka, Y. Funakoshi and T. Machida	Sharp Corporation, Japan
6O-M5-05		HIGH-EFFICIENCY (AVERAGE 16.0%) INDUSTRIAL-TYPE REAR-CONTACTED MULTICRYSTALLINE SILICON SOLAR CELLS	F. Dross <sup>1</sup> , C. Allebé <sup>2</sup> , Y. Ma <sup>1</sup> , H. Dekkers <sup>1</sup> , G. Agostinelli <sup>1</sup> , P. Choulat <sup>1</sup> , X. Loozen <sup>1</sup> , E. Van Kerschaver <sup>1</sup> , J. Szlufcik <sup>2</sup> and G. Beaucarne <sup>1</sup>	1IMEC, v.z.w., Belgium, 2Industrial Area West-Grijpen, Belgium
6O-M5-06		IMPROVING SHUNT RESISTANCE IN MC-SILICON MWT SOLAR CELLS	I. Moon and D. Kim	Samsung SDI, Korea

<b>Characterization and Reliability</b>				
<b>Area 6 December 6th, Thursday 14:00-15:30 (Room A)</b>				
<b>Chs: K. Sakuta AIST, Japan</b>				
<b>R. Gottschalg Centre for Renewable Energy Systems Technology, UK</b>				
6O-A10-01	Invited	12 YEARS EXPERIENCE ON PV MODULE TESTING - ENLARGEMENT OF TESTING SERVICES -	W. Vaassen1, W. Herrmann1, J. Althaus1 and C. Dreier2	1 TÜV Rheinland Immissionsschutz und Energiesysteme GmbH, Germany, 2TÜV Rheinland Japan Ltd., Japan
6O-A10-02		DIFFERENCE IN THE OUTDOOR PERFORMANCES OF BULK AND THIN-FILM SILICON BASED PHOTOVOLTAIC MODULES	T. Minemoto, S. Fukushige and H. Takakura	Ritsumeikan University, Japan
6O-A10-03		AN LED-BASED PHOTOVOLTAIC MEASUREMENT SYSTEM WITH VARIABLE SPECTRUM AND FLASH SPEED	M. Bliss, T. R. Betts and R. Gottschalg	Loughborough University, UK
6O-A10-04		MODELING I-V CURVES OF PV MODULES USING LINEAR INTERPOLATION/EXTRAPORATION	Y. Tsuno1,2, Y. Hishikawa1 and K. Kurokawa2	1National Institute of Advanced Industrial Science and Technology (AIST), Japan, 2Tokyo University of Agriculture and Technology (TUAT), Japan
6O-A10-05		PHOTOVOLTAIC MODULE RELIABILITY, FAILURE MECHANISMS AND SERVICE LIFETIME PREDICTION	N. G. Dhere and V. V. Hadagali	Florida Solar Energy Center, USA
6O-A10-06		EXPERIMENTAL STUDIES OF FAULT LOCALIZATION IN PV MODULE STRINGS	T. Takashima1, J. Yamaguchi2, K. Otani1, T. Oozeki1, K. Kato1 and M. Ishida2	1National Institute of Advanced Industrial Science and Technology (AIST), Japan, 2University of Tsukuba, Japan

<b>Concentrator Cells, Modules, and Systems</b>				
<b>Area 2 December 6th, Thursday 14:00-15:30 (Room B)</b>				
<b>Chs: W. Walkiewicz Lawrence Berkeley National Laboratory, USA</b>				
<b>T. Takamoto SHARP Corporation, Japan</b>				
6O-B10-01	Invited	LATEST ADVANCES IN MULTI-JUNCTION PV SYSTEM DEVELOPMENT	V. Garboushian, A. Slade and R. Gordon	Amonix Inc., USA
6O-B10-02	Invited	FROM CONCENTRATION TO SIMPLICITY: PACKAGING AND COST CUTTING STRATEGIES FOR SOLID CONCENTRATOR DESIGN	H. Chan	SolFocus, Inc., USA
6O-B10-03		OPERATING CHARACTERISTICS OF MULTIJUNCTION SOLAR CELLS	G. S. Kinsey, P. Pien, P. Hebert and R. A. Sherif	Spectrolab, Inc., USA
6O-B10-04		DEVELOPMENT OF A 1,340 X (GCR) MODULE COMPATIBLE TO THE CURRENT 500 X CPV TRACKERS	K. Araki	Daido Steel, Japan
6O-B10-05	Invited	NOVEL PROPERTIES OF STRAIN-BALANCED QUANTUM WELL CELLS AT CONCENTRATOR CURRENT LEVELS	K. W. J. Barnham1, I. M. Ballard1, B. C. Browne1, C. Calder2, J. C. Connolly1, M. F. Führer1, R. Ginige1, G. Hill2, A. Ioannides1, D. C. Johnson1, M. Mazzer1, J. S. Roberts2 and T. N. D. Tibbits1	1Imperial College London, UK, 2EPSRC III-V National Centre for III-V Technologies, UK

<b>PVPS@PVSEC-17</b>				
<b>Area 8 December 6th, Thursday 13:30-15:30 (Room C)</b>				
<b>Chair: G. Watt Australia PVPS Consortium, Australia</b>				
<b>Co-Chair: I. Kaizuka RTS Corporation, Japan</b>				
<b>Welcome and introduction of PVPS</b>			G. Watt	Australia PVPS Consortium, Australia
6O-C10-01	Invited	TASK 1: EXCHANGE AND DISSEMINATION OF INFORMATION ON PHOTOVOLTAIC POWER SYSTEMS, "TRENDS REPORT, FOCUSING ON INDUSTRY AND INVESTMENT TO PV"	P. Hüßer	Nova Energie, Switzerland
6O-C10-02	Invited	TASK 2: PERFORMANCE, RELIABILITY AND ANALYSIS OF PHOTOVOLTAIC SYSTEMS	TBD (Task 2 expert)	
6O-C10-03	Invited	TASK 8: STUDY ON VERY LARGE SCALE PHOTOVOLTAIC POWER GENERATION	K. Komoto	Mizuho Information & Research Institute, Japan
6O-C10-04	Invited	TASK 9: PHOTOVOLTAIC SERVICES FOR DEVELOPING COUNTRIES	P. Ahm	PA Energy, Denmark
6O-C10-05	Invited	TASK 10: URBAN SCALE PHOTOVOLTAIC APPLICATIONS	C. Herig	Segue Energy Consulting, USA
6O-C10-06	Invited	TASK 11: PV HYBRID SYSTEMS WITHIN MINI-GRIDS	K. Mauch	KM Technical Services, Canada
6O-C10-07	Invited	TASK 12: PV ENVIRONMENT, SAFETY & HEALTH	TBD (Task 12 expert)	

**High Efficiency, Mass Production Process, Thinner Cells**  
**Area 3 December 6th, Thursday 16:00-17:30 (Main Hall)**

**Chs: K. Shirasawa Kyocera Corporation, Japan**

**G. Willeke Fraunhofer-Institut für Solare Energiesysteme ISE, Germany**

6O-M6-01	Invited	1GWP INTEGRATED SOLAR FACTORIES (FROM POLY SI TO SOLAR MODULES)	P. Fath1,2, E. Rüländ1, A. Mozer2 and C. Hahn2	1GP Solar GmbH, Germany, 2SolMic GmbH, Germany
6O-M6-02	Invited	TECHNOLOGY DEVELOPMENT OF HIGH-QUALITY n-TYPE MULTICRYSTALLINE SILICON FOR NEXT GENERATION ULTRA-THIN CRYSTALLINE Si SOLAR CELLS	T. Saitoh1, M. Dhamrin1, K. Kamisako1, K. Yamada2, N. Araki2, I. Yamaga2, H. Sugimoto3 and M. Tajima3	1Tokyo Univ. of Agriculture and Technology, Japan, 2Dai-ichi Kiden Corp., Japan, 3JAXA, Japan
6O-M6-03		16.7% EFFICIENCY i-PERC SOLAR CELLS ON LARGE AREA 130 MICRON THICK MULTICRYSTALLINE SILICON SUBSTRATES	Y. Ma, G. Agostinelli, P. Choulat, H. Dekkers, X. Loozen and G. Beaucarne	IMEC vzw, Belgium
6O-M6-04		17 % EFFICIENT 50 UM THIN SOLAR CELLS	M. Reuter, W. Brendle, O. Tobail and J. H. Werner	University of Stuttgart, Germany
6O-M6-05		A 20% EFFICIENT SLIVER® SOLAR CELL	A. Blakers, V. Everett, K. Weber and E. Franklin	Australian National University, Australia
6O-M6-06		CONDUCTIVE SILVER COLLOIDS FOR LIGHT TRAPPING IN CRYSTALLINE SILICON SOLAR CELLS WITH REAR LOCAL CONTACTS	A. Das, V. Meemongkolkiat, A. Ristow and A. Rohatgi	Georgia Institute of Technology, USA

**Large-area Modules and Processing**  
**Area 5 December 6th, Thursday 16:00-17:50 (Room A)**

**Chs: J. van Duren Nanosolar, USA**

**K. Kushiya Showa Shell Sekiyu K.K., Japan**

6O-A11-01	Special Invited	TBD	L. Kazumerski	NREL, USA
6O-A11-02	Invited	MASS-PRODUCTION TECHNOLOGY FOR HIGH-EFFICIENCY CIGS SOLAR CELLS	K. Matsunaga1, T. Komaru1, Y. Nakayama1, T. Kume2 and Y. Suzuki2	1Honda Engineering Co., Ltd., Japan, 2Honda Soltec Co., Ltd., Japan
6O-A11-03		FABRICATION OF PENTANARY Cu(InGa)(SeS) <sub>2</sub> ABSORBERS BY SELENIZATION AND SULFURIZATION	Y. Goushi, H. Hakuma, K. Tabuchi, S. Kijima and K. Kushiya	Showa Shell Sekiyu K.K., Japan
6O-A11-04		HIGHLY EFFICIENT CUIN <sub>1</sub> -XGAXSE <sub>2</sub> -YSY/CDS THIN-FILM SOLAR CELLS BY USING DIETHYLSELENIDE AS SELENIUM PRECURSOR	A. A. Kadam and N. G. Dhere	University of Central Florida, USA
6O-A11-05		COMMERCIALIZATION OF 'INK BASED' CIGS SOLAR CELLS/MODULES	V. K. Kapur, A. Bansal, B. Gergen and P. Le	International Solar Electric Technology Inc. (ISET), USA
6O-A11-06		NANOPARTICLE-BASED TECHNOLOGY FOR THE FORMATION OF CIS SOLAR CELLS	S. Yoon, T. Yoon, K. Lee, S. Yoon and J. Ha	LG Chem, Ltd./Research Park, Korea (South)

**Space**

**Area 2 December 6th, Thursday 16:00-17:40 (Room B)**

**Chs: D. D. Krut Spectrolab-Boeing, USA**

**M. Imaizumi JAXA, Japan**

6O-B11-01	Invited	EVOLUTION OF SPACE SOLAR CELL AND ARRAY TECHNOLOGY FOR THE NEXT DECADE	H. W. Brandhorst, Jr.	Auburn University, USA
6O-B11-02	Invited	RESEARCH AND DEVELOPMENTS ON SPACECRAFT PHOTOVOLTAIC POWER GENERATION SYSTEMS AT JAXA	K. Kibe, M. Imaizumi, H. Toyota and M. Tajima	Japan Aerospace Exploration Agency (JAXA), Japan
6O-B11-03		DEVELOPMENT OF SPACE SOLAR SHEET	T. Kodama1, H. Yamaguchi1, N. Takahashi1, T. Agui1, H. Washio1, K. Nakamura1, T. Hisamatsu1, T. Takamoto1, K. Shimazaki2, M. Imaizumi2 and K. Kibe2	1SHARP Corporation, Japan, 2Japan Aerospace Exploration Agency, Japan
6O-B11-04		DEGRADATION MODELING OF InGaP/GaAs/Ge TRIPLE JUNCTION SOLAR CELLS IRRADIATED WITH VARIOUS ENERGY PROTONS	S. Sato1, H. Miyamoto1, 2, M. Imaizumi3, K. Shimazaki3, C. Morioka3, K. Kawano2 and T. Ohshima1	1JAEA, Japan, 2UEC, Japan, 3JAXA, Japan
6O-B11-05		STRUCTURAL STUDY ON ALINGAP SINGLE-JUNCTION SOLAR CELL FOR PERFORMANCE IMPROVEMENT OF TRIPLE-JUNCTION SOLAR CELLS	C. Morioka1, M. Imaizumi1, H. Sugimoto1, S. Sato2, T. Ohshima2 and M. Tajima1	1Japan Aerospace Exploration Agency (JAXA), Japan, 2Japan Atomic Energy Agency (JAEA), Japan
6O-B11-06		ANALYSIS OF SOLAR CELL DEGRADATION MECHANISM DUE TO ESD IN SPACE	T. Okumura1, K. Toyoda1, M. Imaizumi2 and M. Cho1	1Kyushu Institute of Technology, Japan, 2Japan Aerospace Exploration Agency, Japan

**PVPS@PVSEC-17****Area 8 December 6th, Thursday 15:45-18:00 (Room C)****Chair: G. Watt Australia PVPS Consortium, Australia****Co-Chair: I. Kaizuka RTS Corporation, Japan**

6O-C11-01	Invited	PV STATUS IN AUSTRALIA	G. Watt	Australia PVPS Consortium, Australia
6O-C11-02	Invited	PV STATUS IN MALAYSIA	C. W. Nee	Pusat Tenaga Malaysia, Malaysia
6O-C11-03	Invited	PV STATUS IN KOREA	K. H. Yoon	Korea Institute of Energy Research, Korea
6O-C11-04	Invited	PV STATUS IN CHINA	J. Li	NDRC, CREIA, China
6O-C11-05	Invited	PV STATUS IN JAPAN	H. Matsukawa	RTS Corporation, Japan
6O-C11-06	Invited	PV STATUS IN INDIA	B. A. Kumar	Indian Association for the cultivation of Science, India
6O-C11-07	Invited	PV STATUS IN MEXICO	Y. Matsumoto	Centro de Investigatory De Estudios Avanzados Del, Mexico
6O-C11-08	Invited	PV STATUS IN CANADA	TBD	
6O-C11-09	Invited	PV STATUS IN USA	TBD	

2007/11/22

**Plenary 7**  
**Area 7 December 7th, Friday 8:30-9:30 (Main Hall)**

**Chs: S. Wakao Waseda University, Japan**  
**R. Bründlinger Arsenal Research, Austria**

PL7-1		FUTURE DIRECTION OF PVSYSTEM TECHNOLOGIES AROUND 2030 AND BEYOND	K. Kurokawa	Tokyo University of Agriculture and Technology – TUAT, Japan
PL7-2		PV HYBRIDS IN MINI-GRIDS - NEW IEA PVPS TASK 11	K. Mauch	KM Technical Services, Canada
PL7-3		LARGE SCALE PV DEMONSTRATIVE PROJECTS PROMOTED BY NEDO	S. Morozumi, Y. Arashiro and N. Inoue	New Energy and Industrial Technology Development Organization, Japan

**Plenary 8**  
**Area 8 December 7th, Friday 9:30-10:30 (Main Hall)**

**Chs: O. Ikki RTS Corporation, Japan**  
**(TBD)**

PL8-1		OVERVIEW OF NEDO'S PHOTOVOLTAIC R&D PROJECTS	H. Fukuda	NEDO, Japan
PL8-2		AN OVERVIEW OF THE U.S. DEPARTMENT OF ENERGY SOLAR PROGRAM: STRATEGY, R&D PIPELINE, AND NEXT STEPS	M. K. Mapes	U.S. Department of Energy Solar Energy Technologies Program, USA
PL8-3		THE GERMAN NATIONAL R&D PROGRAMMES	C. F. Hünnekes	Forschungszentrum Jülich GmbH, Germany

**Next Generation Inorganic Solar Cell**  
**Area 1 December 7th, Friday 11:00-12:30 (Room A)**

**Chs: M. Konagai Tokyo Institute of Technology, Japan**  
**S. Panyakeow Chulalongkorn University, Thailand**

70-A12-01		IMPROVED CONVERSION EFFICIENCY OF SOLAR CELL USING RARE EARTH ION	K. Kawano, B. C.Hong, S. Kohketsu, Y. Nakamura and K. Sakamoto	The University of Electro-Communications, Japan
70-A12-02		QUANTUM CONFINEMENT OF SIZE-CONTROLLED SILICON QUANTUM DOTS IN SI DOTS/AMORPHOUS SIC SUPERLATTICE	Y. Kurokawa, S. Tomita, S. Miyajima, A. Yamada and M. Konagai	Tokyo Institute of Technology, Japan
70-A12-03		PLASMONIC ENHANCEMENT OF SILICON SOLAR CELLS	T. Temple and D. Bagnall	University of Southampton, UK
70-A12-04		A MOLECULAR APPROACH TO THE INTERMEDIATE BAND SOLAR CELL	N. J. Ekins-Daukes and T. W. Schmidt	University of Sydney, Australia
70-A12-05		REDUCTION OF ESCAPE CONE LOSSES IN LUMINESCENT CONCENTRATORS WITH CHOLESTERIC MIRRORS	A. R. Burgers <sup>1</sup> , L. H. Slooff <sup>1</sup> and M.G. Debije <sup>2</sup>	<sup>1</sup> ECN Solar Energy, The Netherlands, <sup>2</sup> Technical University of Eindhoven, The Netherlands
70-A12-06		BASIC PROPERTIES OF SEMICONDUCTOR NANOWIRES WITH BUILT IN P-N JUNCTIONS AND THEIR POTENTIAL AS NANO-PHOTOVOLTAIC DEVICES.	M. Zervos	University of Cyprus, Cyprus

**Spherical Solar Cells, Cell Fabrication**  
**Area 3 December 7th, Friday 11:00-12:30 (Room B)**

**Chs: H. Takakura Ritsumeikan University, Japan**  
**M. Dhamrin Tokyo University of Agriculture and Technology, Japan**

70-B12-01		APPROACHES FOR IMPROVING THE PERFORMANCES OF SPHERICAL SILICON SOLAR CELL	Z. Liu <sup>1</sup> , T. Nagai <sup>1</sup> , A. Masuda <sup>1</sup> , T. Hibino <sup>2</sup> , M. Murozono <sup>2</sup> and M. Kondo <sup>1</sup>	<sup>1</sup> National Institute of Advanced Industrial Science and Technology (AIST), Japan, <sup>2</sup> Clean Venture 21 Co., Japan
70-B12-02		3-D GEOMETRY OF SPHELAR® CELLS	K. Taira, S. Ohtani, I. Inagawa, E. Omura and J. Nakata	Kyosemi Corporation, Japan
70-B12-03		PULSED LASER-DOPED SELECTIVE EMITTER FOR SILICON SOLAR CELLS	C. Carlsson, J. R. Köhler and J. H. Werner	University of Stuttgart, Germany
70-B12-04		PROCESSING OF HOT MELT INKS FOR HIGH EFFICIENCY SOLAR CELLS	S. Akasaka <sup>1</sup> , H. Kuno <sup>1</sup> , H. Okamoto <sup>1</sup> , A. Chang <sup>2</sup> , J. Chang <sup>2</sup> , H. Kerp <sup>3</sup> and H. Miranda <sup>4</sup>	<sup>1</sup> Ferro Japan, KK, Japan, <sup>2</sup> Ferro Performance Materials Co, Ltd., China (PRC), <sup>3</sup> Ferro Electronic Materials System, The Netherlands, <sup>4</sup> Ferro Electronic Materials System, USA
70-B12-05		FABRICATION OF SILICON SOLAR CELLS WITH BACK SURFACE FIELD BY LASER DOPING TECHNIQUE	K. Horiuchi, Y. Takahashi, A. Ogane, A. Kitiyanan, Y. Uraoka and T. Fuyuki	Nara Institute of Science and Technology (NAIST), Japan
70-B12-06		A METHOD OF MANUFACTURING MULTI-LAYERED ANTI-REFLECTIVE COATINGS FOR SILICON SOLAR CELLS	H. Park, D. Lee, J. Kim, J. You and J. Jeong	LG Chem, Ltd./ Research Park, Korea (South)

**PV Programs, Policies and Incentives**  
**Area 8 December 7th, Friday 11:00-12:30 (Room C)**

**Chs: K. Matsubara NEDO, Japan**  
**D. Kim Korea University, Korea (South)**

70-C12-01	Invited	KOREAN NATIONAL R&D PROGRAMS, POLICY AND INCENTIVES ON PV	J. Song <sup>1</sup> , H. Lim <sup>2</sup> and D. Kim <sup>2</sup>	<sup>1</sup> Korea Institute of Energy Research, Korea (South), <sup>2</sup> Korea University, Korea (South)
70-C12-02	Invited	SOLAR PHOTOVOLTAICS IN INDIA: STATUS AND PROSPECTS	A. K. Barua	Indian Association for the Cultivation of Science, India
70-C12-03	Invited	TBD	J. Li	China Renewable Energy Industries Association, China
70-C12-04	Invited	FRENCH PHOTOVOLTAIC PROGRAMME – FROM R&D TO MARKET DEPLOYMENT	A. Claverie	Agency for Environment and Energy Management, France
70-C12-05	Invited	PROMOTING TARIFFS IN ITALY	A. De Lillo and S. Castello	ENEA, Italy
70-C12-06	Invited	1st REPORT BY THE PHOTOVOLTAIC WORKING GROUP OF THE INTERNATIONAL SCIENCE PANEL ON RENEWABLE ENERGIES (ISPREE)	M. Yamaguchi <sup>1</sup> , J. Luther <sup>2</sup> , T. Schlegl <sup>2</sup> and A. Blakers <sup>3</sup>	<sup>1</sup> Toyota Technological Institute, Japan, <sup>2</sup> Fraunhofer Institute for Solar Energy Systems, Germany, <sup>3</sup> The Australian National University, Australia



**Closing Session**  
**December 7th, Friday 14:00-15:30 (Main Hall)**

**CL-I Conference Highlights & Awards**

Chs: H. Okamoto Osaka University, Japan  
M. Kondo AIST, Japan  
S. Wakao Waseda University, Japan

Highlights	H. Okamoto	Osaka University, Japan
Paper Award	M. Kondo	AIST, Japan
Poster Award	A. Yamamoto	Fukui University, Japan
Young Reseacher Award	S. Wakao	Waseda University, Japan

**CL-II Conference Summary & Announcement of PV Conferences**

Chs: T. Fuyuki Nara AIST, Japan  
T. Nagatomo Shibaura University, Japan  
Y. Ohshita Toyota TI, Japan

Conference Summary	Y. Ohshita	Toyota TI, Japan
33rd IEEE PVSC		
23rd EU-PVSEC		
PVSEC-18		
Closing Remarks	M. Yamaguchi	Toyota TI, Japan
Farewell	T. Fuyuki	Nara AIST, Japan